

Design and development practice of power electronic products

-Week 5

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Course content

- Principle of switching converter ...1 week
- Understanding of components, materials and loss ...2 weeks
- Operation principle and application scope of common circuit architecture ...2 weeks
- Small signal model and stability analysis ...3 weeks
- Basic control methods ...1 week
- The stability of the cascade system ...1 week
- Introduction and design of EMI conducted noise sources, coupling paths,
and non-ideal filters ...1 week

Course outline – Week 5

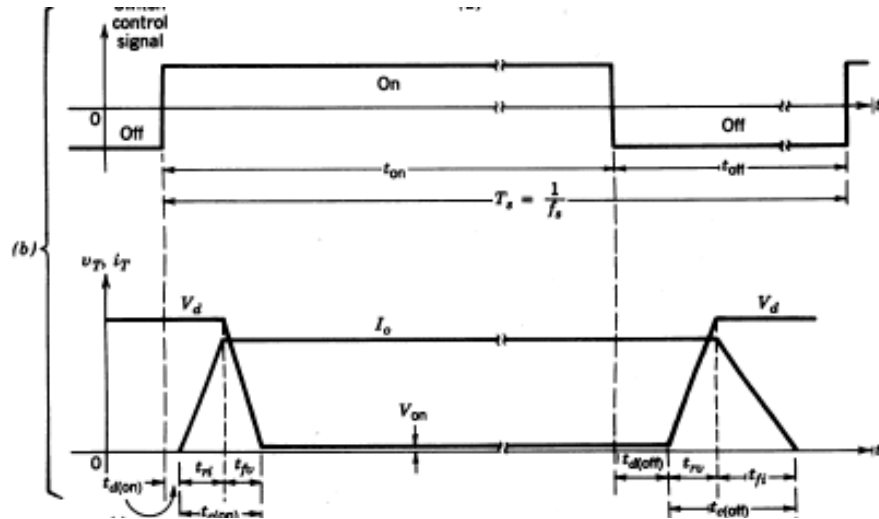
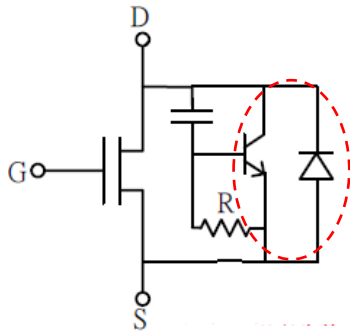
- **Introduction of Zero Voltage Switching / Zero Current Switching technology**
 - Review the switching characteristics and the reasons for adopting ZVS or ZCS
 - The basic principle to realize ZVS
- **Common methods to implement ZVS**
 - Triangular Current Mode, TCM
 - Zero Voltage Transition, ZVT
 - Quasi-Resonant Converter, QRC
 - Active-Clamp
 - Resonant Converter
 - Dual Active Bridge, DAB
 - Phase-Shift Full Bridge, PSFB

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Review the switching characteristics and the reasons for adopting ZVS or ZCS

MOSFET (ZVS)



https://www.st.com/resource/en/application_note/dm00207043-half-bridge-resonant-llc-converters-and-primary-side-mosfet-selection-stmicroelectronics.pdf

IGBT (ZCS)

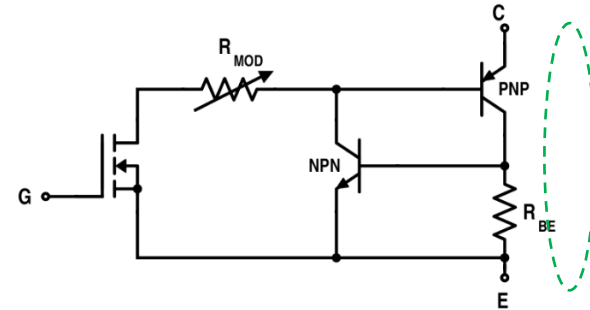
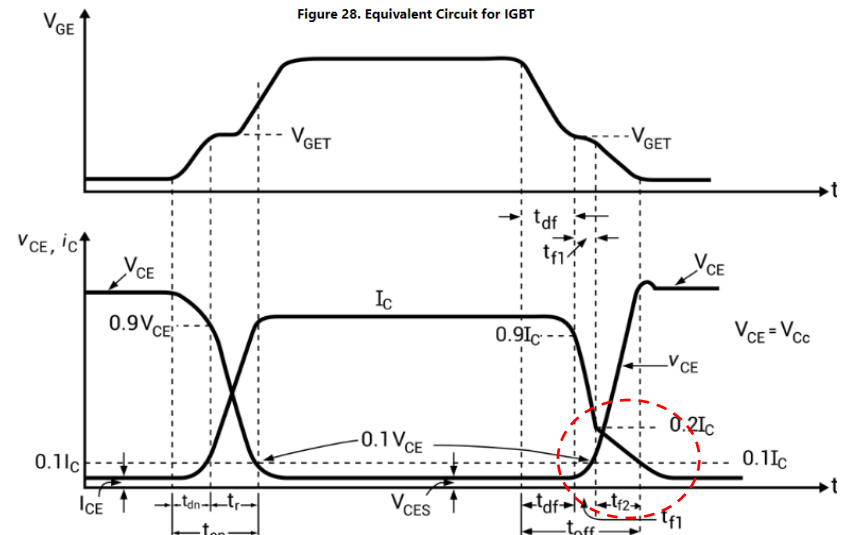
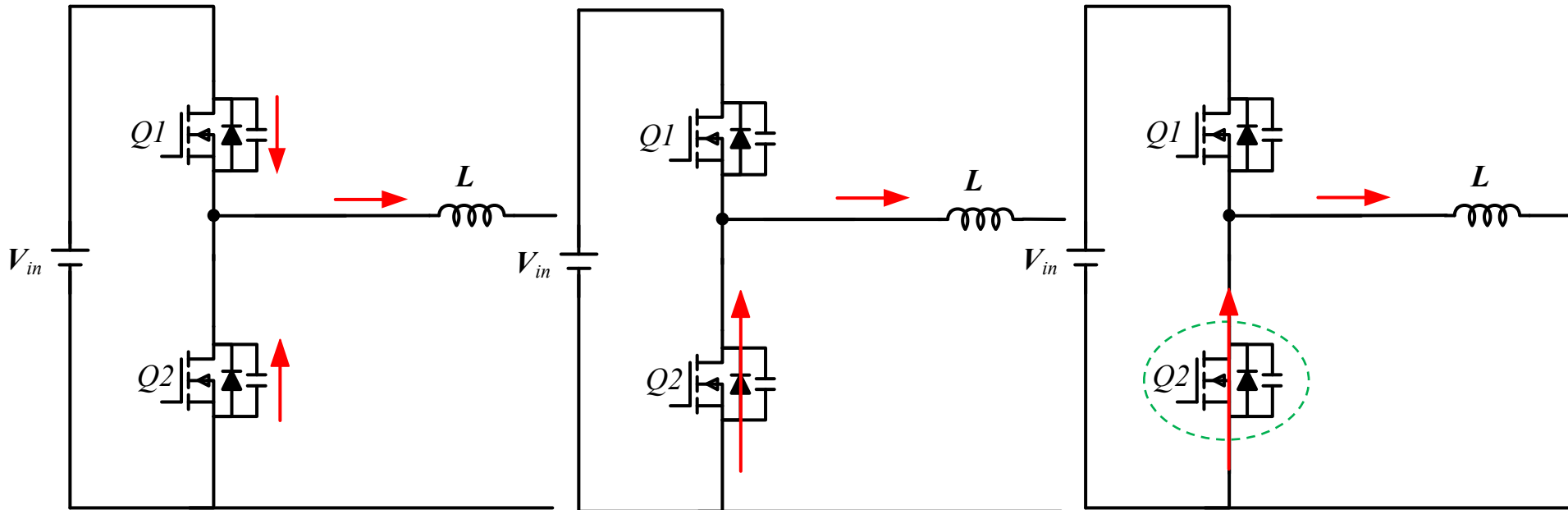


Figure 28. Equivalent Circuit for IGBT



Trivedi, M., & Shenai, K. (1999). *Internal dynamics of IGBT under zero-voltage and zero-current switching conditions*. *IEEE Transactions on Electron Devices*, 46(6), 1274–1282. doi:10.1109/16.766898

The basic principle to realize ZVS

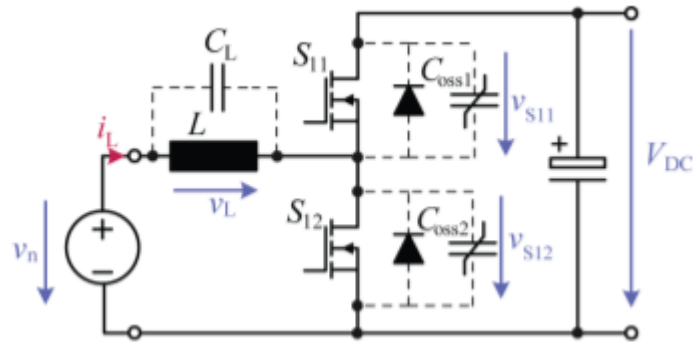


- Create a current to turn on the body diode in the switch dead zone, and then the switch is turned on
- Whether ZVS can be achieved depends on whether the discharge can be completed during the dead time
- Saving switching loss and turns on driver loss, but still have turns off loss

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Triangular Current Mode, TCM (Choose TCM-Boost for example)

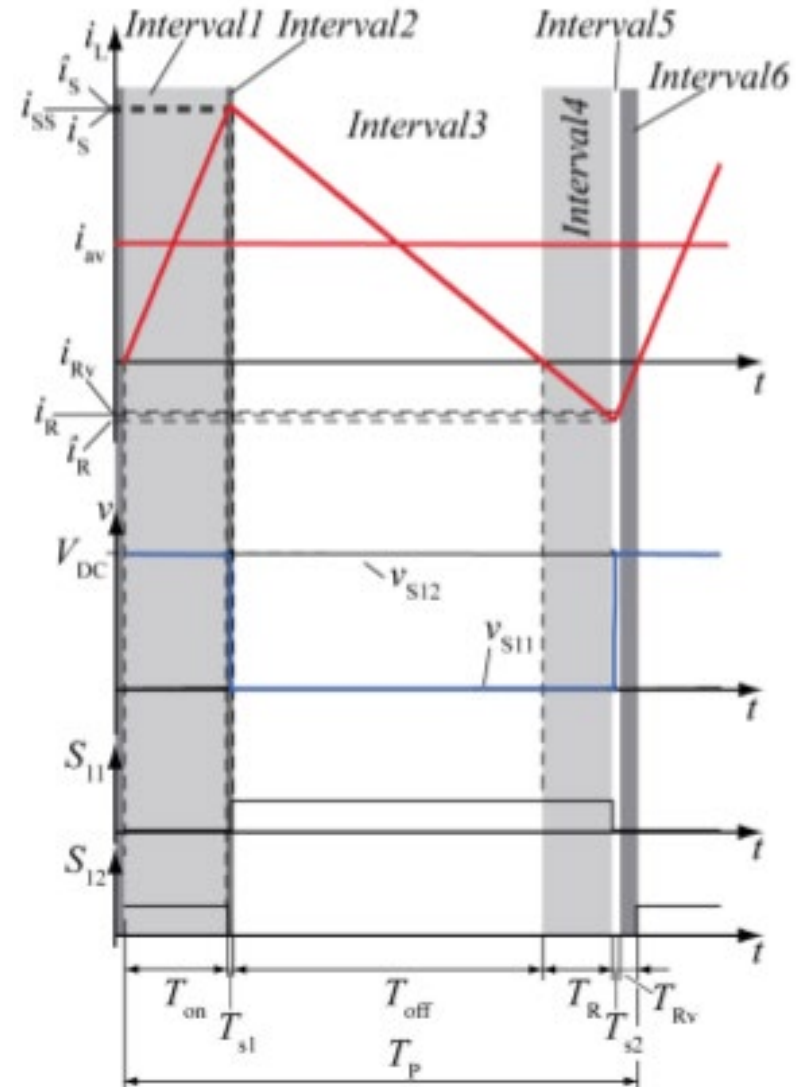


Advantage

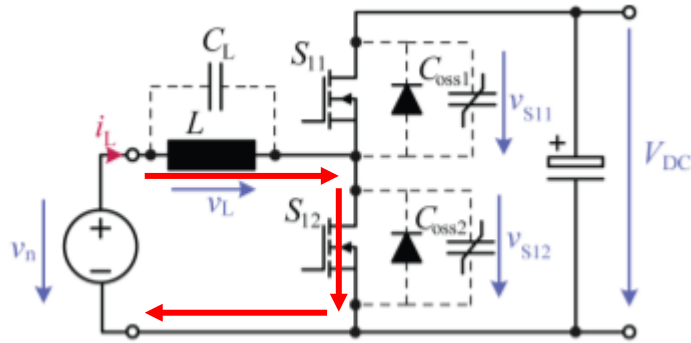
1. No additional switches are required. ZVS can be achieved by controlling complementary switches.

Shortcoming

1. The negative current of the switch must reach a certain level to complete the zero voltage switching.
2. If entirely complementary switching control is adopted, although converter can adopt constant switching frequency operation, it will increase the circulating current loss of the switch.
3. If the lowest negative current control is adopted, although the circulating current loss is reduced, the switching frequency must increase under light load conditions, and the switching loss will increase.

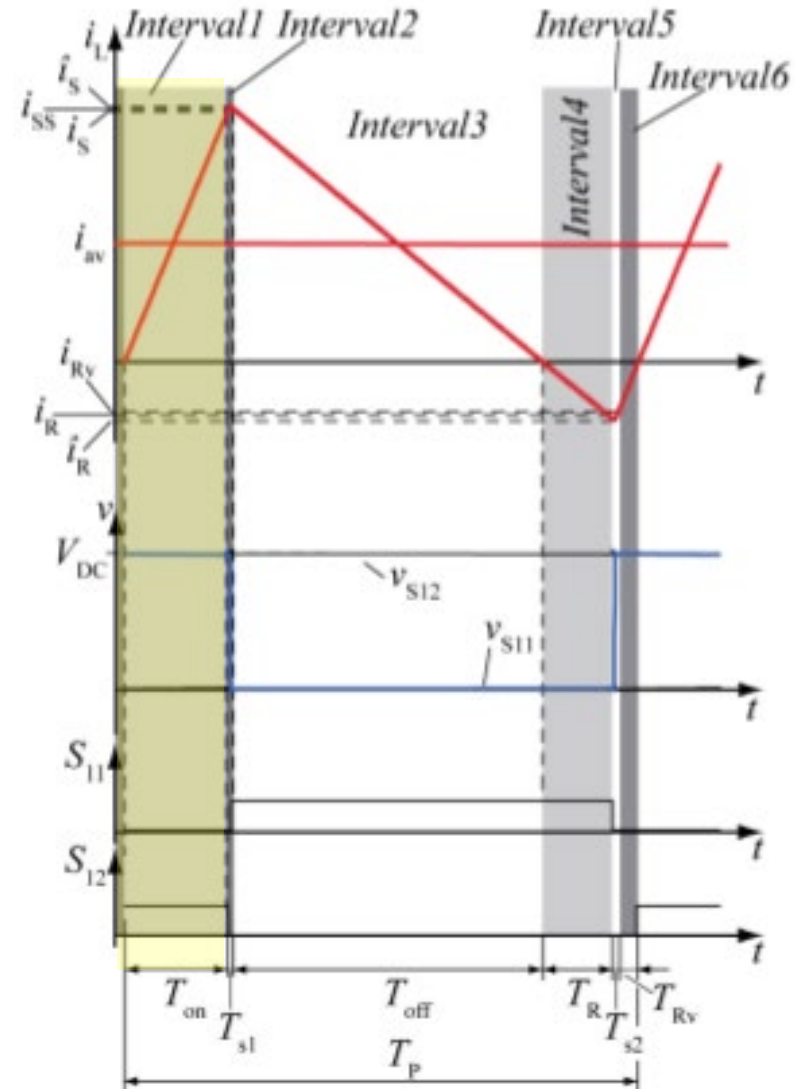


TCM-Boost – Interval 1

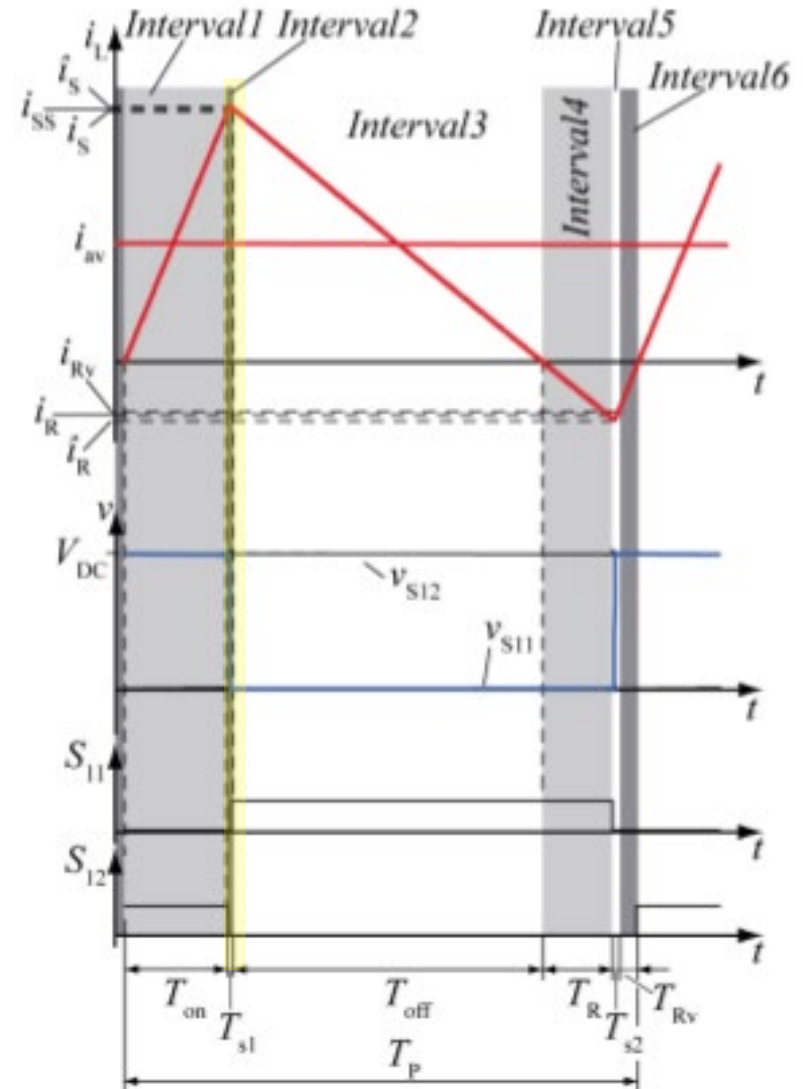
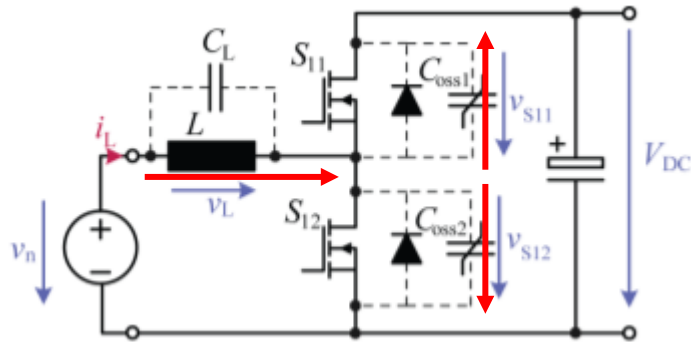


Interval 1

1. Switch S12 ON, $i_L > 0$
2. $v_L = v_n$, i_L increase linearly



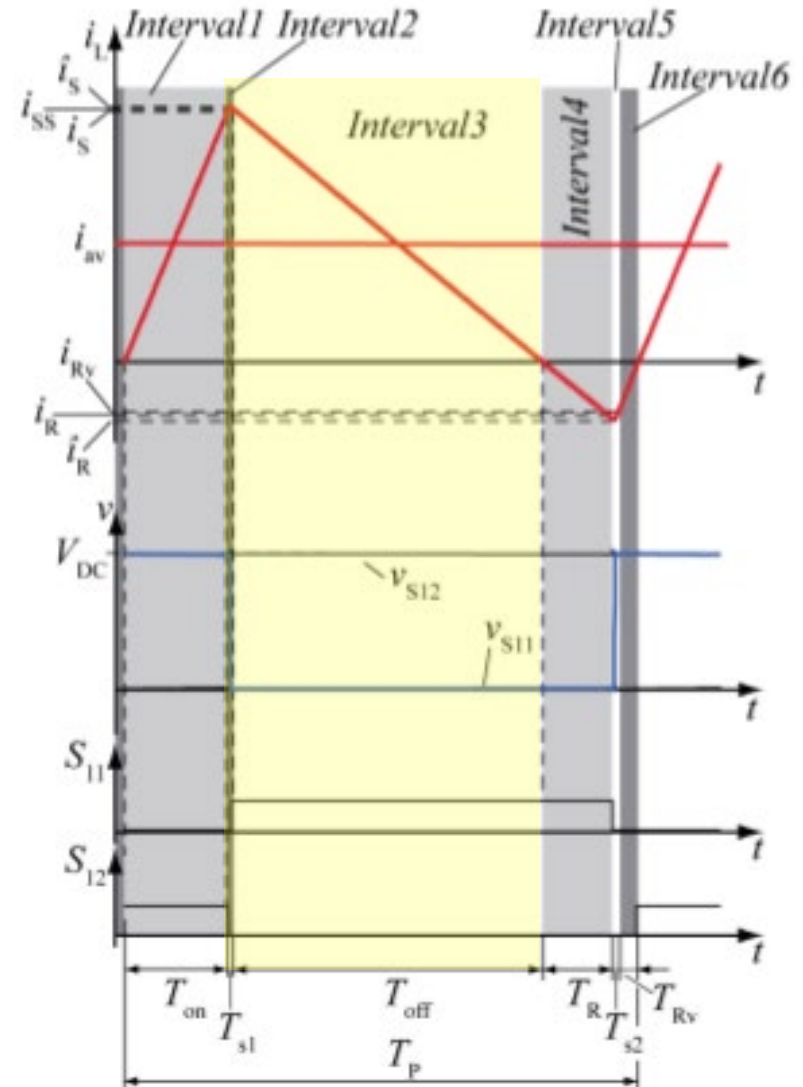
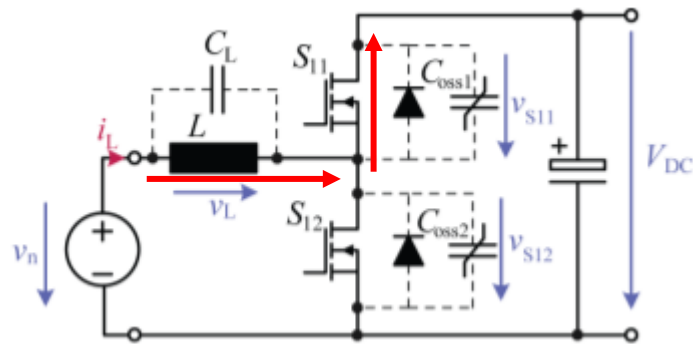
TCM-Boost – Interval 2



Interval 2

1. Dead time interval, $i_L > 0$, charge C_{oss2} and discharge C_{oss1}
2. S11's body diode conduct finally

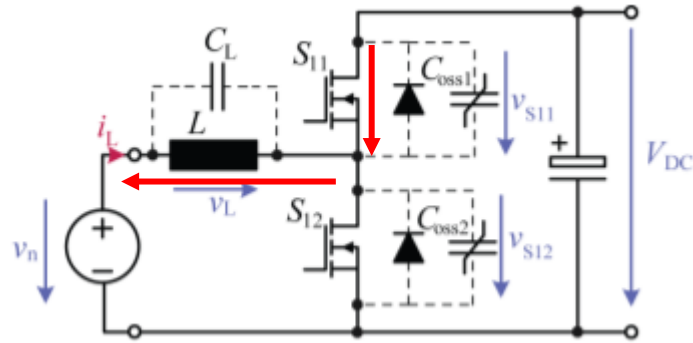
TCM-Boost – Interval 3



Interval 3

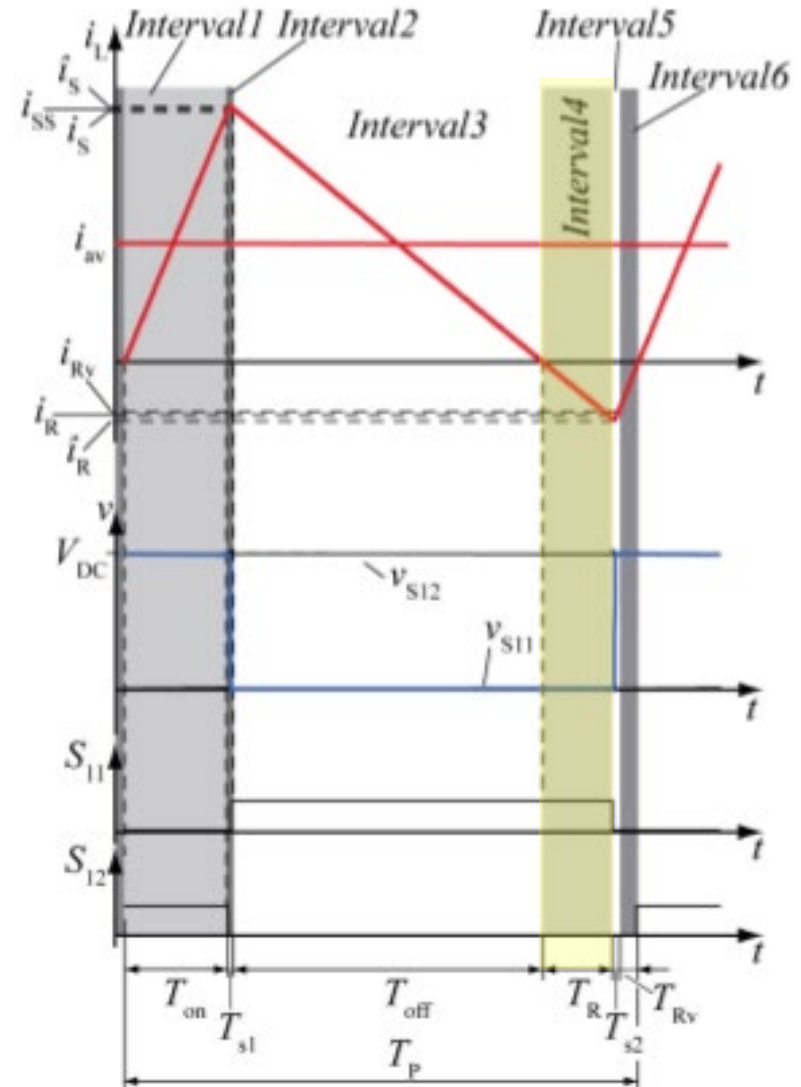
1. S11 turns on with ZVS
2. i_L decrease linearly with $v_L = V_{DC} - V_n$

TCM-Boost – Interval 4

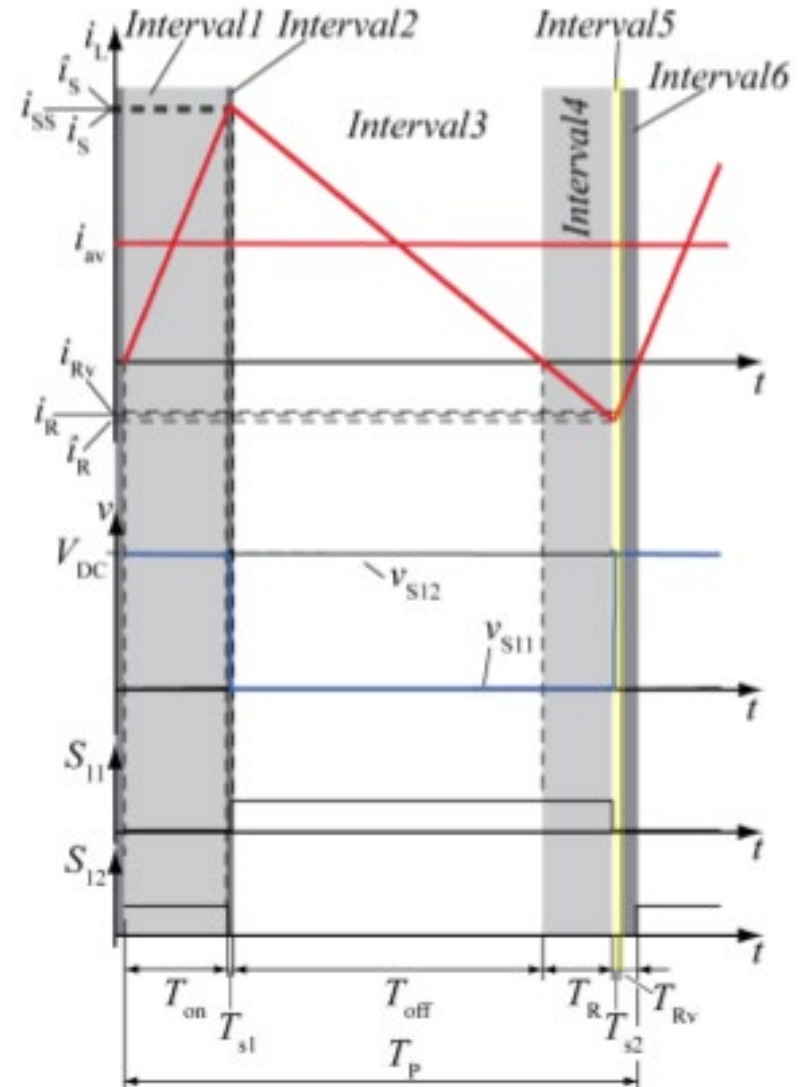
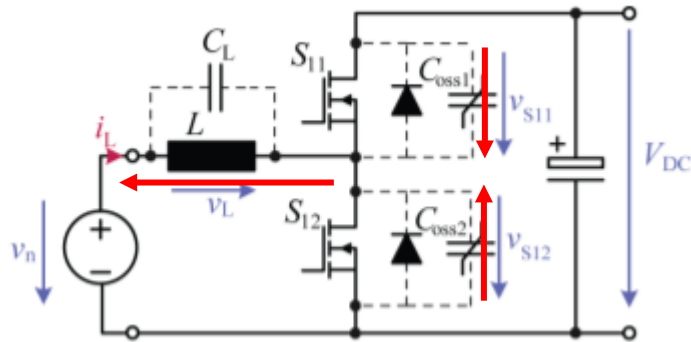


Interval 4

1. i_L decrease linearly with $v_L = V_{DC} - V_n$
2. $i_L < 0$ in interval 4



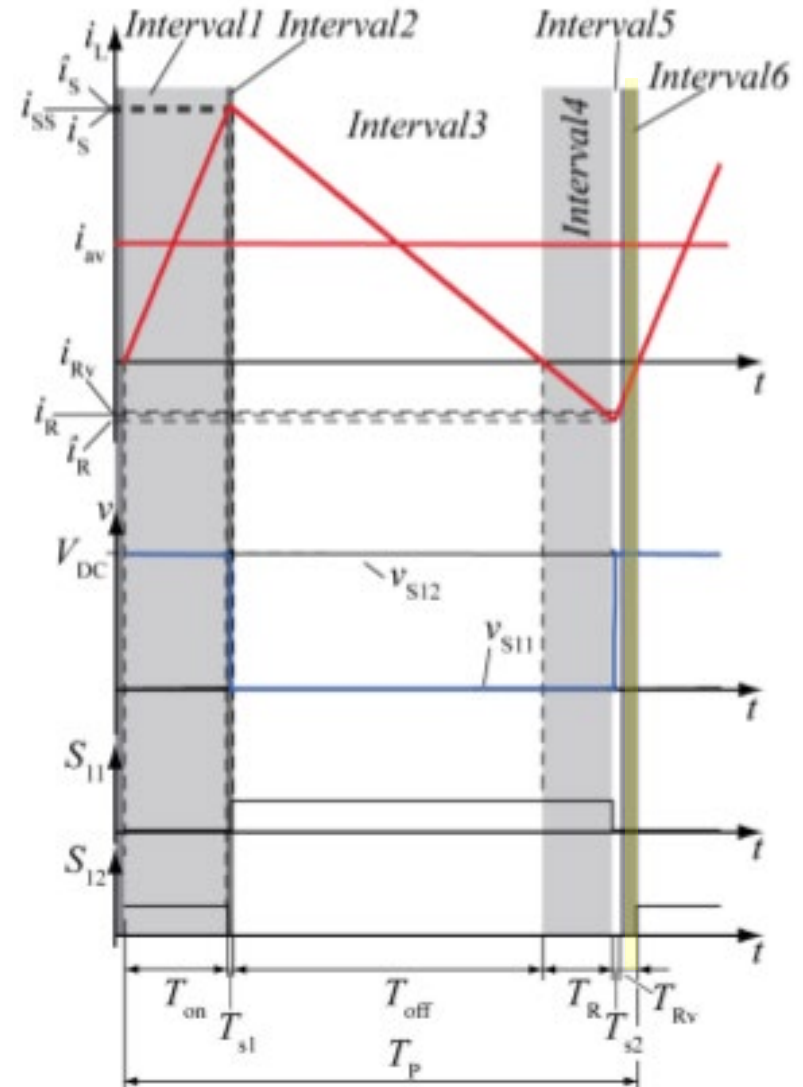
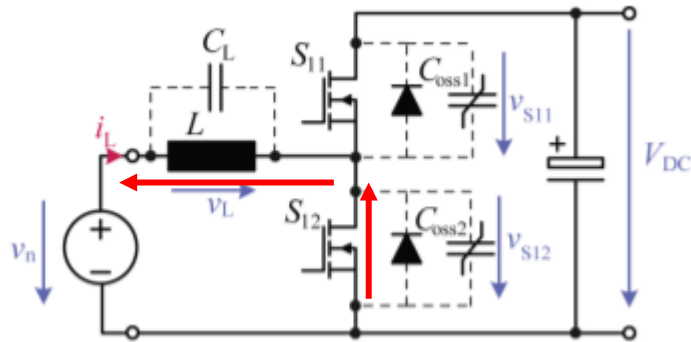
TCM-Boost – Interval 5



Interval 5

1. Dead time interval, $i_L < 0$, charge C_{oss1} and discharge C_{oss2}
2. S12's body diode conduct finally

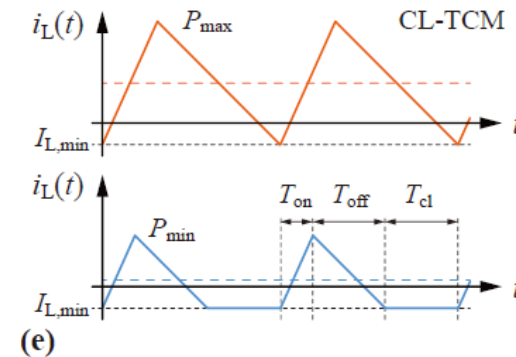
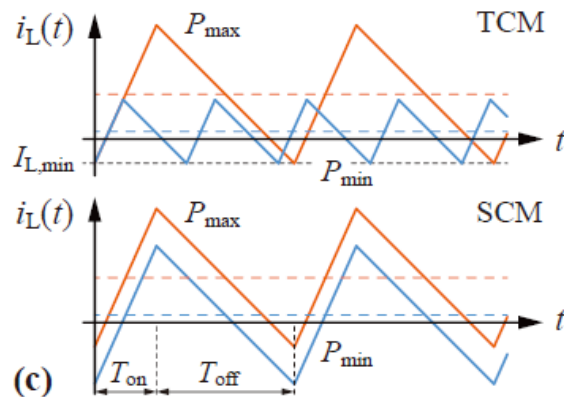
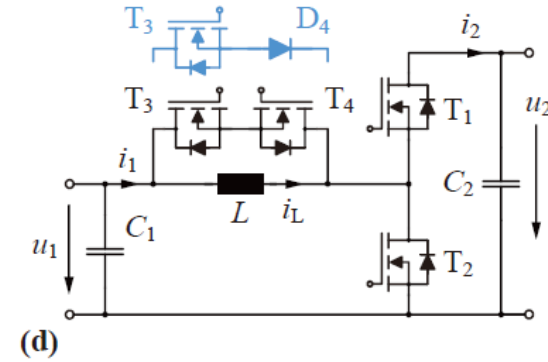
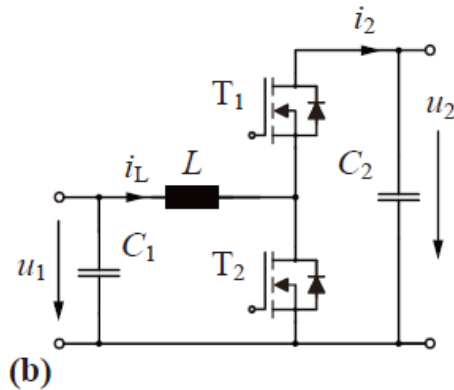
TCM-Boost – Interval 6



Interval 5

1. S12 turns on with ZVS
2. i_L increase linearly with $v_L = V_n$

Synchronous Conduction Mode (SCM), Triangular Current Mode (TCM) and Clamp-Switch TCM (CL-TCM)

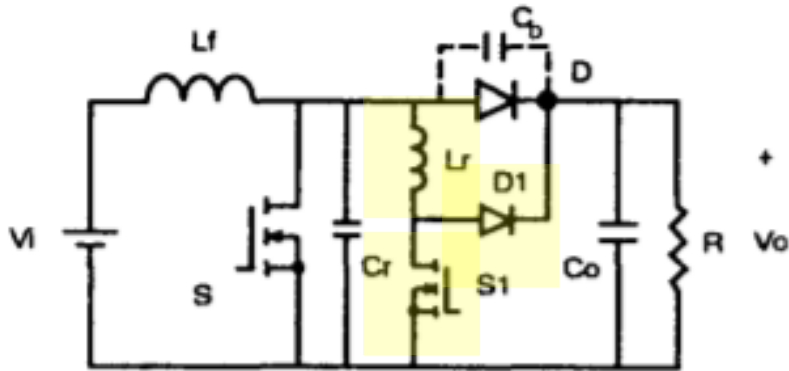


- TCM w/i min negative current, light load with higher switching frequency.
- SCM with constant switching frequency, but have larger circulating current loss.
- CL-TCM could be a better solution but with more components.

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Zero Voltage Transition, ZVT (Choose ZVT-Boost for example)



Advantage

1. Use auxiliary switches to help zero-voltage switching of the main switch
2. The main circuit structure can still switch with zero voltage when working under CCM
3. The linkage sequence of the main switch and auxiliary switch is simple

Shortcoming

1. The withstand current of the auxiliary switch will be larger than that of the main switch
2. The on-time of the auxiliary switch will compress the duty cycle of the main switch.
3. The design of the auxiliary inductor is subject to the auxiliary switch-on time and the highest resonant inductor current

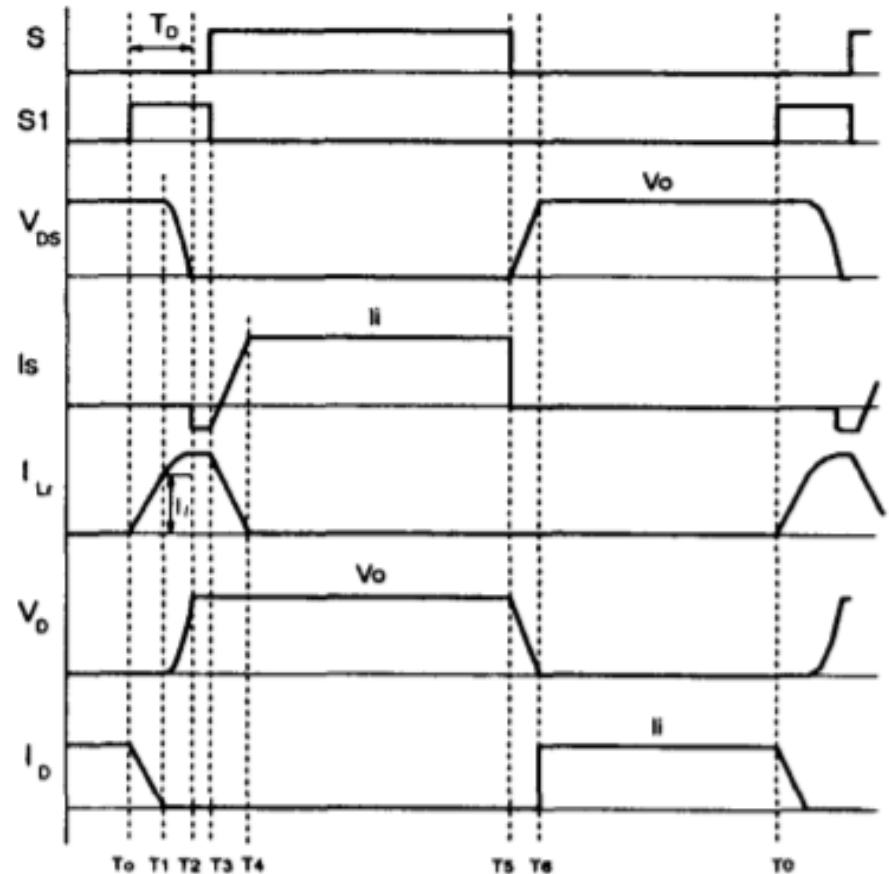
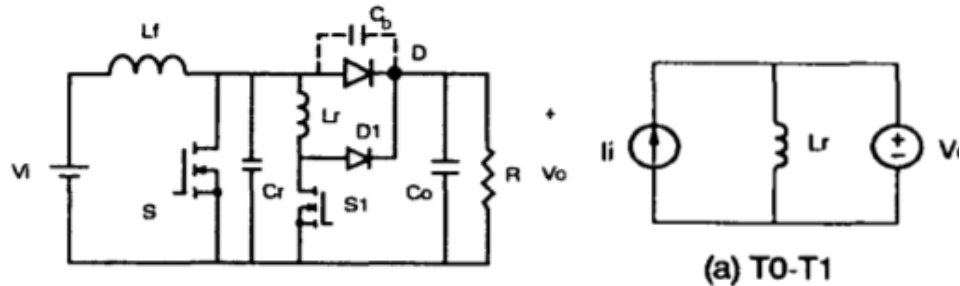


Fig. 1. Circuit diagram and waveforms of the boost ZVT-PWM converter.

Zero Voltage Transition, ZVT – ($T_0 \sim T_1$)



$T_0 \sim T_1$: Prior to T_0 , the main switch (S) and the auxiliary switch (S_1) are off, and the rectifier diode (D) is conducting. At T_0 , S_1 is turned on. **The L_r current linearly ramps up** until it reaches I_i at T_1 , where **D is turned off with soft switching**. This time interval, t_{01} , is given by:

$$t_{01} = \frac{I_i}{V_o/L_r}.$$

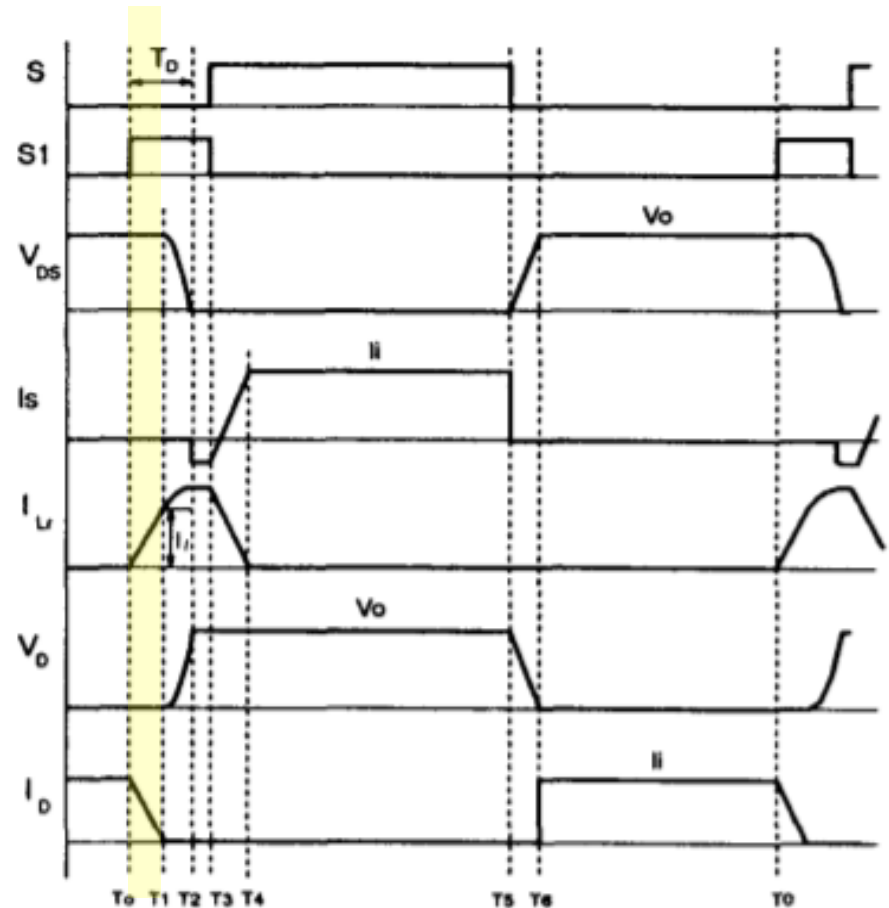
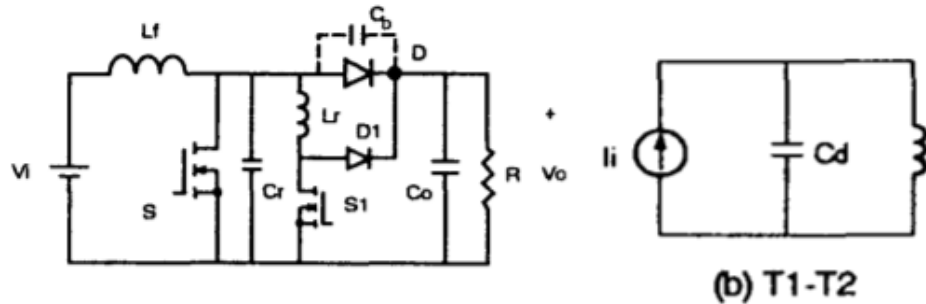


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Zero Voltage Transition, ZVT – ($T_1 \sim T_2$)



T1-T2: L_r current continues to increase due to the resonance between L_r and C_r . C_r is discharged until the resonance brings its voltage to zero at T2, where the anti-parallel diode of S starts to conduct. This resonant time period, t_{12} , is:

$$t_{12} = \frac{\pi}{2} \sqrt{L_r C_r}$$

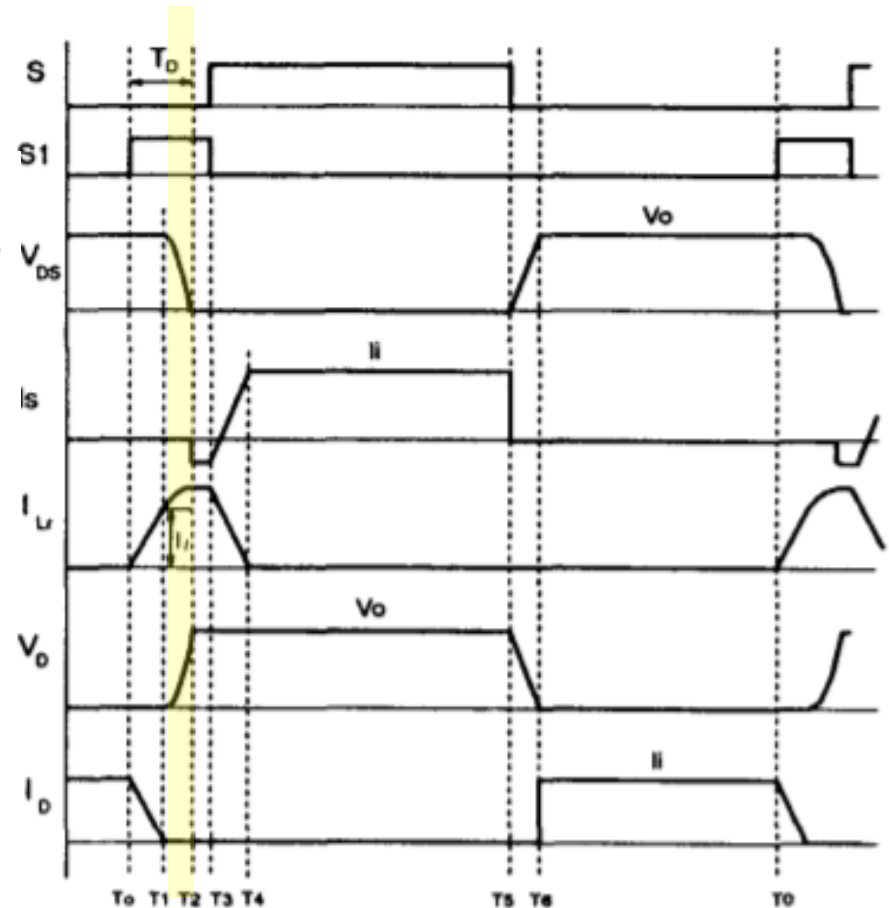
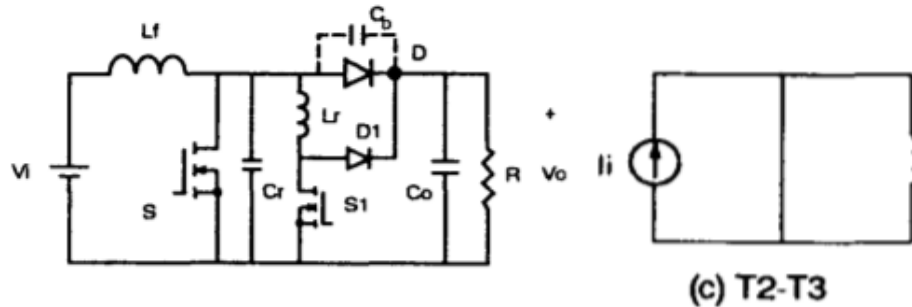


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Zero Voltage Transition, ZVT – ($T_2 \sim T_3$)



T2-T3: The anti-parallel diode of S is on. To achieve ZVS, the turn-on signal of S should be applied while its body diode is conducting. Besides, the time delay between S1 and S gate signals, T_D , has to satisfy the following inequality:

$$T_D \geq t_{01} + t_{12} = \frac{I_i}{V_o L_r} + \frac{\pi}{2} \sqrt{L_r C_s}.$$

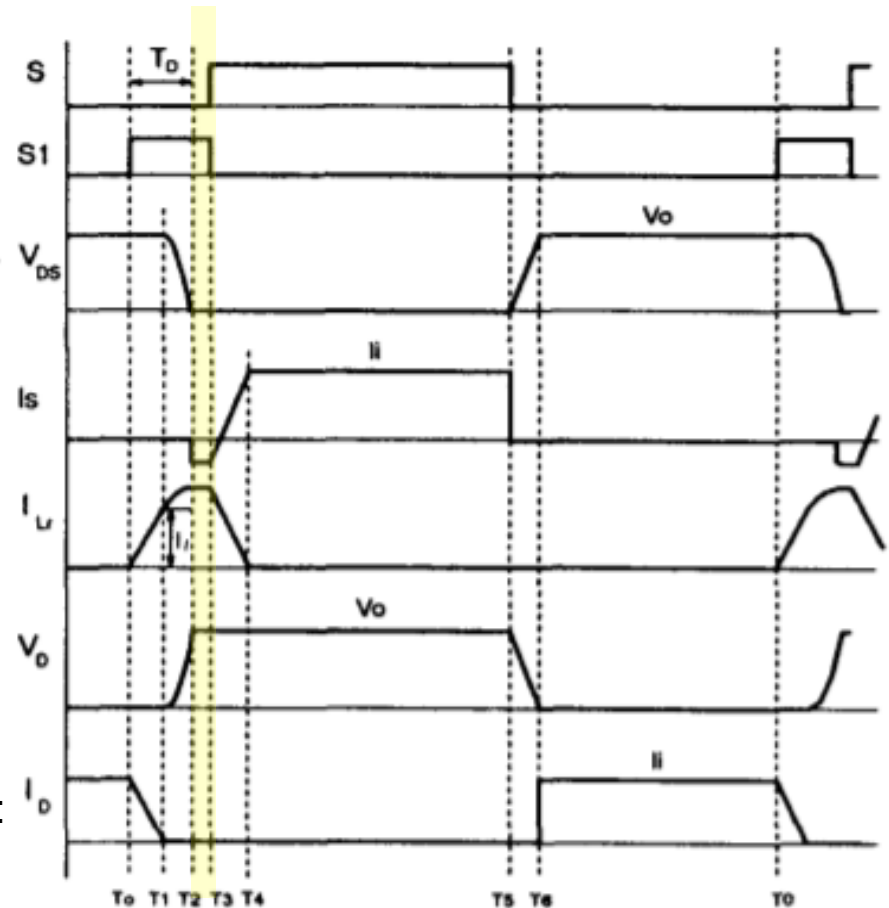
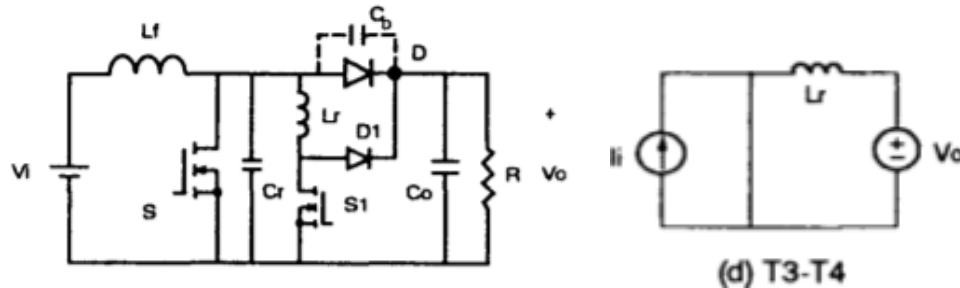


Fig. 1. Circuit diagram and waveforms of the boost ZVT-PWM converter.

Zero Voltage Transition, ZVT – ($T_3 \sim T_4$)



T3-T4: At T3, S1 is turned off, and its voltage is clamped at V_o , due to the conduction of D1. During this time period, S is turned on. The energy stored in the resonant inductor is transferred to the load during this time interval. L_r current decreases linearly until it reaches zero at T4.

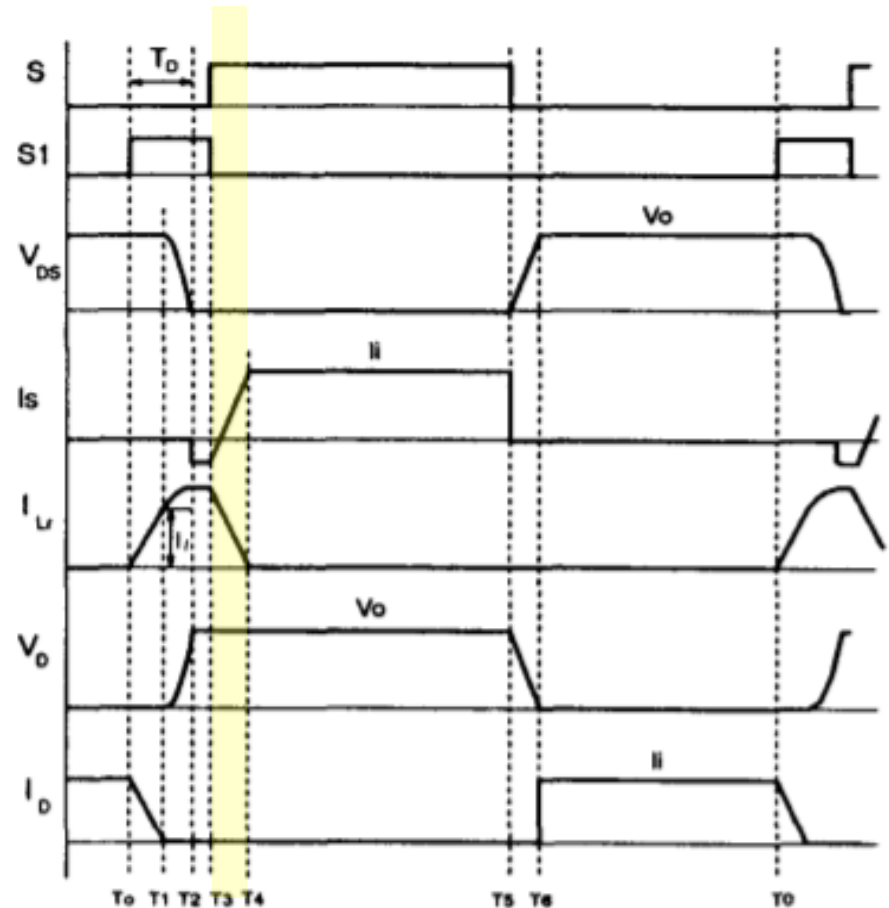
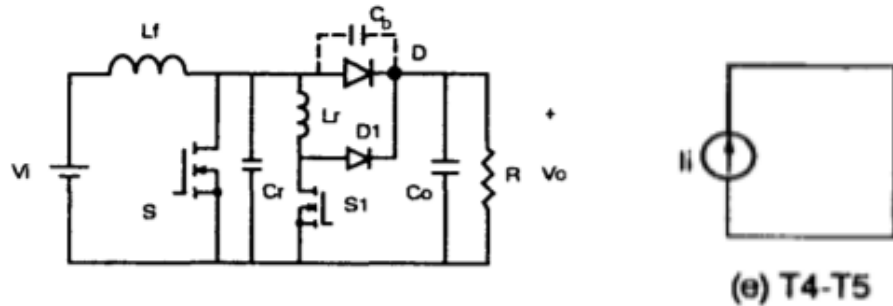


Fig. 1. Circuit diagram and waveforms of the boost ZVT-PWM converter.

Zero Voltage Transition, ZVT – ($T_4 \sim T_5$)



T_4 - T_5 : D_1 is turned off at T_4 . The operation of the circuit at this stage is identical to that of the PWM boost converter

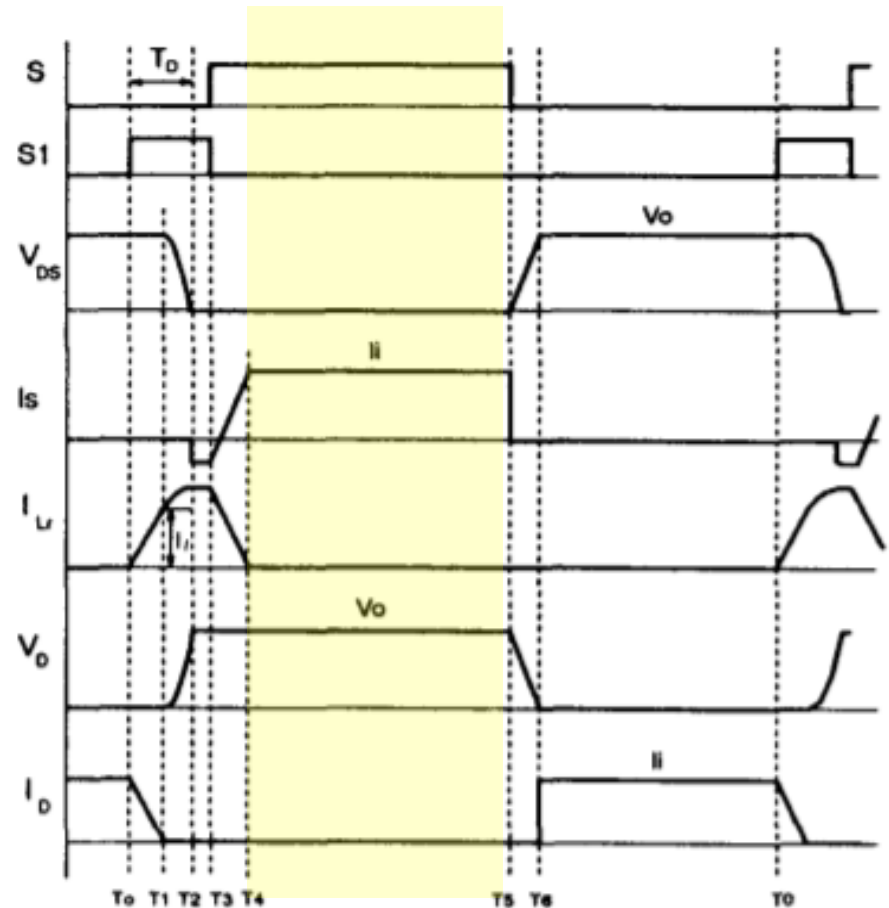
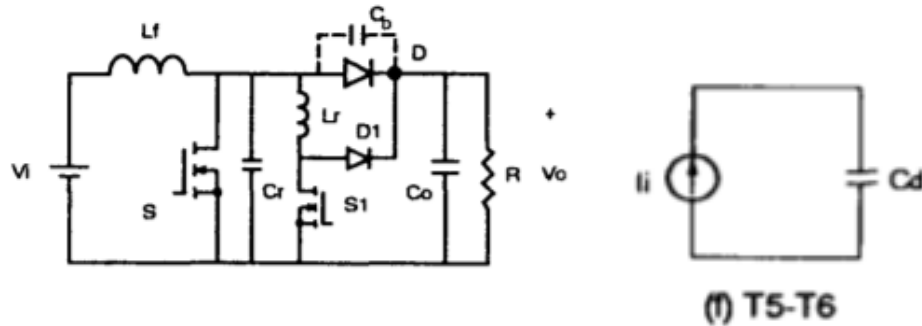


Fig. 1. Circuit diagram and waveforms of the boost ZVT-PWM converter.

Zero Voltage Transition, ZVT – ($T_5 \sim T_6$)



T5-T6: At T5, S is turned off. C_r is linearly charged by i_l to V_i voltage

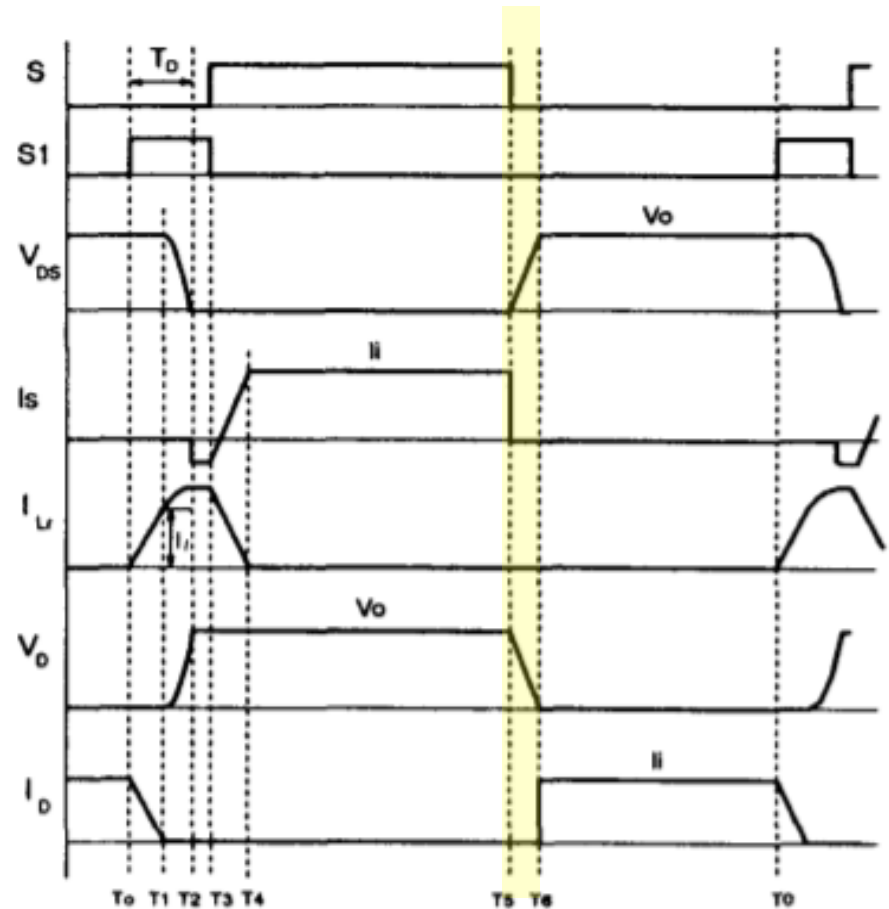
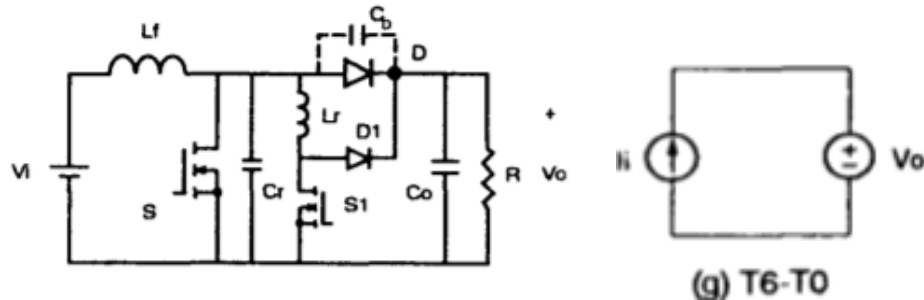


Fig. 1. Circuit diagram and waveforms of the boost ZVT-PWM converter.

Zero Voltage Transition, ZVT – ($T_6 \sim T_0$)



T6-T0: This interval is identical to the freewheeling stage of the boost PWM converter. At T_0 , S1 is turned on again, starting another switching cycle.

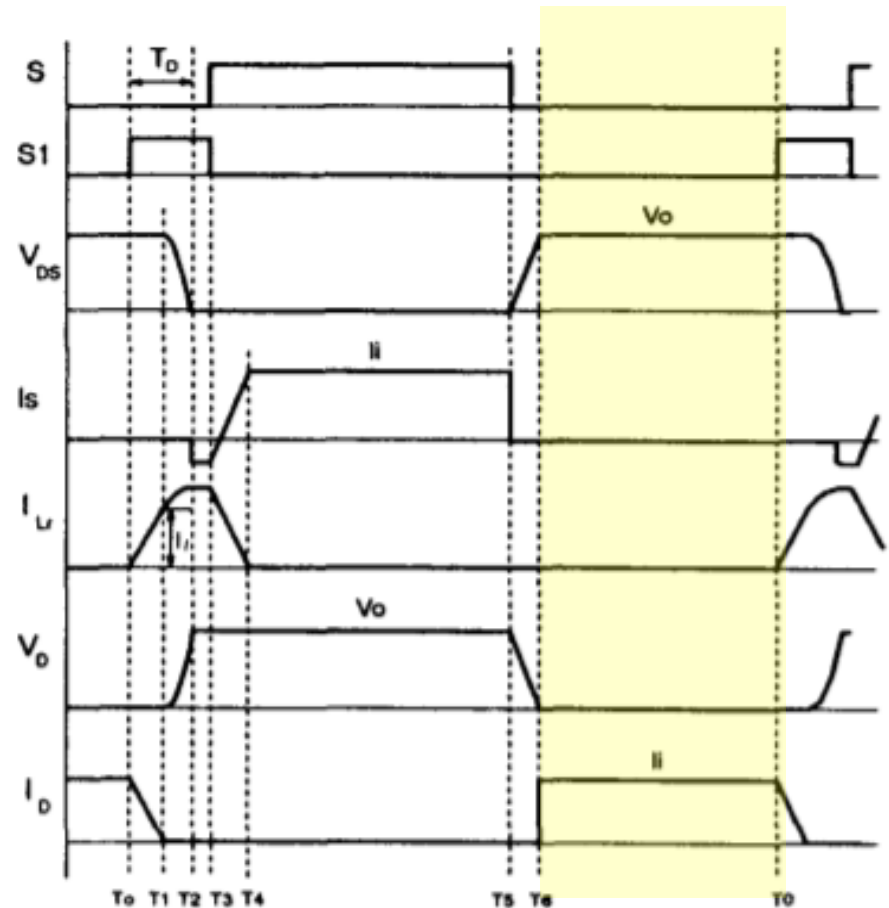
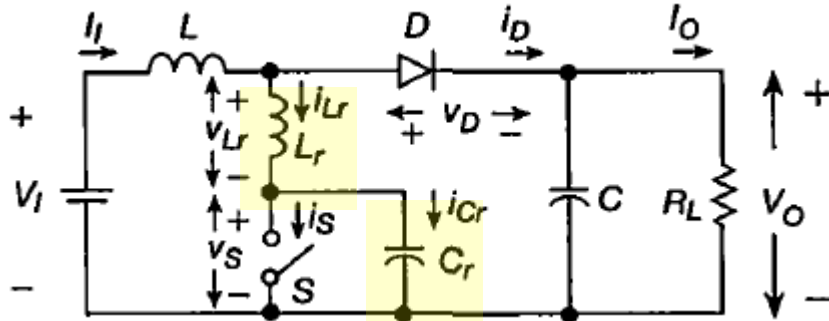


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Quasi-Resonant Converter, QRC (Choose QRC-Boost for example)

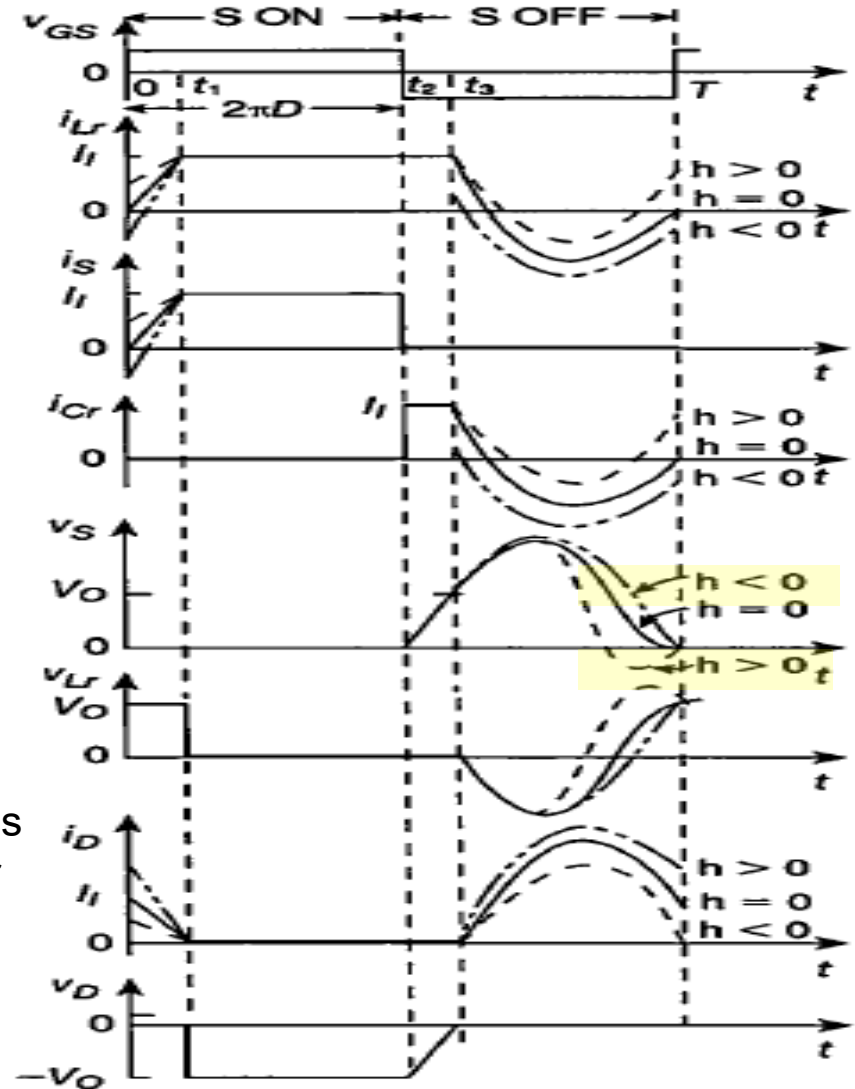


Advantage:

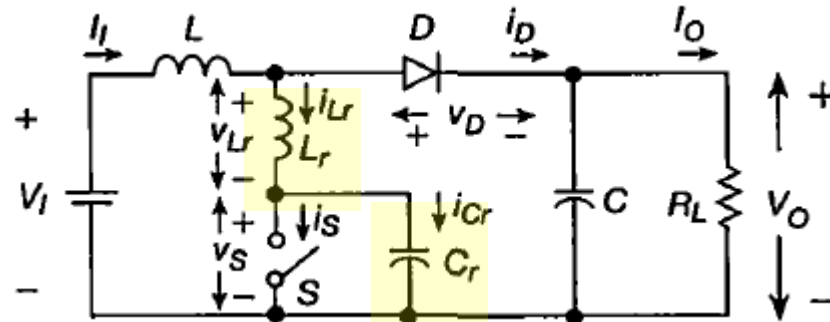
1. No need for additional auxiliary switches and drive signals
2. The main converter can have zero voltage switching function under CCM operation

Shortcoming:

1. Increase the voltage stress level of the main switch
2. The peak value of output diode current increases
3. The voltage conversion formula of the converter is changed to be related to the load and the switching frequency
4. Zero voltage switching can not be achieved under all load conditions



Quasi-Resonant Converter, QRC (Choose QRC-Boost for example) - Symbol definition



- The following definitions are used in the subsequent analysis.

- The resonant frequency of the L_r - C_r circuit is

$$\omega_0 = \frac{1}{\sqrt{L_r C_r}}.$$

- The normalized switching frequency is

$$A = \frac{f_s}{f_0}.$$

- The loaded-quality factor is

$$Q = \frac{R_L}{\omega_0 L_r} = \omega_0 C_r R_L = \frac{R_L}{\sqrt{\frac{L_r}{C_r}}} = \frac{A R_L}{\omega_s L_r} = \frac{\omega_s C_r R_L}{A}.$$

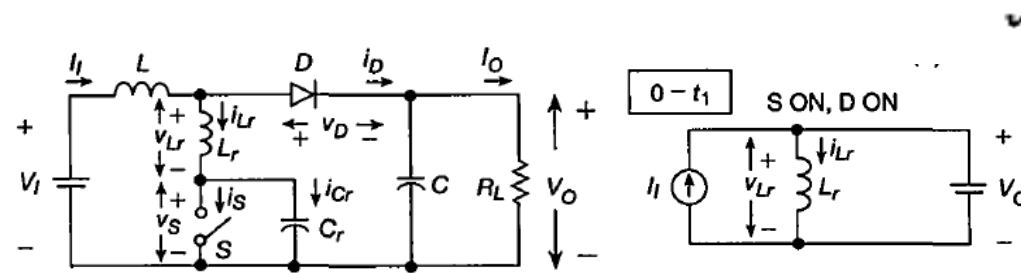
- The DC voltage transfer function is

$$M_{VDC} = \frac{V_O}{V_I}.$$

- The normalized initial resonant inductor and switch current when the switch turns on are

$$h = \frac{i_L(0)}{I_I} = \frac{i_S(0)}{I_I}.$$

Quasi-Resonant Converter, QRC – 0~t₁



Inductor charging time interval $0 < t < t_1$:

Both the switch and diode are ON, during this time interval, $v_S = 0, v_D = 0, i_{Cr} = 0, v_{Lr} = V_O$, and

$$i_{Lr} = \frac{1}{\omega_s L_r} \int_0^{\omega_s t} v_{Lr} d(\omega_s t) + i_{Lr}(0) = \frac{V_O \omega_s t}{\omega_s L_r} + i_S(0).$$

Since $V_O = R_L I_O$ and $V_O / \omega_s L_r = I_l Q / (AM_{VDC})$,

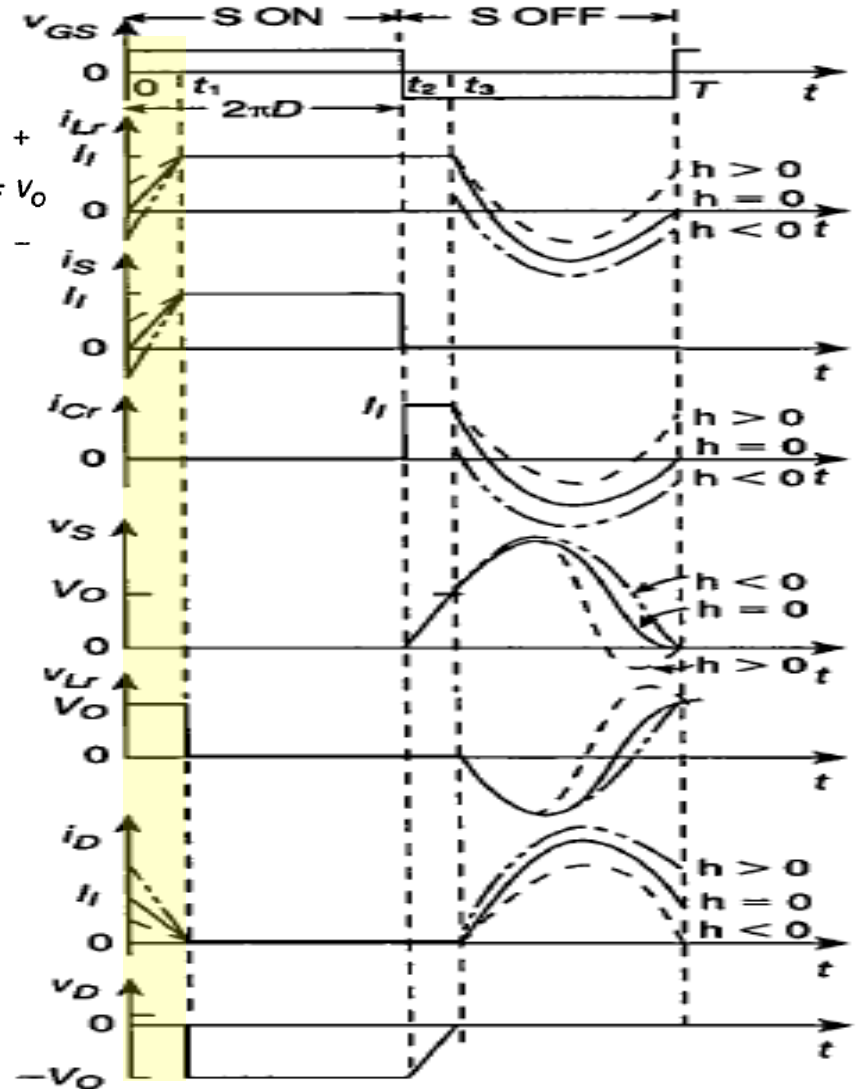
$$\frac{i_{Lr}(\omega_s t)}{I_l} = \frac{i_S(\omega_s t)}{I_l} = \frac{Q}{AM_{VDC}} \omega_s t + h.$$

The diode current waveform is given by

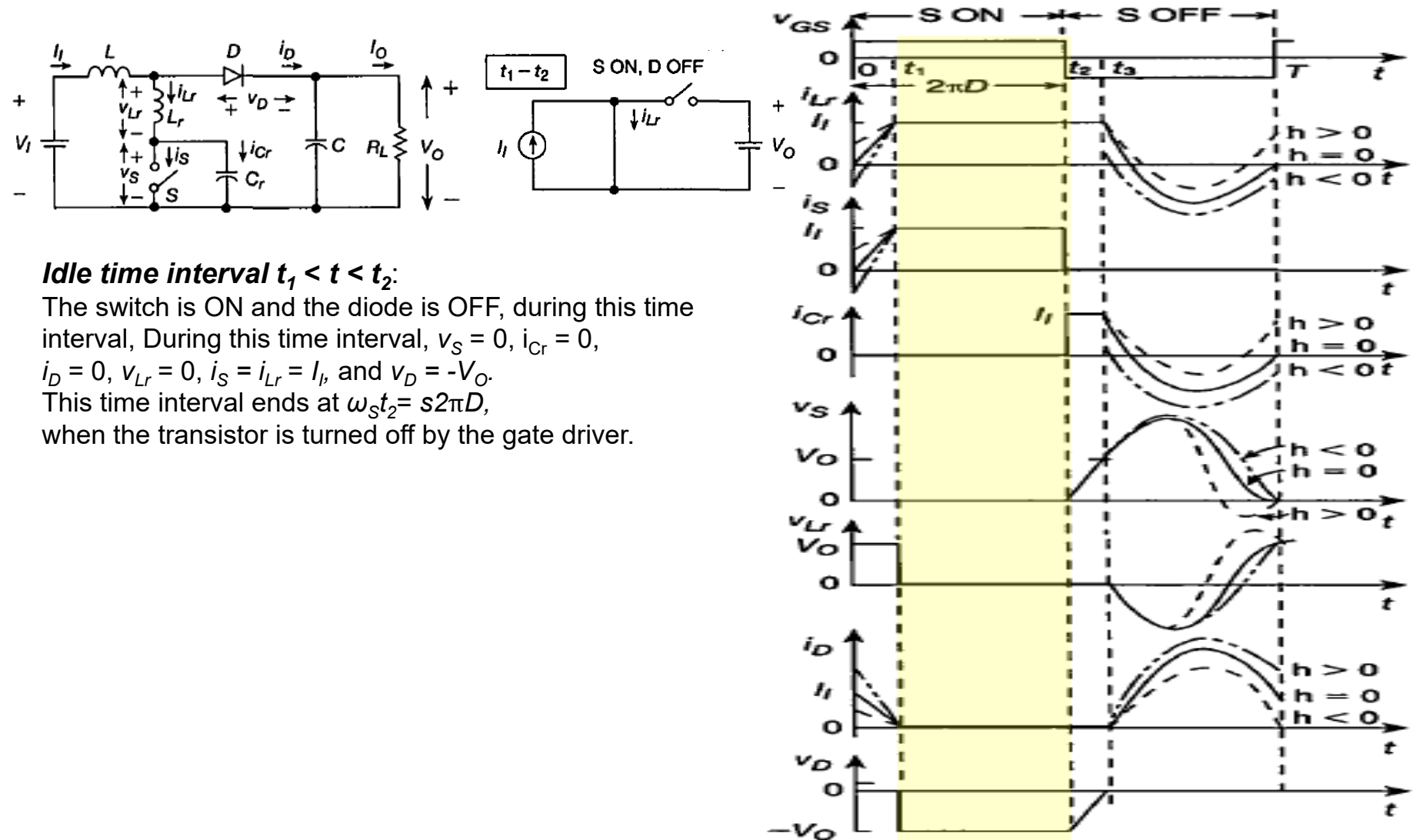
$$\frac{i_D(\omega_s t)}{I_l} = -\frac{Q}{AM_{VDC}} \omega_s t - h + 1.$$

At the end of this time interval, $i_D(\omega_s t_1) = 0$. Hence,

$$\omega_s t_1 = \frac{AM_{VDC}}{Q} (1 - h).$$



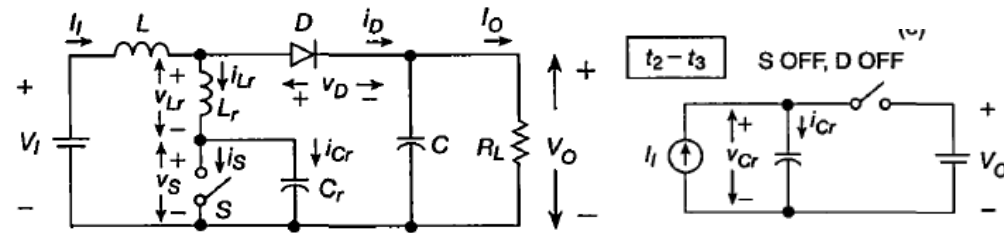
Quasi-Resonant Converter, QRC – $t_1 \sim t_2$



Idle time interval $t_1 < t < t_2$:

The switch is ON and the diode is OFF, during this time interval, During this time interval, $v_S = 0$, $i_{Cr} = 0$, $i_D = 0$, $v_{Lr} = 0$, $i_S = i_{Lr} = I_I$, and $v_D = -V_O$. This time interval ends at $\omega_S t_2 = s2\pi D$, when the transistor is turned off by the gate driver.

Quasi-Resonant Converter, QRC – $t_2 \sim t_3$



Capacitor charging time interval $t_2 < t < t_3$:

Both the switch and the diode are OFF., during this time interval, During this time interval, $i_S = 0$, $i_D = 0$, $i_{Lr} = i_{Cr} = I_I$, $v_{Lr} = 0$, and.

$$\begin{aligned} v_S &= \frac{1}{\omega_s C_r} \int_{2\pi D}^{\omega_s t} v_{Cr} d(\omega_s t) + v_{Cr}(2\pi D) = \frac{1}{\omega_s C_r} \int_{2\pi D}^{\omega_s t} V_I d(\omega_s t) + v_{Cr}(2\pi D) \\ &= \frac{I_I}{\omega_s C_r} (\omega_s t - 2\pi D). \end{aligned} \quad (22.67)$$

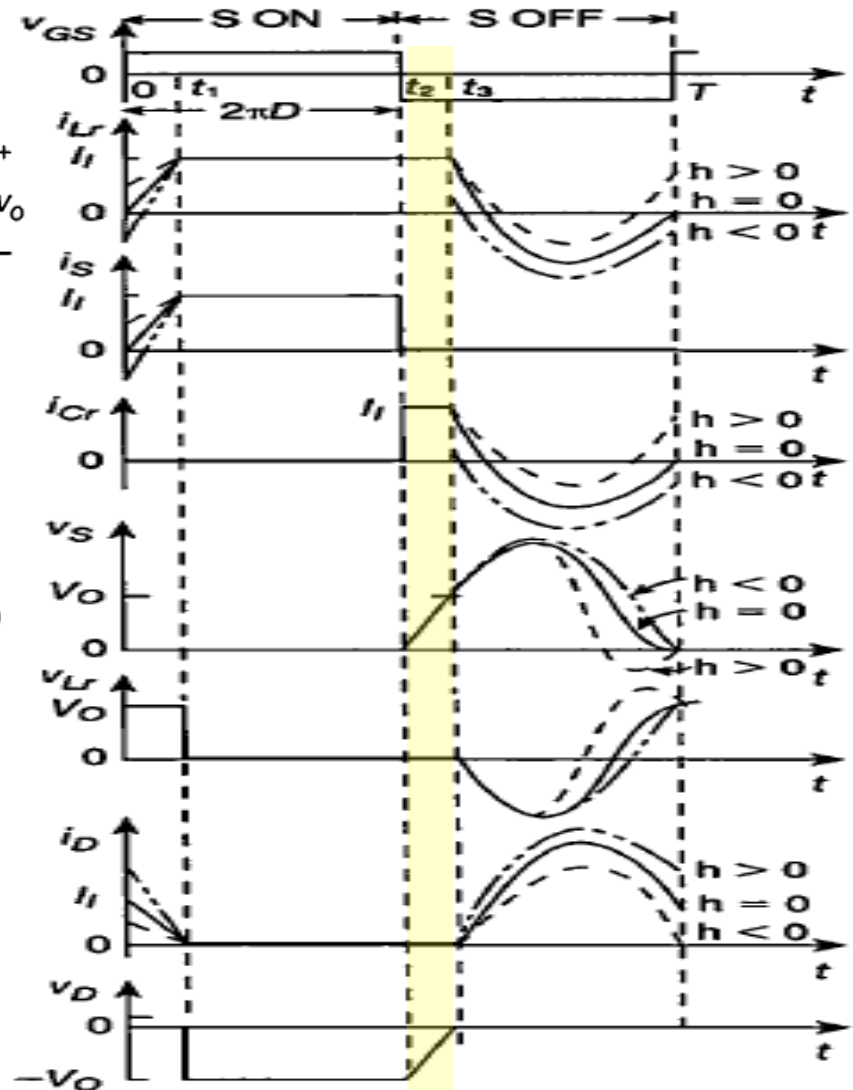
Because $I_I/(\omega_s C_r) = M_{VDC} V_O/(AQ)$ and $I_O = V_O/R_L$, we get

$$\frac{v_S}{V_O} = \frac{M_{VDC}}{AQ} (\omega_s t - 2\pi D) \quad \frac{v_D}{V_O} = \frac{M_{VDC}}{AQ} (\omega_s t - 2\pi D) - 1.$$

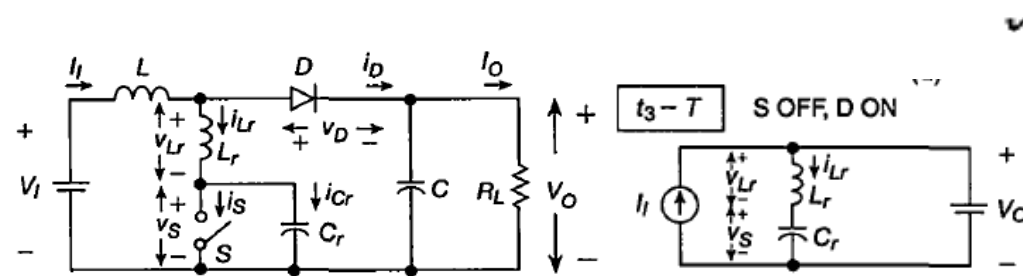
The end of this time interval is determined by $v_D(\omega_s t_3) = 0$.

Hence,

$$\omega_s t_3 = 2\pi D + \frac{AQ}{M_{VDC}}.$$



Quasi-Resonant Converter, QRC – $t_3 \sim t_4$



Resonant time interval $t_3 < t < T$:

The switch is OFF and the diode is ON. During this time interval, $i_S = 0$ and $v_D = 0$. The initial conditions are $i_{Lr}(\omega_s t_3) = I_I$ and $v_{Sr}(\omega_s t_3) = V_I$, and

$$\frac{i_{Lr}}{I_I} = \frac{i_{Cr}}{I_I} = \cos \frac{\omega_s t - \omega_s t_3}{A}.$$

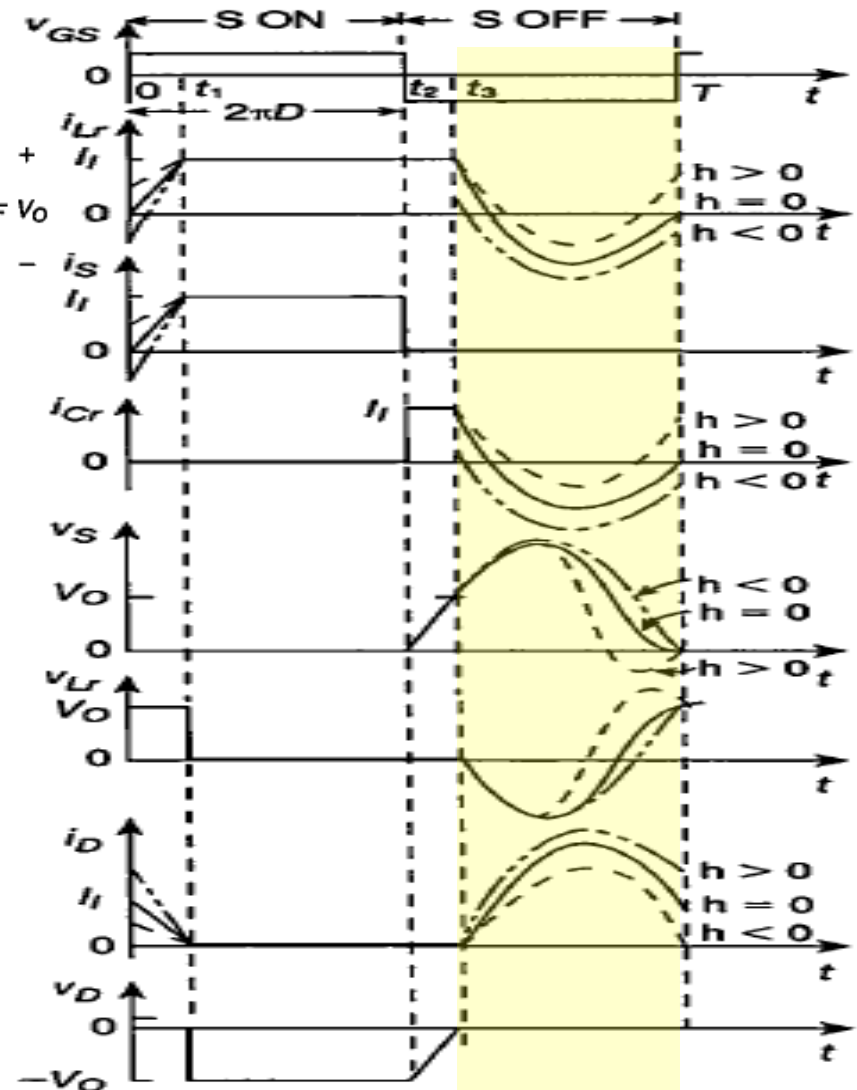
The diode current waveform is

$$\frac{i_D}{I_I} = 1 - \cos \frac{\omega_s t - \omega_s t_3}{A}.$$

The switch voltage waveform is

$$\frac{v_S}{V_I} = \frac{M_{VDC}}{Q} \sin \frac{\omega_s t - \omega_s t_3}{A} + 1.$$

ZVS condition: $M_{VDC}/Q \geq 1$, depend on load condition



Derivation of the duty cycle

For ZVS operation, $v_S(2\pi)=v_S(0)=0$. Also, $i_{Lr}(2\pi)=i_{Lr}(0)=hI_p$. Hence, the relationships among M_{VDC} , Q , and h are given by a set of equation

$$h = \cos \left[\frac{2\pi(1-D)}{A} - \frac{Q}{M_{VDC}} \right] \quad \frac{Q}{M_{VDC}} = -\sin \left[\frac{2\pi(1-D)}{A} - \frac{Q}{M_{VDC}} \right].$$

This set of equations and trigonometric identity yield

$$\left(\frac{Q}{M_{VDC}} \right)^2 + h^2 = 1$$

Producing

$$\frac{Q}{M_{VDC}} = \sqrt{1-h^2} \quad h = \pm \sqrt{1 - \left(\frac{Q}{M_{VDC}} \right)^2}.$$

The duty cycle is given by

$$\begin{aligned} D &= 1 - \frac{1}{2\pi} \left(\frac{f_s}{f_0} \right) \left[2\pi n - \arccos h + \sqrt{1-h^2} \right] \\ &= 1 - \frac{1}{2\pi} \left(\frac{f_s}{f_0} \right) \left[2\pi n - \arccos \sqrt{1 - \left(\frac{Q}{M_{VDC}} \right)^2} + \frac{Q}{M_{VDC}} \right] \end{aligned}$$

For $h = 0$, *$h = 0$ means $v_S(2\pi)=0$. Also, $i_{Lr}(2\pi)=i_{Lr}(0)=0$, ZVS with main switch & ZCS with diode*

$$D = 1 - \frac{(4n-1)\pi + 2}{4\pi} \left(\frac{f_s}{f_0} \right).$$

For $n = 1$,

$$D = 1 - \frac{3\pi + 2}{4\pi} \left(\frac{f_s}{f_0} \right) = 1 - 0.9092 \left(\frac{f_s}{f_0} \right).$$

DC Voltage Transfer Function

The DC output current is

$$I_O = \frac{1}{2\pi} \int_0^{2\pi} i_D d(\omega_s t) = I_I \left[1 - D + \frac{(1-h^2)}{4\pi\sqrt{1-h^2}} \right].$$

Assuming that the converter is lossless, $I_O V_O = I_I V_I$. Hence, the DC voltage transfer function is given by

$$\begin{aligned} M_{VDC} = \frac{V_O}{V_I} = \frac{I_I}{I_O} &= \frac{1}{1 - D + \frac{A(1-h^2)}{4\pi\sqrt{1-h^2}}} \\ &= \frac{2\pi}{A \left[2\pi n - \arccos h + \sqrt{1-h^2} + \frac{(1-h)^2}{2\sqrt{1-h^2}} \right]}. \end{aligned}$$

Thus,

$$\begin{aligned} M_{VDC} &= \frac{2\pi}{\left(\frac{f_s}{f_0}\right) \left\{ (2n-1)\pi + \frac{Q}{2M_{VDC}} + \arccos \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2} + \frac{M_{VDC}}{Q} \left[1 + \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2} \right] \right\}} \quad \text{for } h \leq 0 \\ M_{VDC} &= \frac{2\pi}{\left(\frac{f_s}{f_0}\right) \left\{ 2n\pi + \frac{Q}{2M_{VDC}} - \arccos \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2} + \frac{M_{VDC}}{Q} \left[1 - \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2} \right] \right\}} \quad \text{for } h \geq 0. \end{aligned}$$

For $h = 0$,

$$M_{VDC} = \frac{1}{1-D} = \frac{4\pi}{[(4n-1)\pi + 2] \left(\frac{f_s}{f_0}\right)}$$

which for $n = 1$ becomes

$$M_{VDC} = \frac{1}{1-D} = \frac{4\pi}{(3\pi + 2) \left(\frac{f_s}{f_0}\right)} = \frac{1.1}{\left(\frac{f_s}{f_0}\right)}.$$

Current and Voltage Stresses

The switch peak current and voltage are

$$I_{SM} = I_I = M_{VDC} I_O$$

and

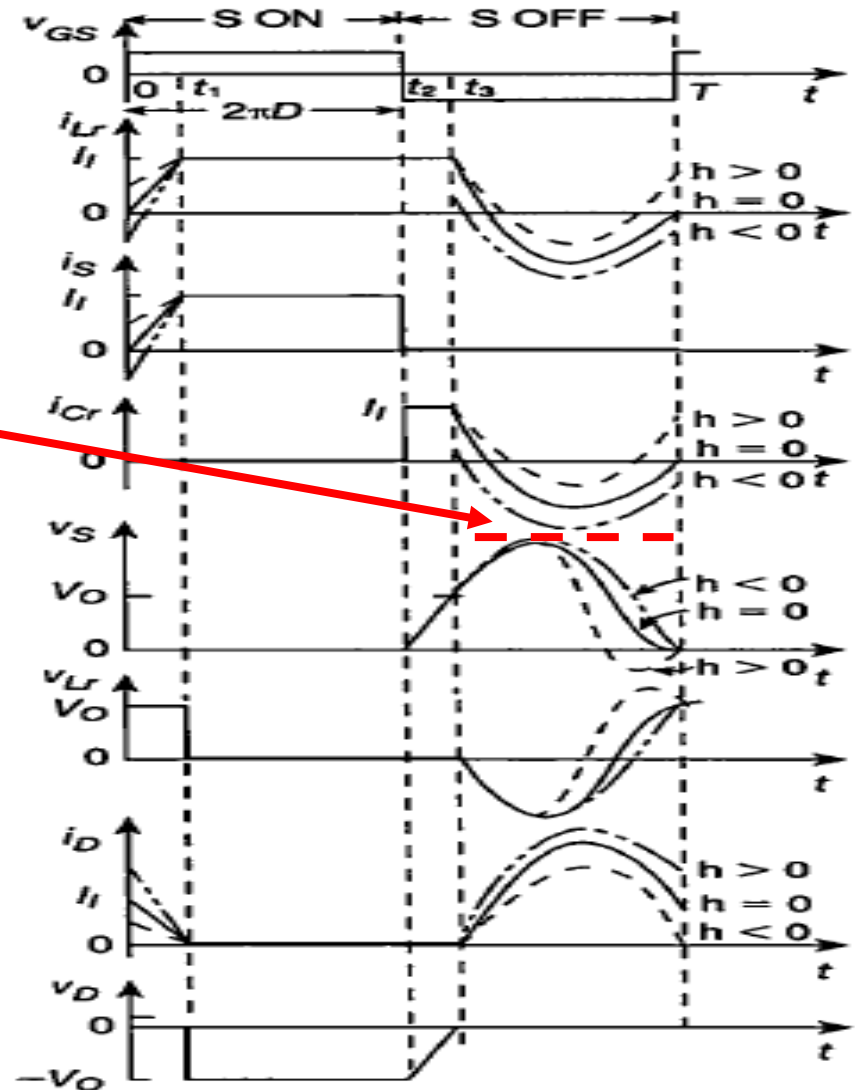
$$V_{SM} = \left(\frac{M_{VDC}}{Q} + 1 \right) V_O = \left(\frac{Z_o M_{VDC}}{R_L} + 1 \right) V_O.$$

The diode peak current and voltage are

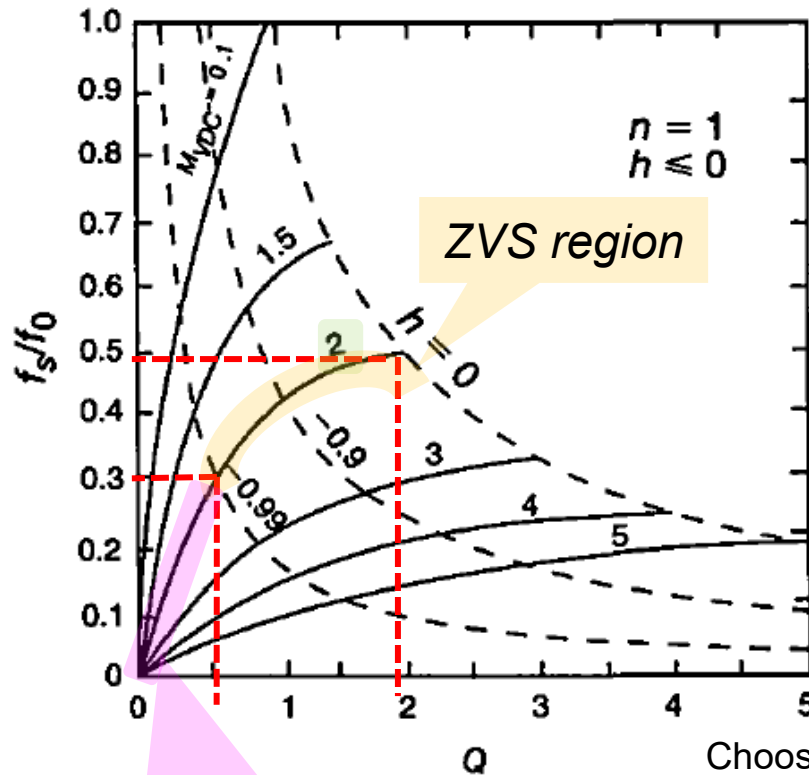
$$I_{DM} = 2I_I = 2M_{VDC} I_O$$

and

$$V_{DM} = V_O.$$



The relationship between voltage gain, switching frequency and load condition.



$$Q = \frac{R_L}{\omega_0 L_r} = \omega_0 C_r R_L = \frac{R_L}{\sqrt{\frac{L_r}{C_r}}} = \frac{A R_L}{\omega_s L_r} = \frac{\omega_s C_r R_L}{A}$$

$$h = \pm \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2}$$

ZVS condition: $M_{VDC}/Q \geq 1$, depend on load condition, Thus, $h = -1 \sim 1$

$$M_{VDC} = \frac{2\pi}{\left(\frac{f_s}{f_0}\right) \left\{ (2n-1)\pi + \frac{Q}{2M_{VDC}} + \arccos \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2} + \frac{M_{VDC}}{Q} \left[1 + \sqrt{1 - \left(\frac{Q}{M_{VDC}}\right)^2} \right] \right\}}$$
 for $h \leq 0$

$$M_{VDC} = \frac{1}{1-D} = \frac{4\pi}{(3\pi+2)\left(\frac{f_s}{f_0}\right)} = \frac{1.1}{\left(\frac{f_s}{f_0}\right)} \quad \text{for } h = 0$$

Choose $M_{VDC}=2$ curve for example:

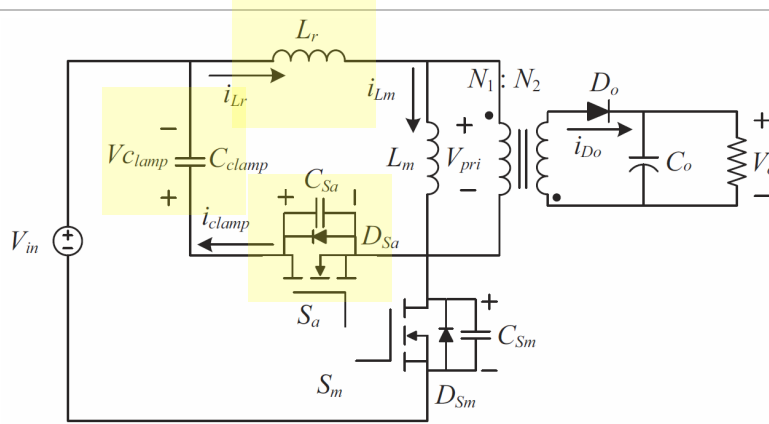
- Under the fixed voltage gain condition, the converter must reduce the switching frequency to meet the voltage regulation rate when the loading is increased.
- The load can only meet zero voltage switching within a specific range.

Course outline – Week 5

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Active-Clamp

(Choose Active-Clamp Flyback CCM for example)

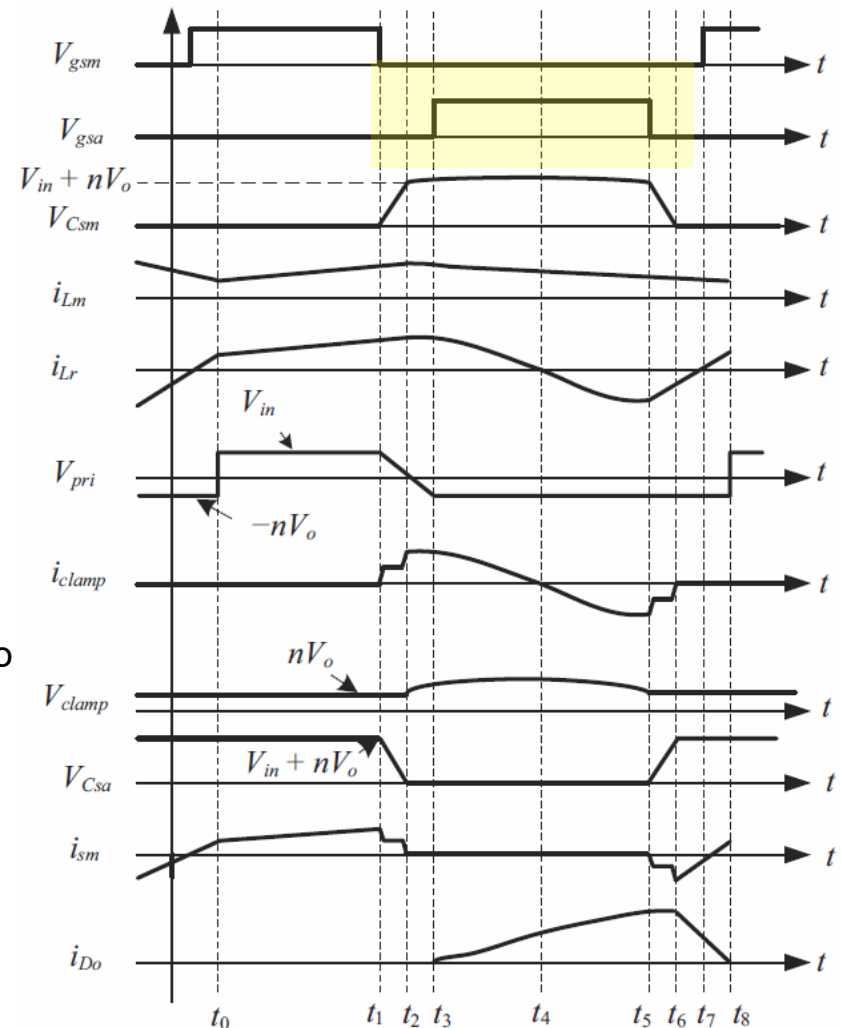


Advantage:

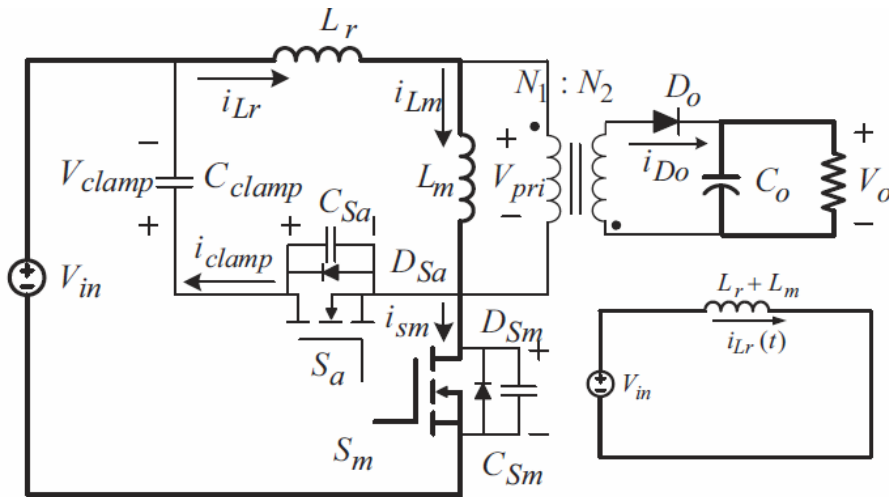
1. The auxiliary switch and the main switch are complementary, and the control signal of the auxiliary switch is simple to realize
2. Both the main switch and the auxiliary switch can achieve zero voltage conduction
3. Recovery of transformer leakage inductance energy to increase efficiency
4. Suppress the maximum cross voltage of the main switch (eliminate voltage spike)
5. Fixed switching frequency

Shortcoming:

1. The peak current of the output diode increases
2. The zero voltage cut range is limited by the load condition and the magnitude of the resonance inductance

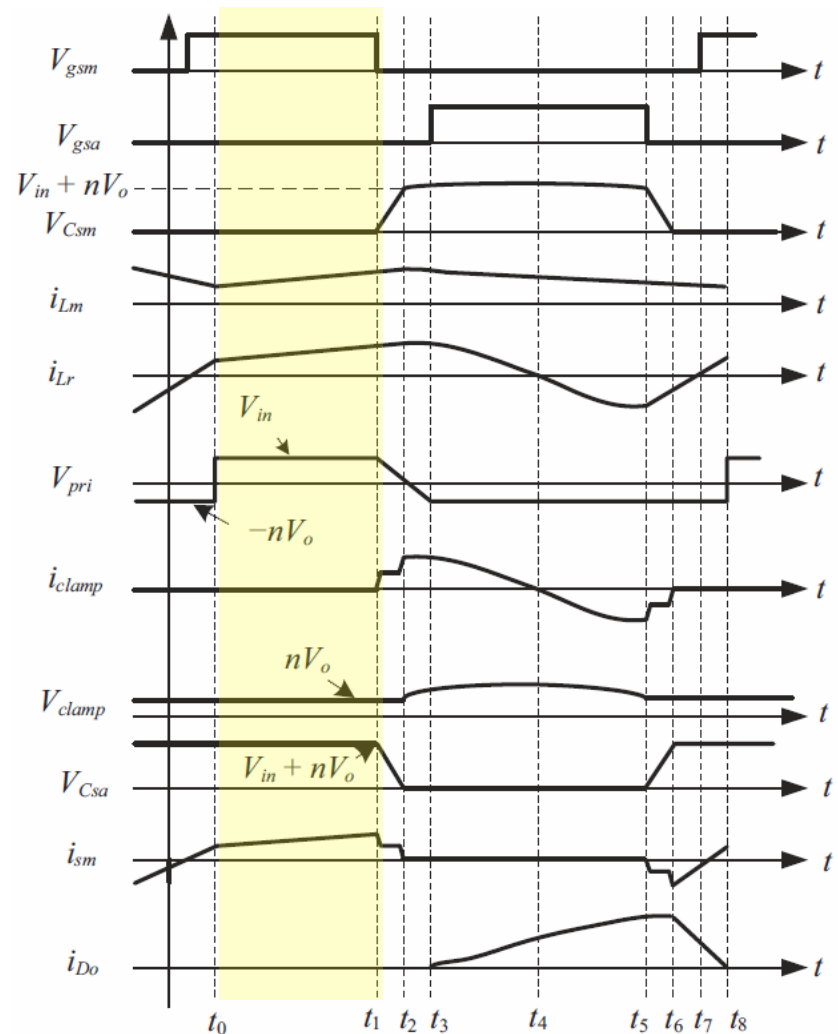


Active Clamp Flyback CCM - $t_0 \sim t_1$

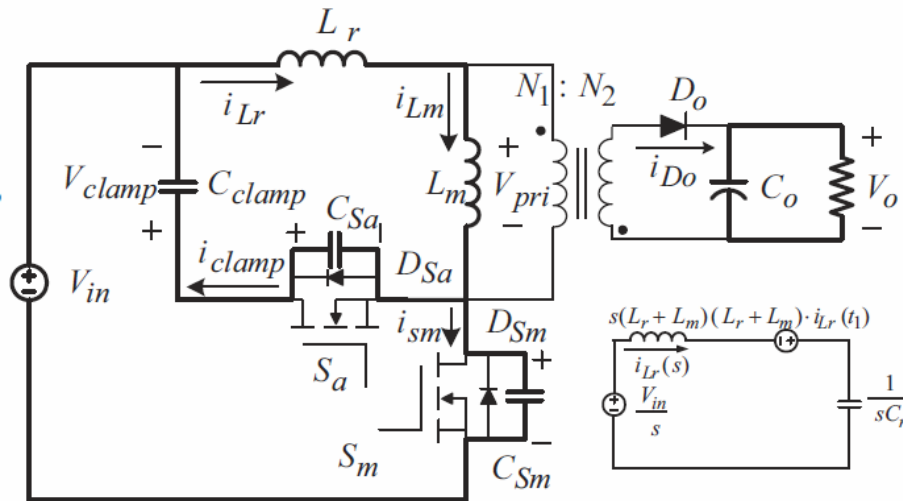


• State 1(Linear charging interval):

- $i_{Lr} = i_{Lm}$ current increase linearly.
- $V_{in} = (L_m + L_r) \cdot di_{Lr} / dt$

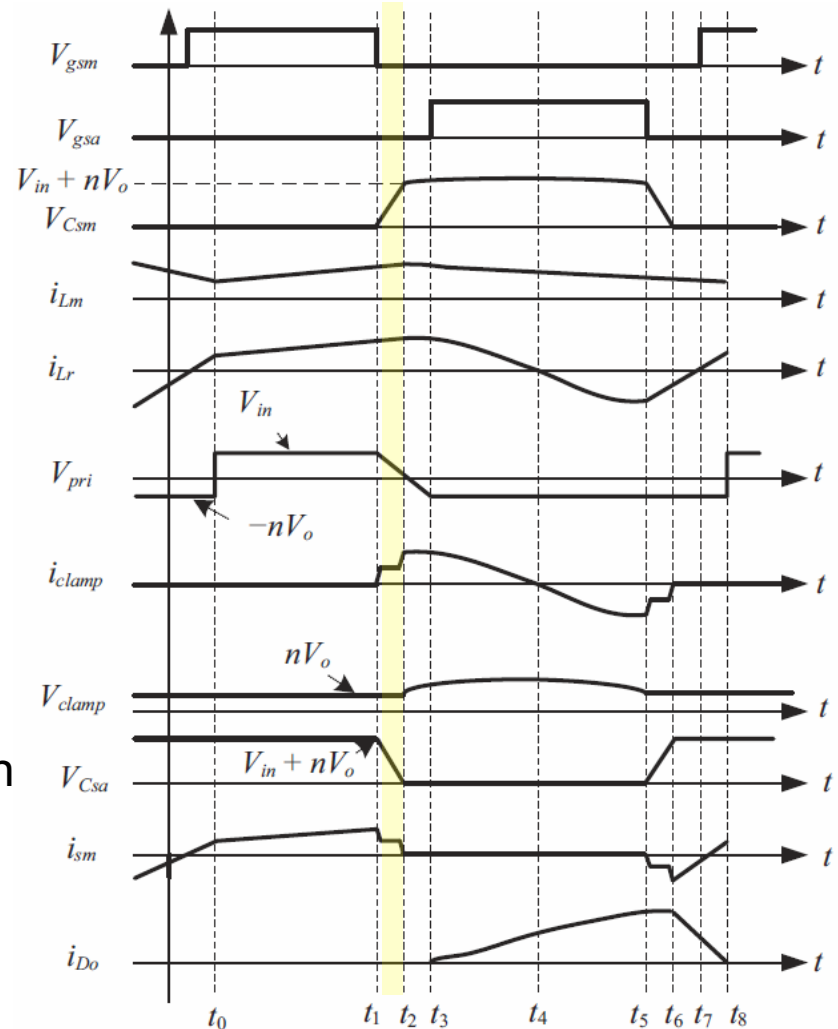


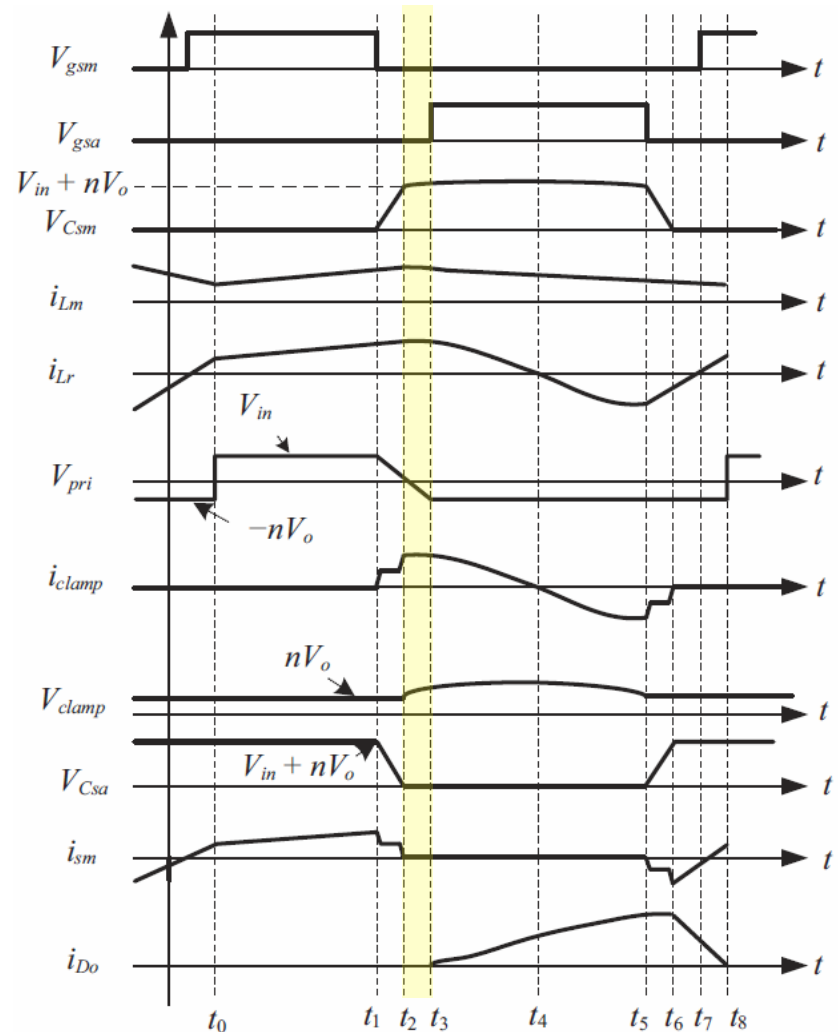
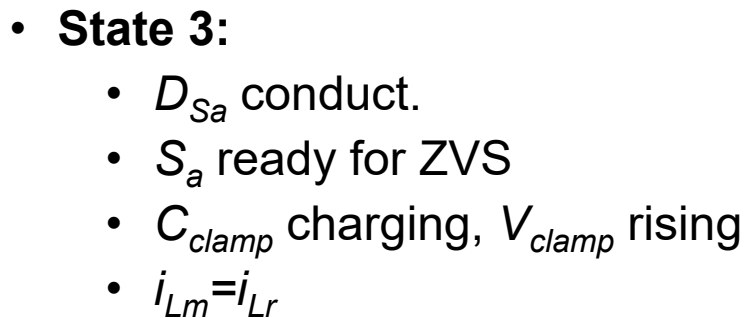
Active Clamp Flyback CCM – $t_1 \sim t_2$



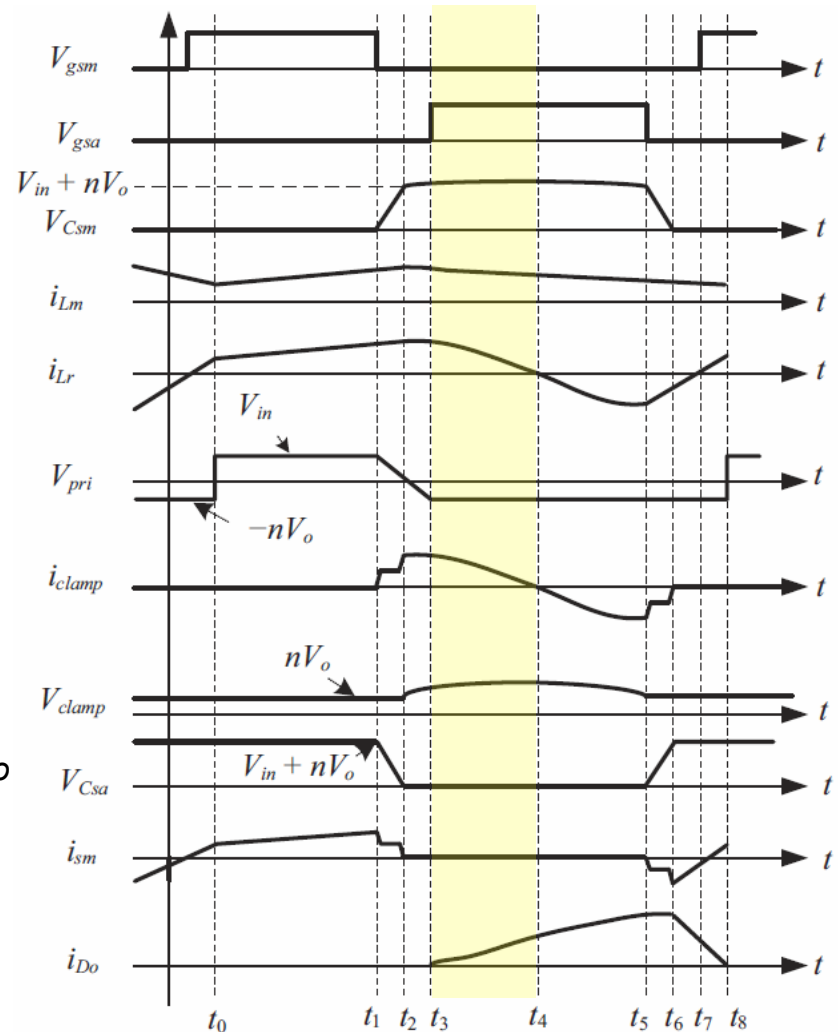
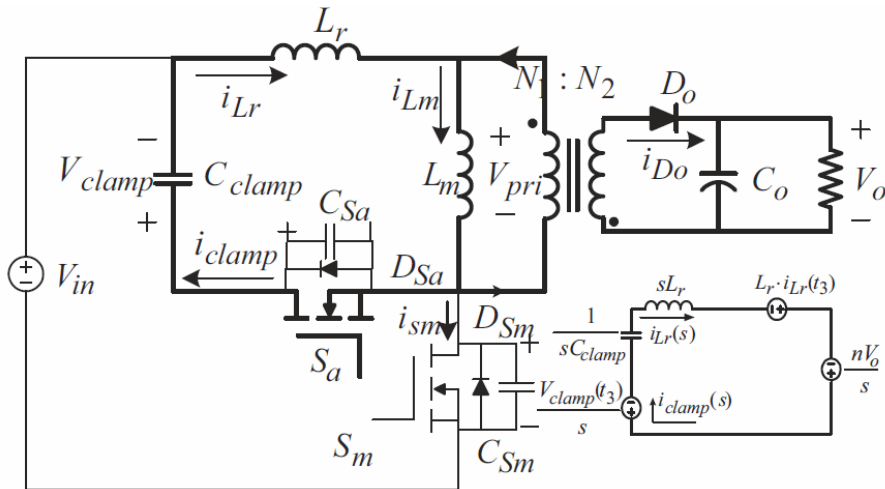
• State 2(Resonant interval) :

- S_m turns off
- L_r , L_m , C_{Sm} , C_{Sa} , C_{clamp} start to resonan
- Interval ends with $V_{Csm} = V_{in} + V_{clamp}$



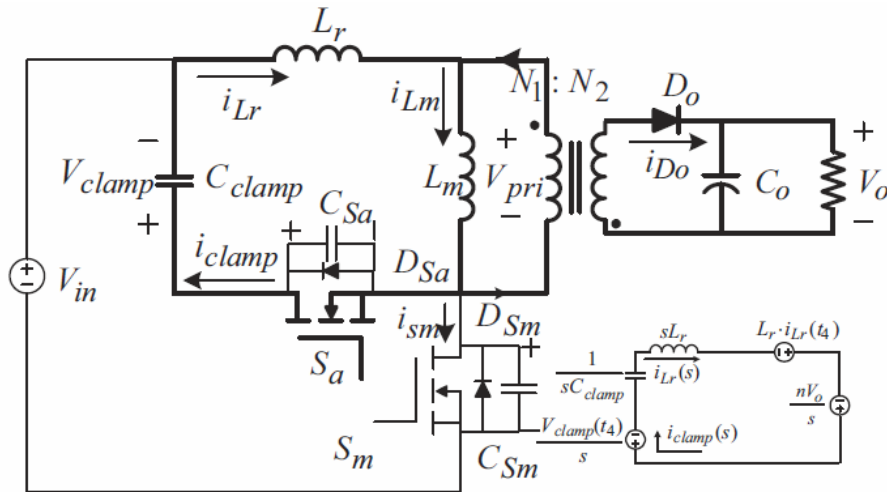


Active Clamp Flyback CCM – $t_3 \sim t_4$



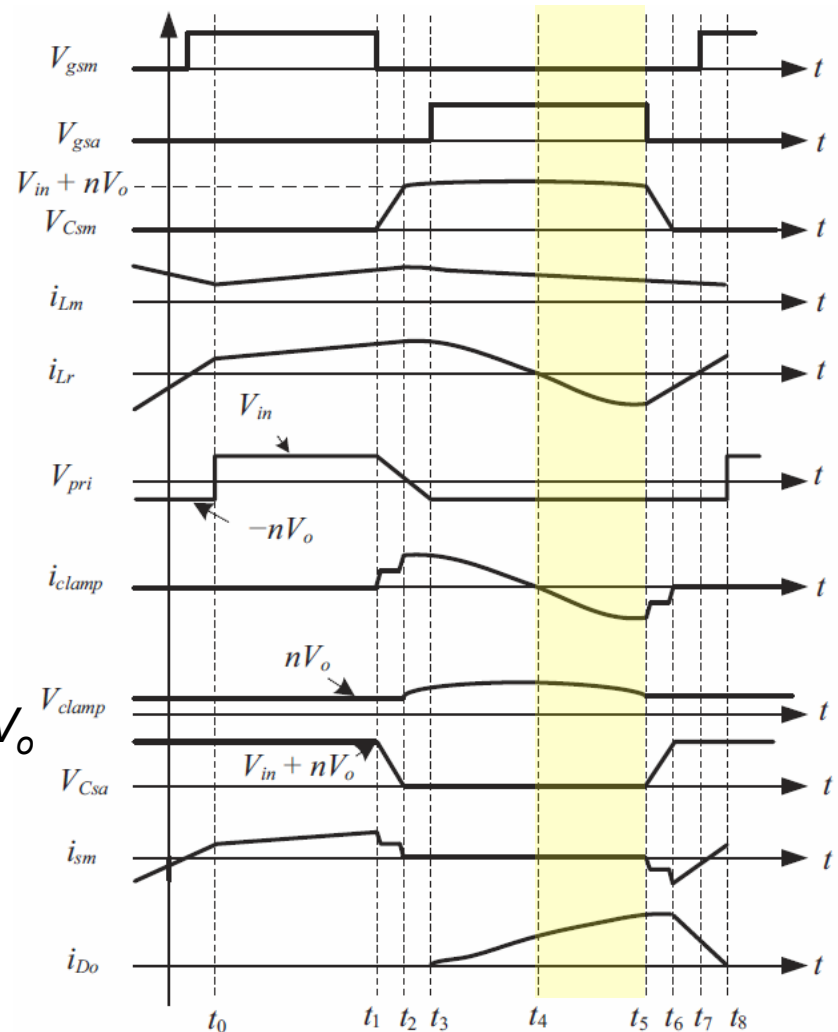
- **State 4 (Start power deliver interval):**
 - S_a conduct with ZVS
 - $i_{Lm} > i_{Lr} > 0$, $i_{clamp} > 0$, V_{clamp} rising
 - D_o conduct with $i_{Lm} - i_{Lr} > 0$, $V_{Lm} = N_1/N_2 \cdot V_o$
 L_r resonant with C_{clamp}
 Energy transfer to output
 - $i_{Do} = (i_{Lm} - i_{Lr}) \cdot N_1/N_2$

Active Clamp Flyback CCM – $t_4 \sim t_5$

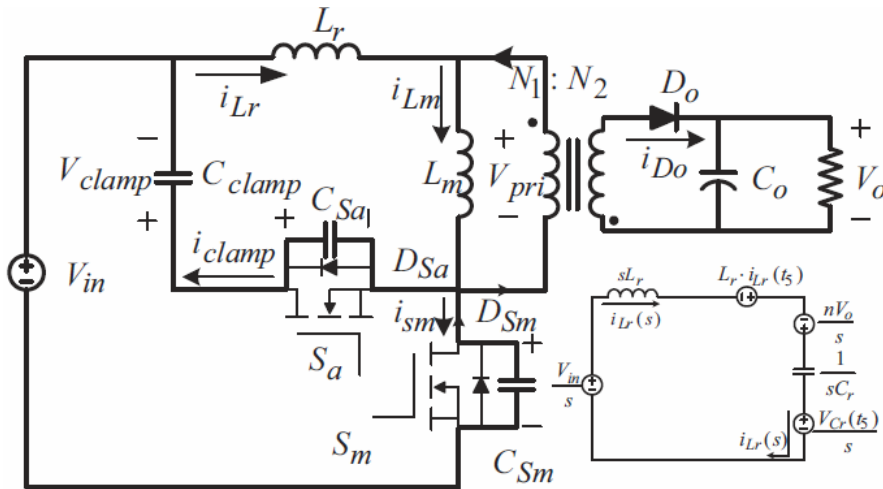


• State 5 (Power deliver interval):

- $i_{Lm} > 0 > i_{Lr}$, $i_{Lr} < 0$, $i_{clamp} < 0$, V_{clamp} falling
- D_o conduct with $i_{Lm} - i_{Lr} > 0$, $V_{Lm} = N_1/N_2 * V_o$
 L_r resonant with C_{clamp}
 Energy transfer to output
- $i_{Do} = (i_{Lm} - i_{Lr}) * N_1/N_2$
- Notice the $i_{Do} \geq i_{Lm} * N_1/N_2$

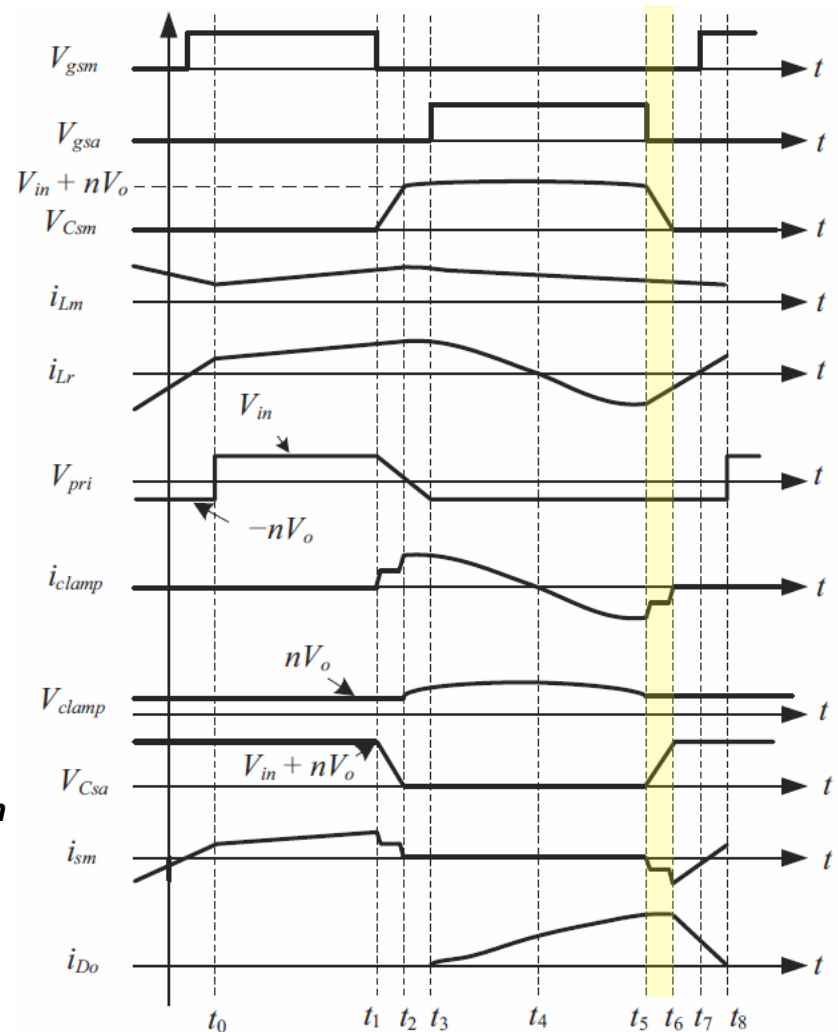


Active Clamp Flyback CCM – $t_5 \sim t_6$

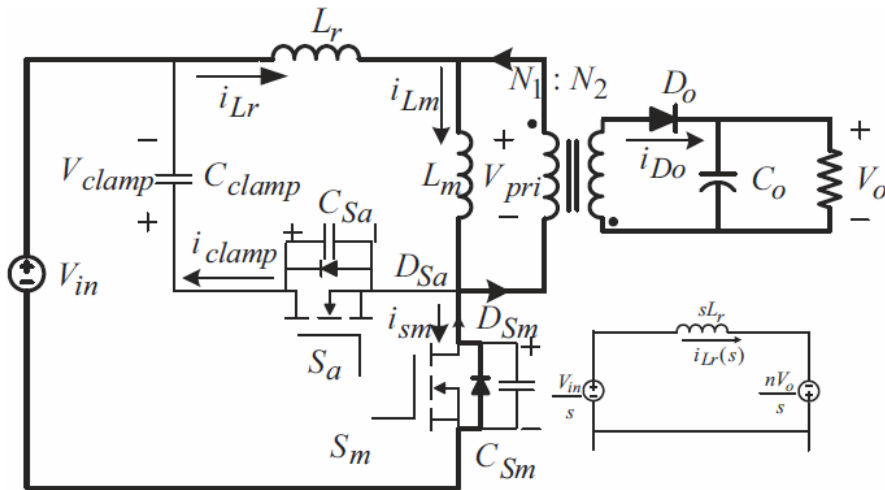


• State 6 (Resonant interval):

- S_a turns off
- L_r , C_{Sm} , C_{Sa} , C_{clamp} start to resonant.
- $i_{Lm} > 0 > i_{Lr}$, $i_{Lr} < 0$, $i_{sm} < 0$, **discharge C_{sm}**
- Energy still deliver to output,
- $i_{Do} = (i_{Lm} - i_{Lr}) * N_1 / N_2$

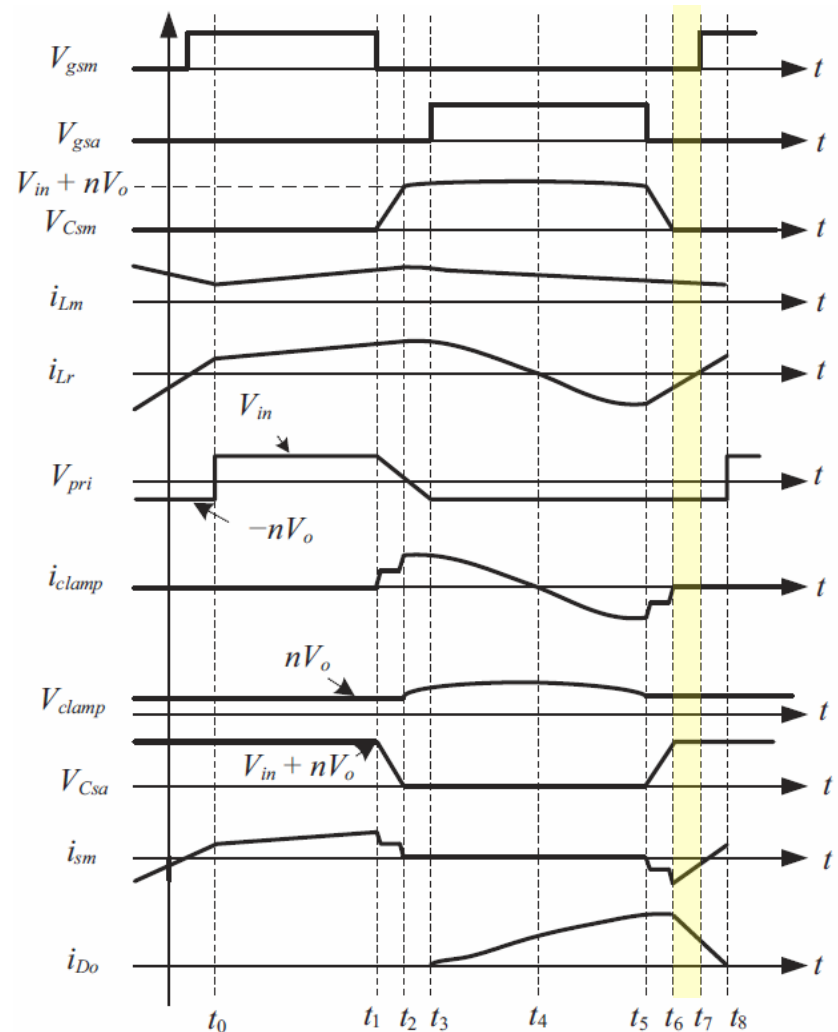


Active Clamp Flyback CCM – $t_6 \sim t_7$

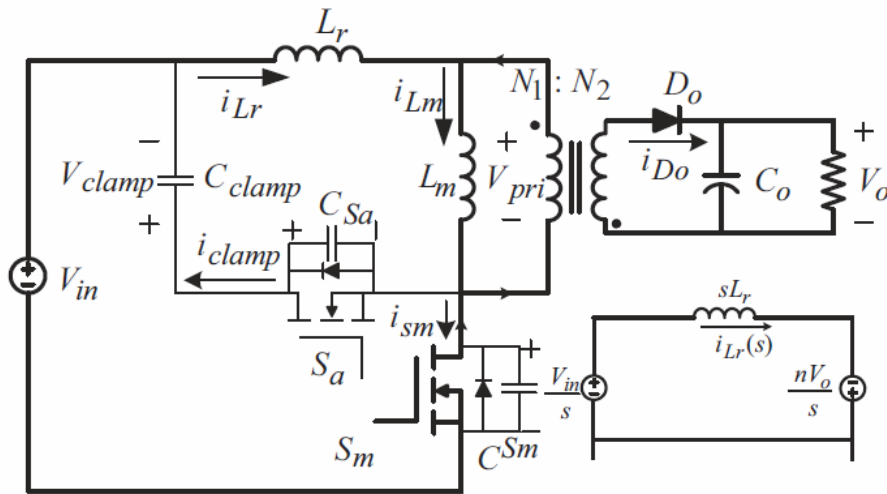


• State 7 (ZVS interval):

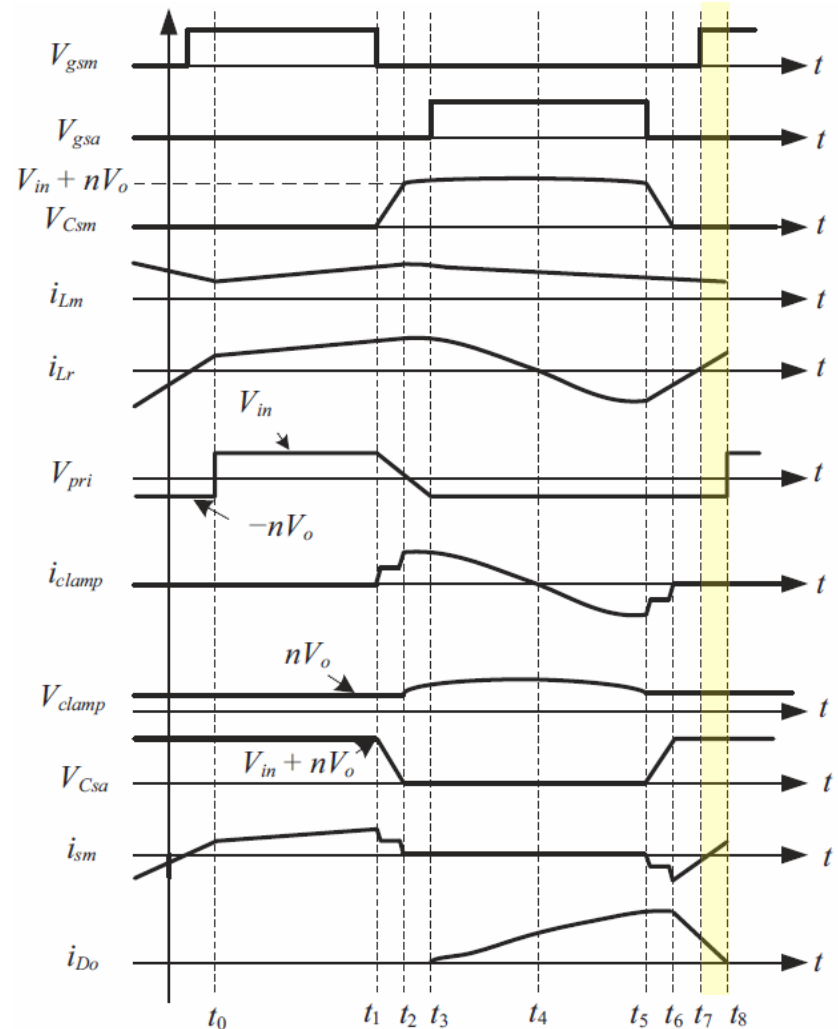
- D_{Sm} conduct.
- i_{Lr} increase rapidly, i_{Lm} still decrease
- $i_{Do} > 0$, D_o still conduct
- Still transfer energy to output, but i_{Do} linearly decrease



Active Clamp Flyback CCM – $t_7 \sim t_8$



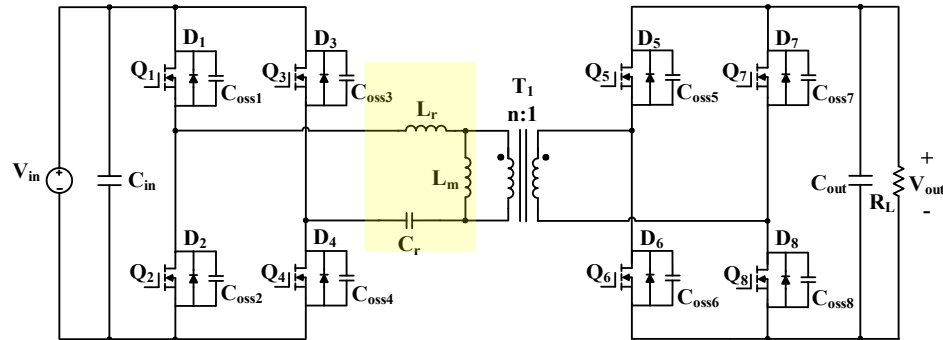
- State 8:
 - S_m conduct with ZVS
 - D_o turns off when $i_{Lr} = i_{Lm}$
 - $V_{in} - (N_1/N_2)V_o = L_r \cdot di_{Lr}/dt$



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Resonant Converter (Choose LLC converter for example)

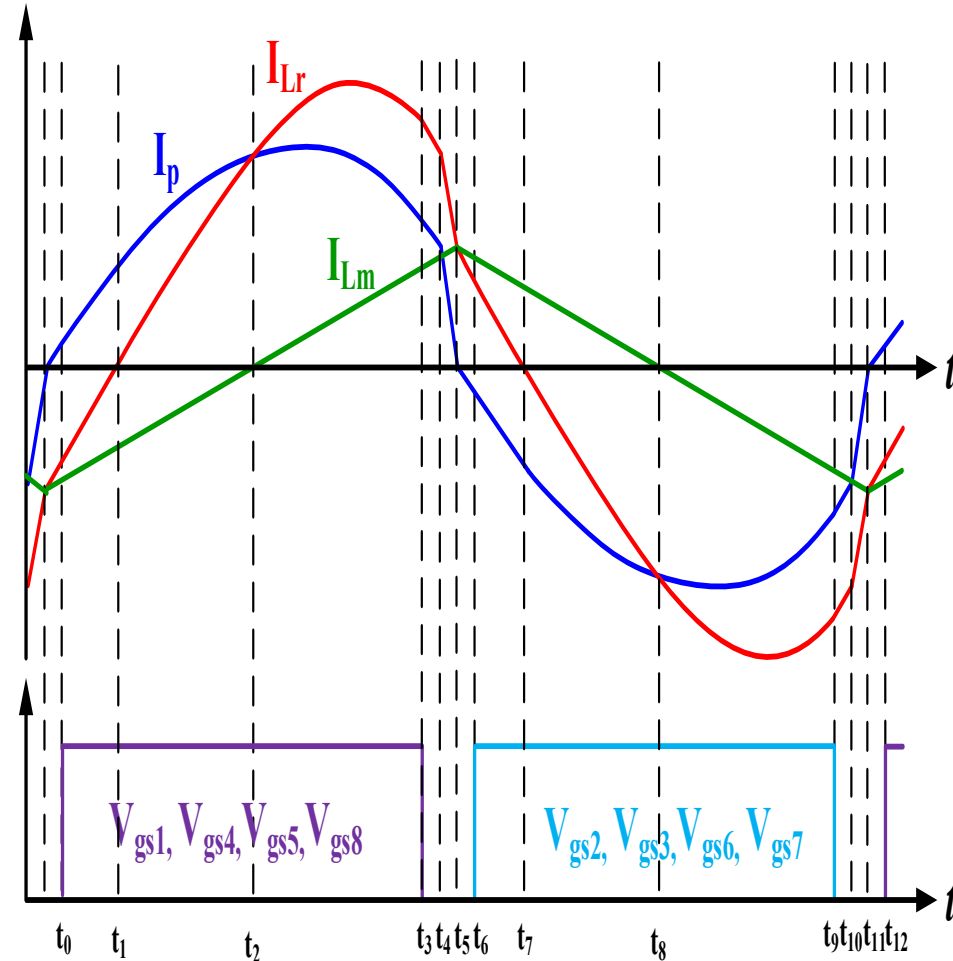


Advantage:

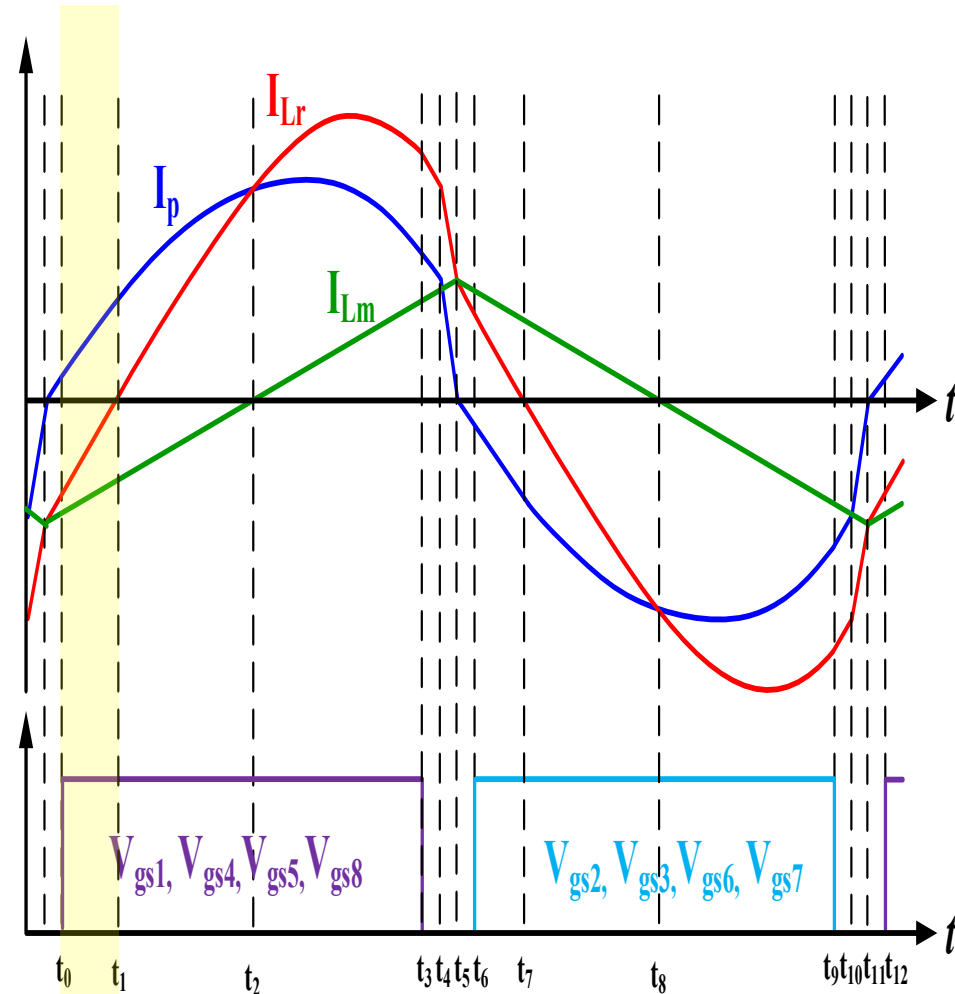
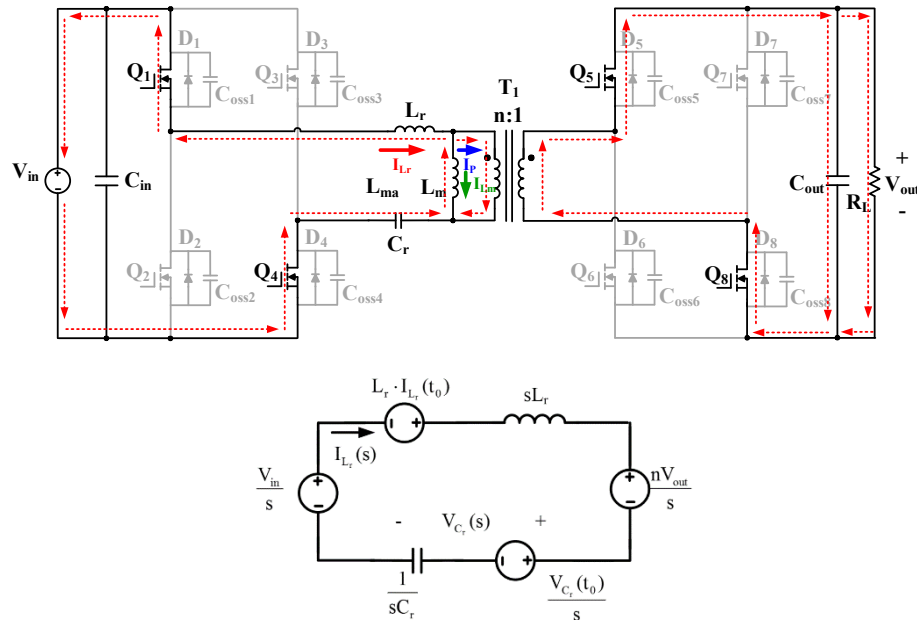
1. Switch with ZVS, rectifier with ZCS (LLC Mode), increase converter efficiency.
2. LLC converter can still maintain the switches ZVS at light load (LLC uses resonant inductor current to achieve zero voltage switching)

Shortcoming:

1. The characteristics of the converter are not easy to design in a wide range of input and output applications
2. The frequency conversion control is purely used, and the switching frequency needs to be increased at light load to reduce the converter efficiency
3. Controller must note that the converter must not enter the impedance range of the capacitor, and additional protection is required
4. The rectified current's peak and RMS values are higher, increasing the conduction loss and voltage ripple.
5. Variable frequency control



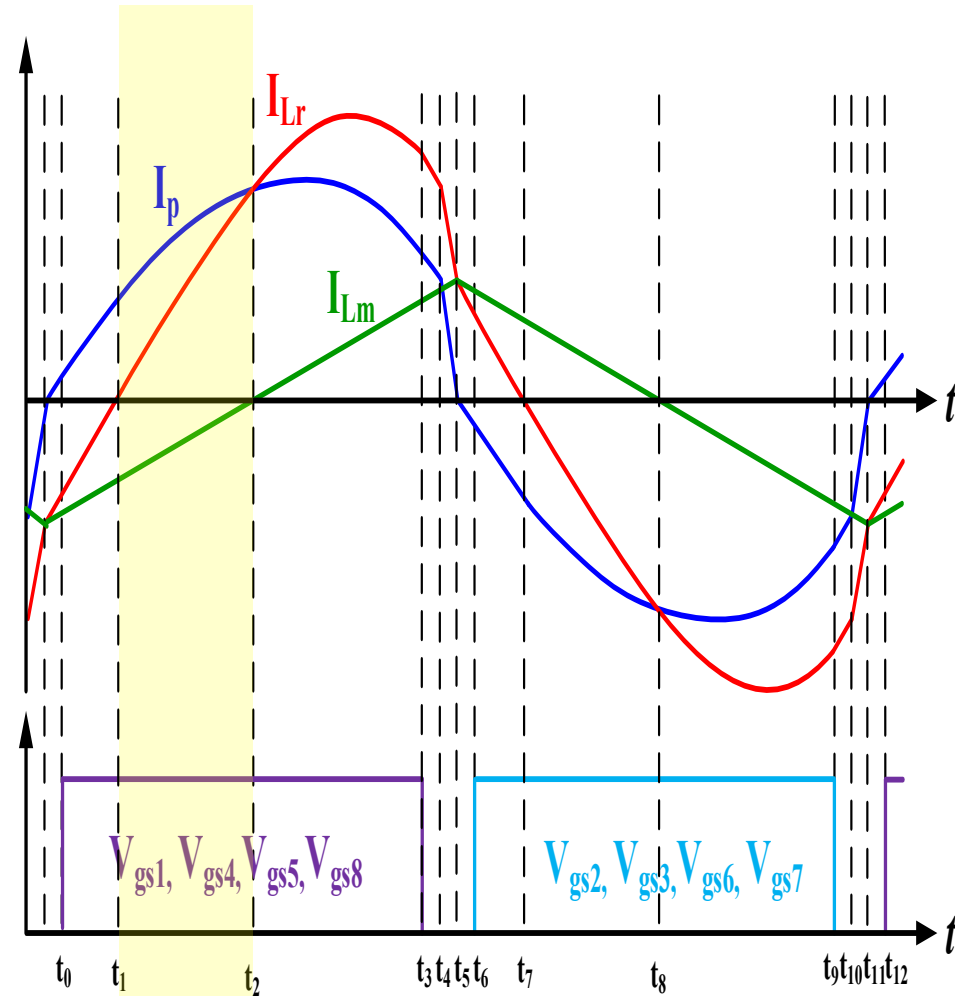
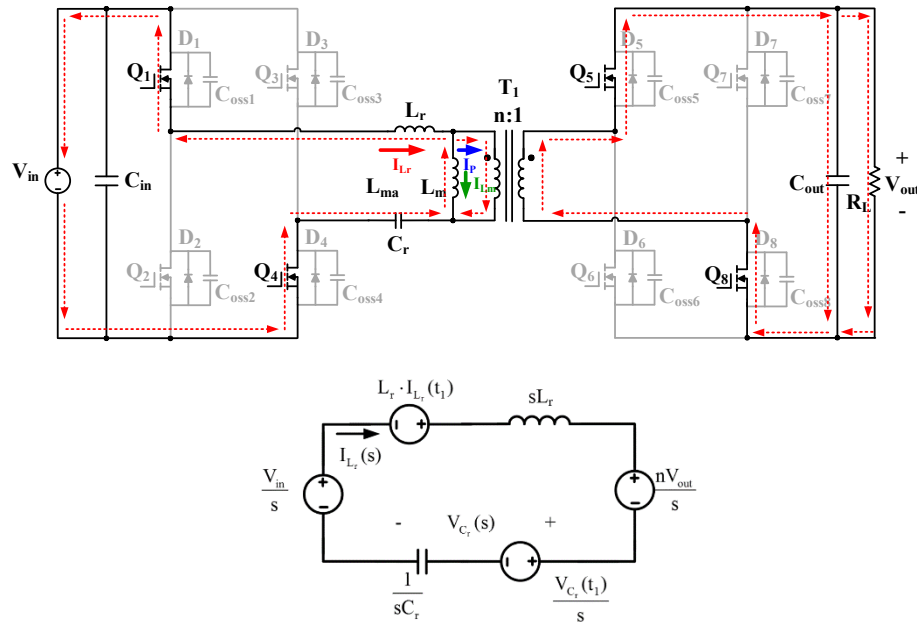
LLC Converter – $t_0 \sim t_1$



Interval 1 ($t_0 \sim t_1$):

1. $i_{Lm}(t_0) = i_{Lr}(t_0) < 0$
2. $v_{Lm} = nV_{out}$, $i_{Lm}(t)$ increase linearly
3. $i_p(t) = i_{Lr}(t) - i_{Lm}(t)$, power delivery

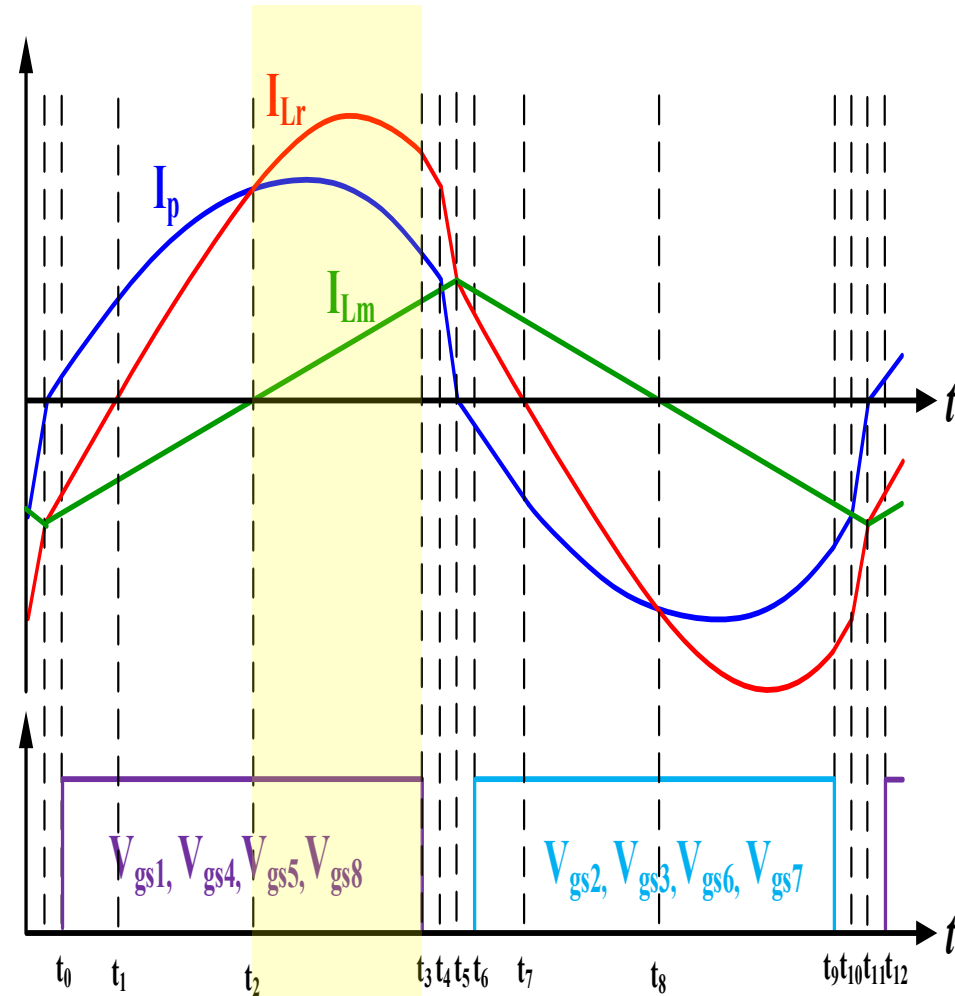
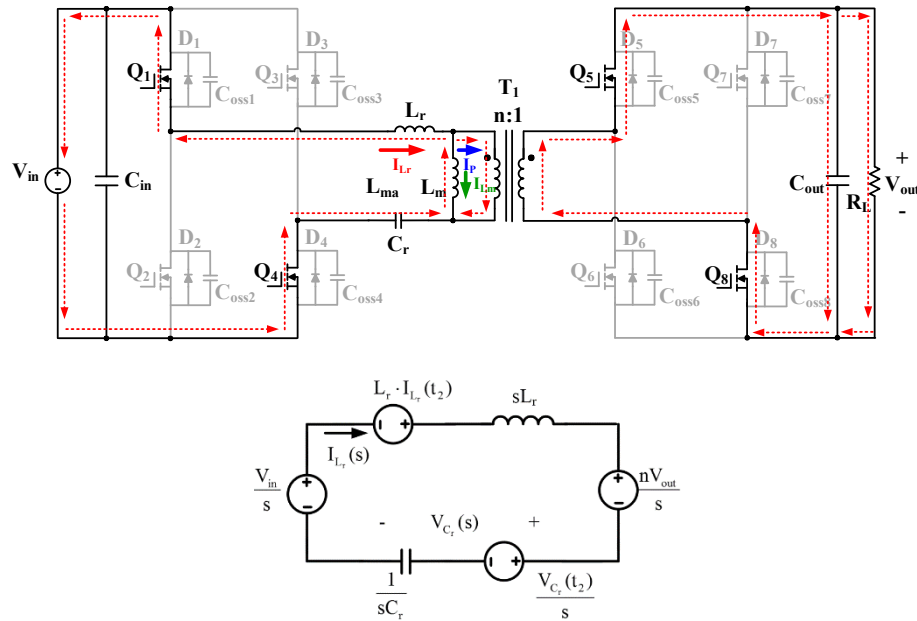
LLC Converter – $t_1 \sim t_2$



Interval 2 ($t_1 \sim t_2$):

1. $i_{Lm}(t_1) < 0, i_{Lr}(t_1) = 0$
2. $v_{Lm} = nV_{out}$, $i_{Lm}(t)$ increase linearly
3. $i_p(t) = i_{Lr}(t) - i_{Lm}(t)$, power delivery
4. $i_{Lm}(t_2) = 0$, The polarity of i_{Lm} start to reverse

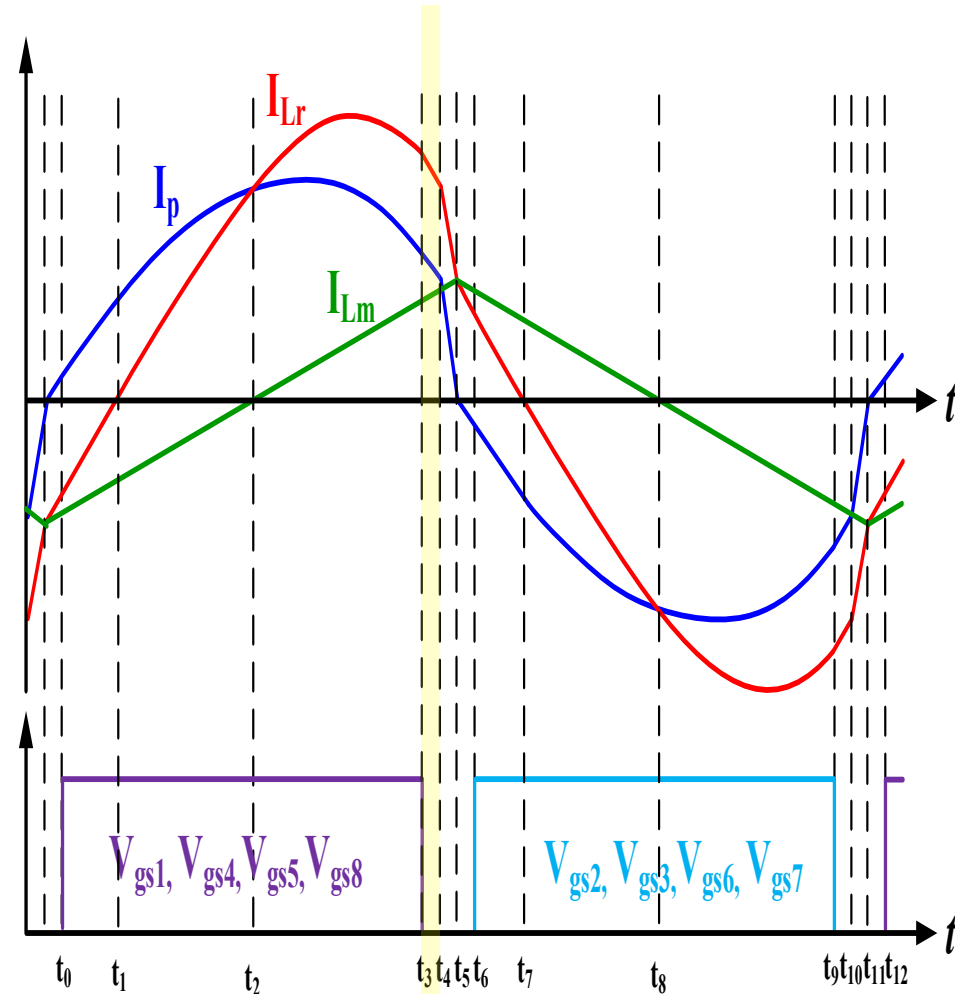
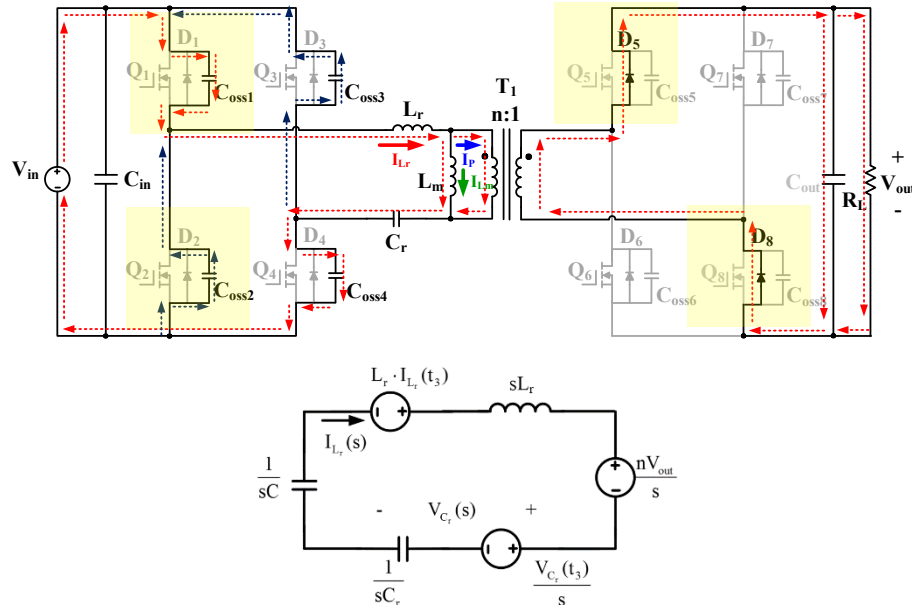
LLC Converter – $t_2 \sim t_3$



Interval 3 ($t_2 \sim t_3$):

1. PWM turns off @ $t=t_3$
2. $v_{Lm} = nV_{out}$, $i_{Lm}(t)$ increase linearly
3. $i_p(t) = i_{Lr}(t) - i_{Lm}(t)$, power delivery

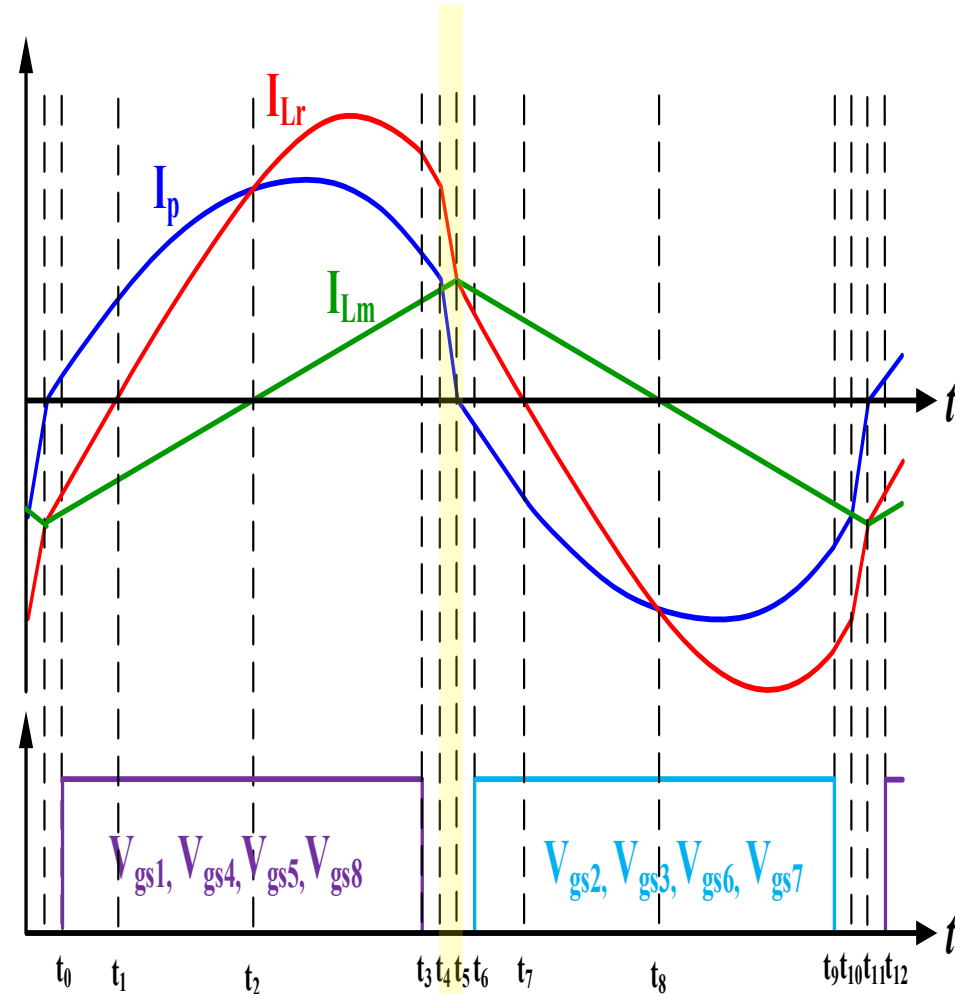
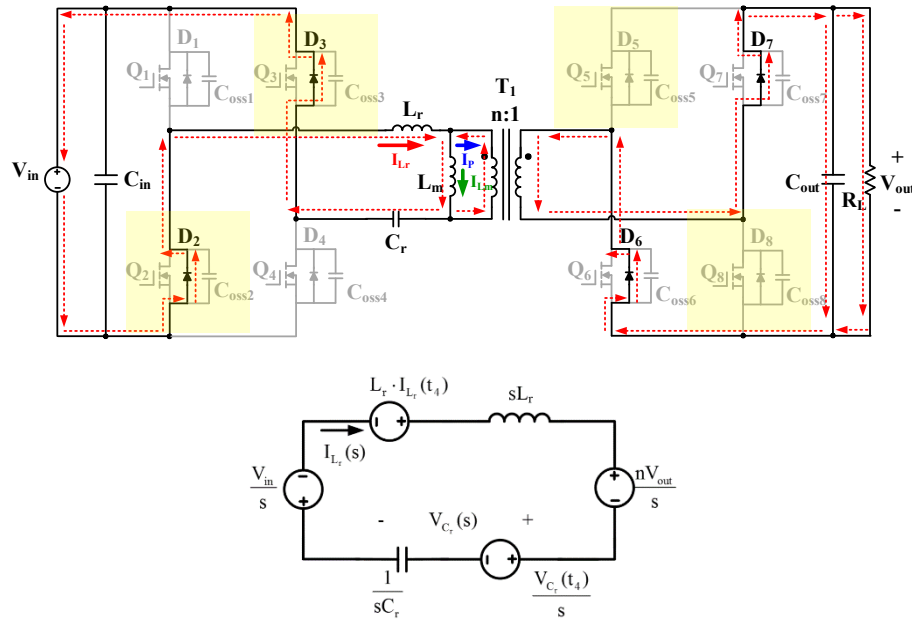
LLC Converter – $t_3 \sim t_4$



Interval 4 ($t_3 \sim t_4$):

1. PWM turns off @ $t=t_3$, dead time interval
2. $i_p(t) > 0$, D_5, D_8 conduct naturally
3. $v_{Lm} = nV_{out}$, $i_{Lm}(t)$ increase linearly
4. C_{oss} , L_r , C_r start resonant
5. $i_{Lr}(t_3) > 0$, Charge C_{oss1} , discharge C_{oss2}

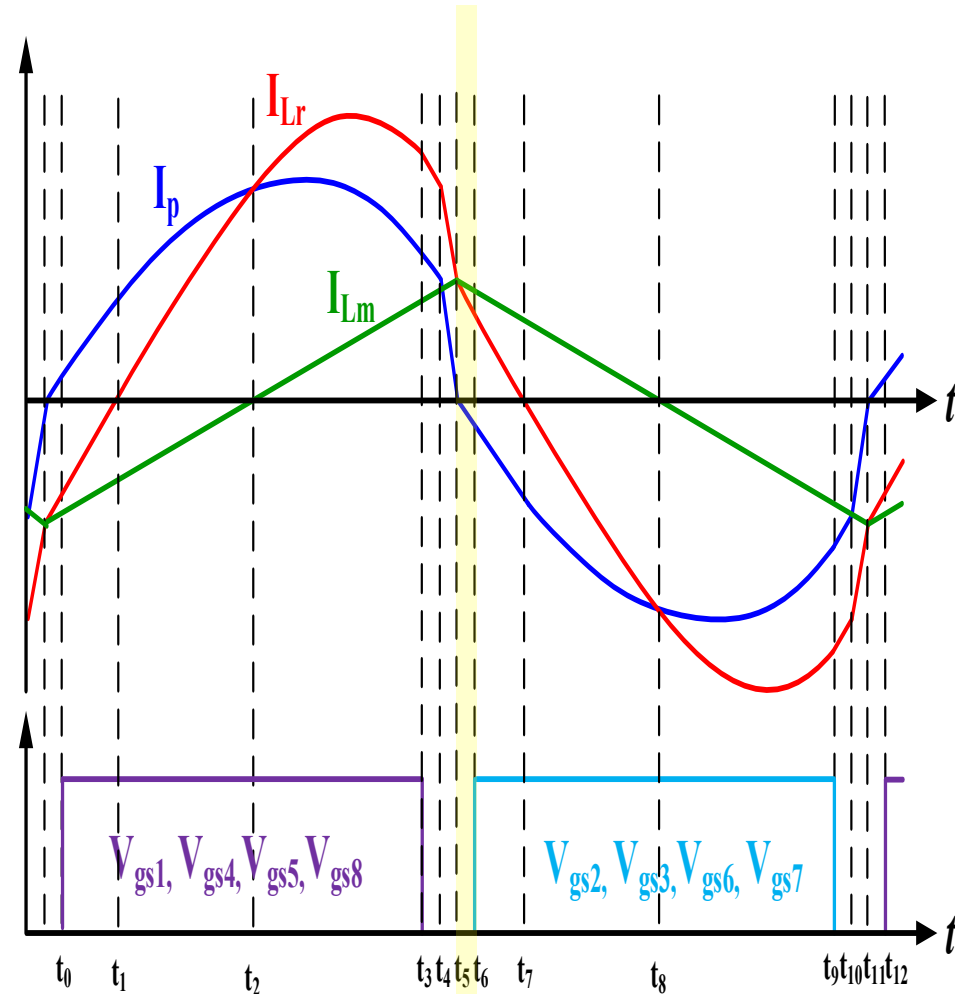
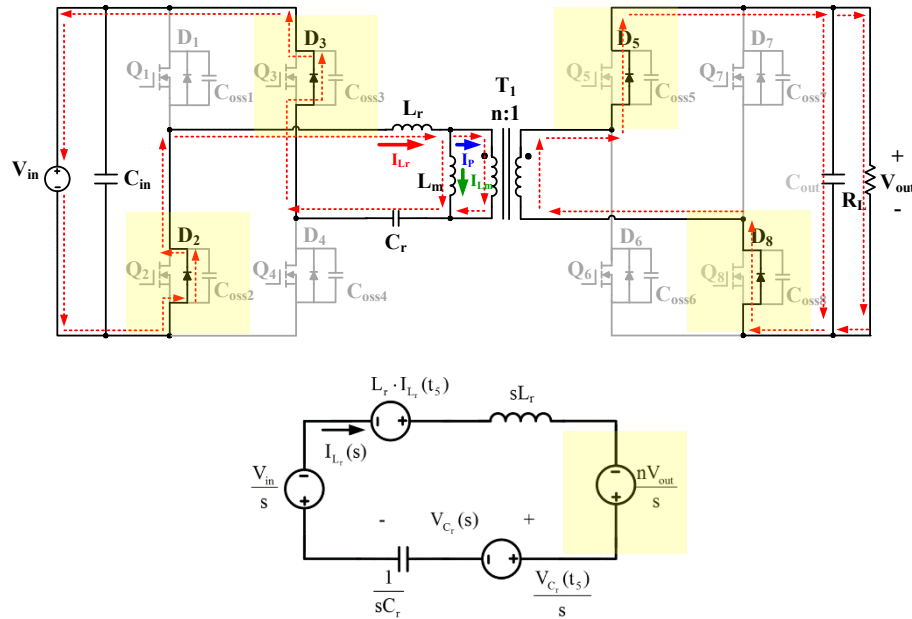
LLC Converter – $t_4 \sim t_5$



Interval 4 ($t_4 \sim t_5$):

1. Body diode D_2, D_3 conduct
2. Primary side resonant tank input voltage reverse
3. $i_{Lr}(t)$ decreases significantly
4. $i_p(t) > 0$, D_5, D_8 conduct naturally
5. $v_{Lm} = nV_{out}$, $i_{Lm}(t)$ increase linearly
6. Interval ends with $i_p(t_5) = 0A$

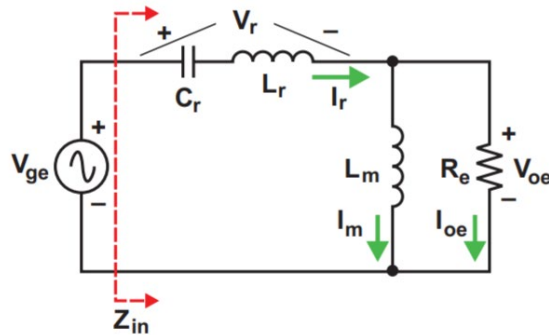
LLC Converter – $t_5 \sim t_6$



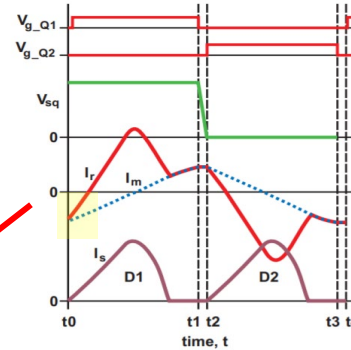
Interval 5 ($t_5 \sim t_6$):

1. $i_{Lr}(t) < i_{Lm}(t)$, $i_p(t) < 0$ (ignore $C_{oss5,6,7,8}$ resonant period)
2. Secondary side D_6, D_7 conduct naturally
3. $v_{Lm} = -nV_{out}$, $i_{Lm}(t)$ decrease linearly
4. $i_p(t) = i_{Lr}(t) - i_{Lm}(t)$, power delivery

The relationship with ZVS & input impedance



a. Input impedance.

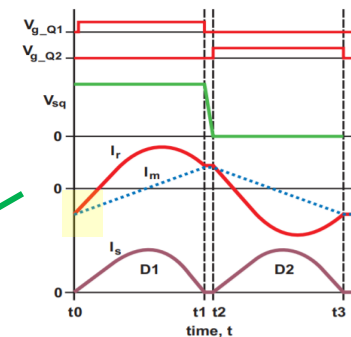
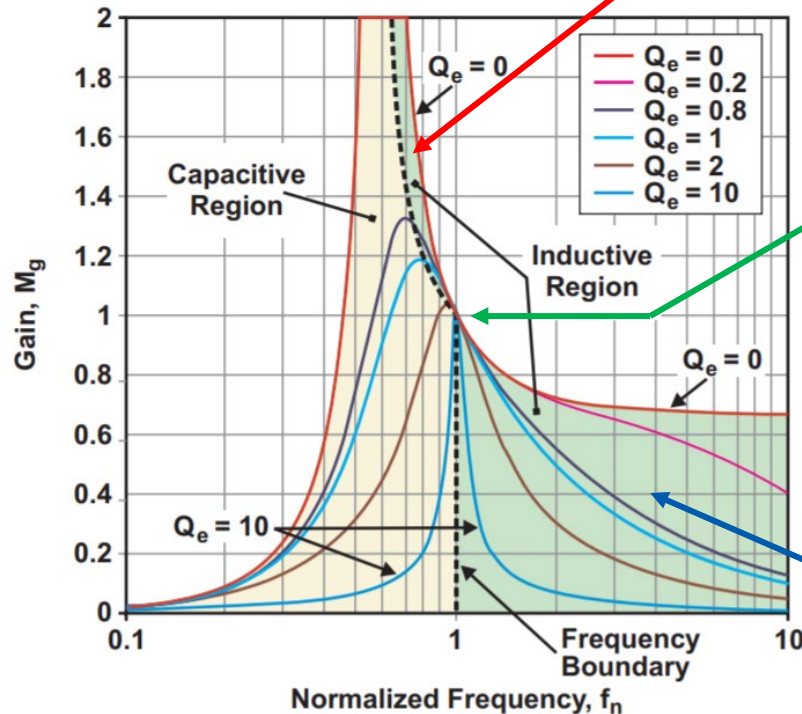


b. Below f_0 .

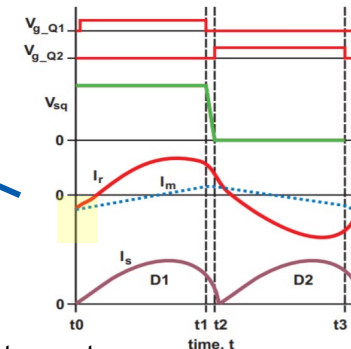
$$Q_e = \frac{\sqrt{L_r/C_r}}{R_e}$$

$$R_e = \frac{V_{oe}}{I_{oe}} = \frac{8 \times n^2}{\pi^2} \times \frac{V_o}{I_o} = \frac{8 \times n^2}{\pi^2} \times R_L$$

$$f_0 = \frac{1}{2\pi\sqrt{L_r C_r}}$$



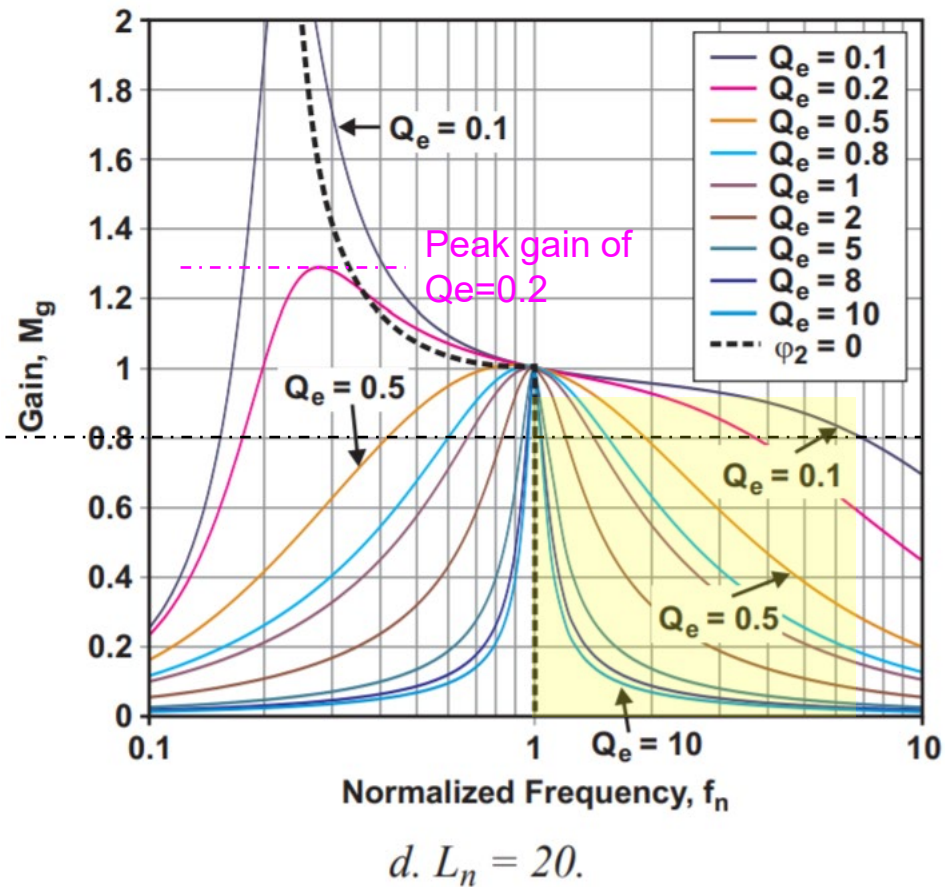
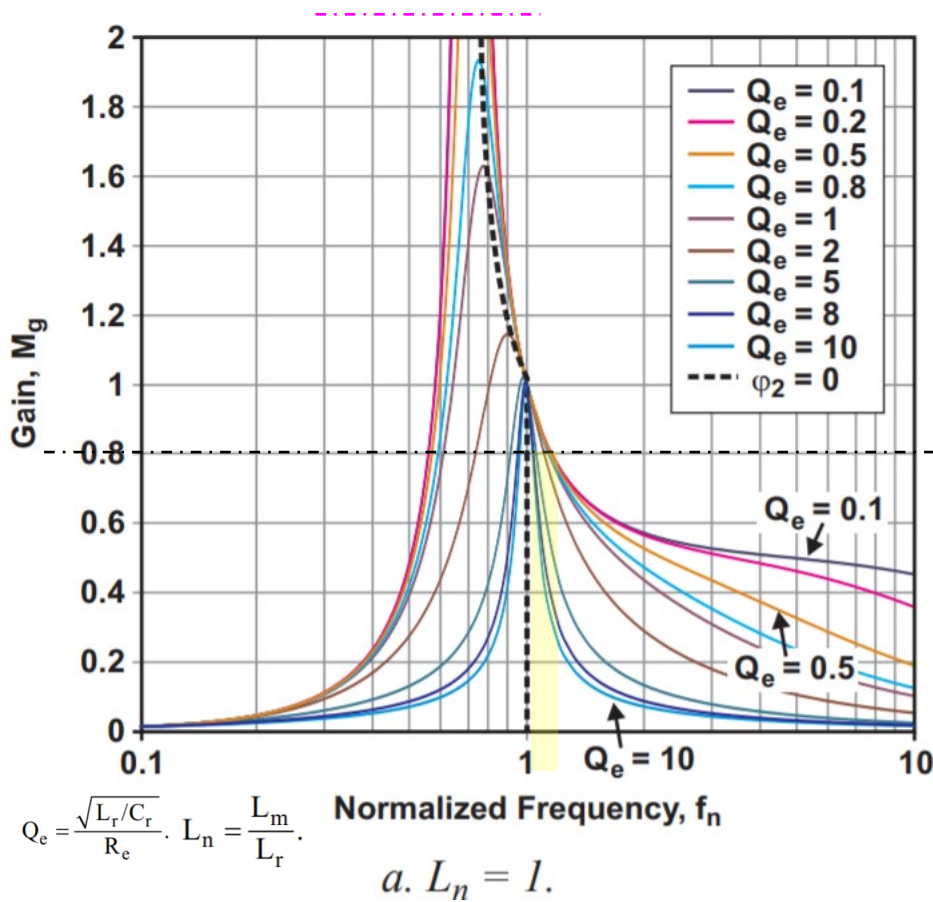
a. At f_0 .



c. Above f_0 .

- ZVS occur with inductance impedance
- Do not work@ capacitive region
- The more deviated from the resonance point, the conduction loss increases

Interpretation of voltage gain curve



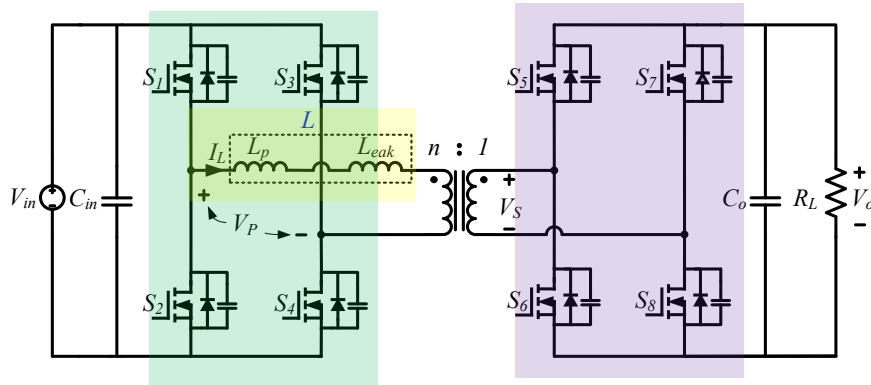
- The smaller the design of L_n , the greater the peak gain of the converter (hold up time requirement)
- The smaller the design of L_n , the narrower the converter's regulated frequency modulation range
- For conduction loss consideration, the greater the L_m , the lower the conduction loss. But for the ZVS range and peak gain of converter requirement, the maximum L_m value should be limited.

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 - Active-Clamp
 - Resonant Converter
 - Dual Active Bridge, DAB
 - Phase-Shift Full Bridge, PSFB

Dual Active Bridge Converter, DAB

(Choose Single Phase Shift control for example)

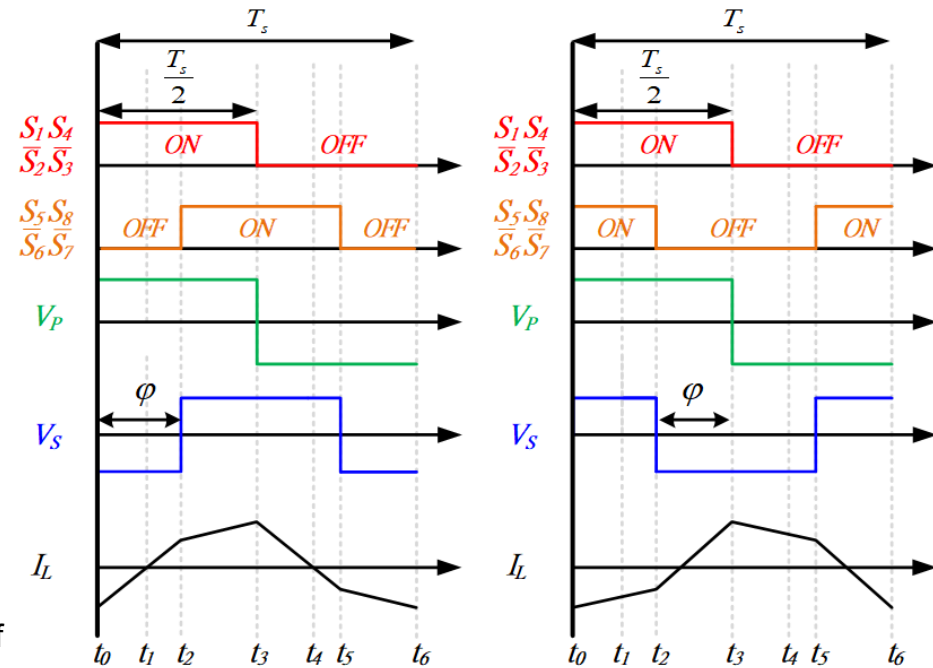


Advantage:

1. Easy bi-directional power flow control
2. Achieve ZVS, but still has the limitation of zero voltage switching conditions
3. Change the phase shift angle to adjust the voltage regulation, and the converter operates at a fixed frequency
4. The RMS value of the switching current is smaller than that of the resonant converter

Shortcoming:

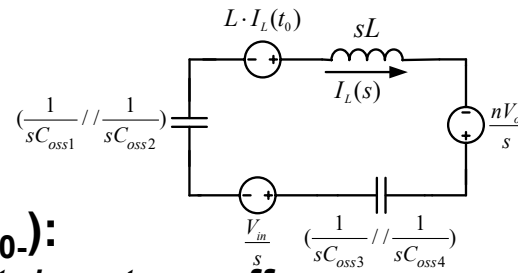
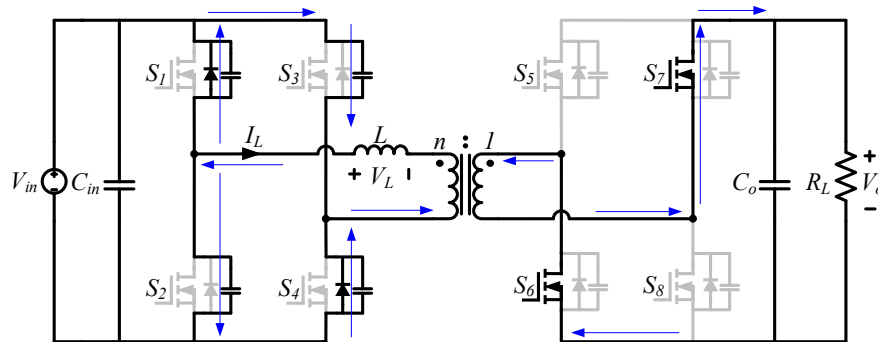
1. Compared with the resonant converter, the rectifier test switch does not have the characteristic of ZCS turns off
2. The cut-off current of the switch is more significant than that of the resonant converter, and the turn off loss is higher
3. When the switch turns off with hard switching, the switch's v_{DS} spike and the interference to the surrounding circuits are relatively large.
4. Zero voltage switching (SPS) is not possible when the voltage conversion ratio is 1.



(a) 正功率潮流

(b) 负功率潮流

SPS DAB Converter – $t_0 \sim t_1$



Resonant period ($t=t_0$):

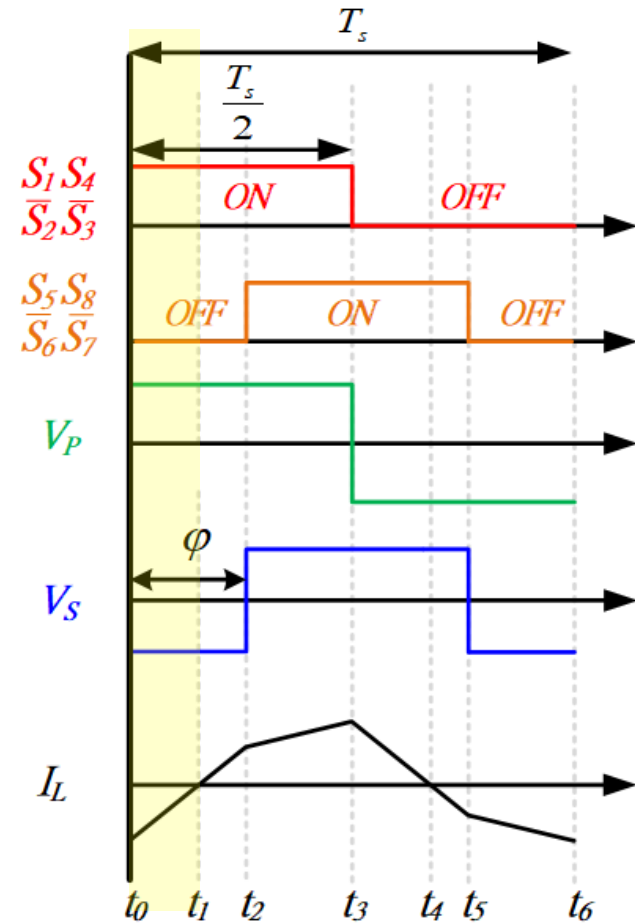
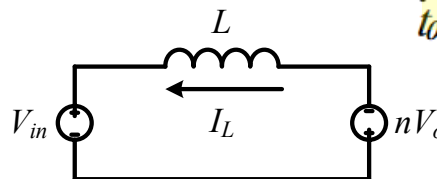
1. Primary side 4 switches turn off
2. $i_{Lr}(t_0) < 0$, discharge C_{oss} and make body diode conduct.

ZVS period ($t=t_0+$):

1. S_1, S_4 turn on with ZVS

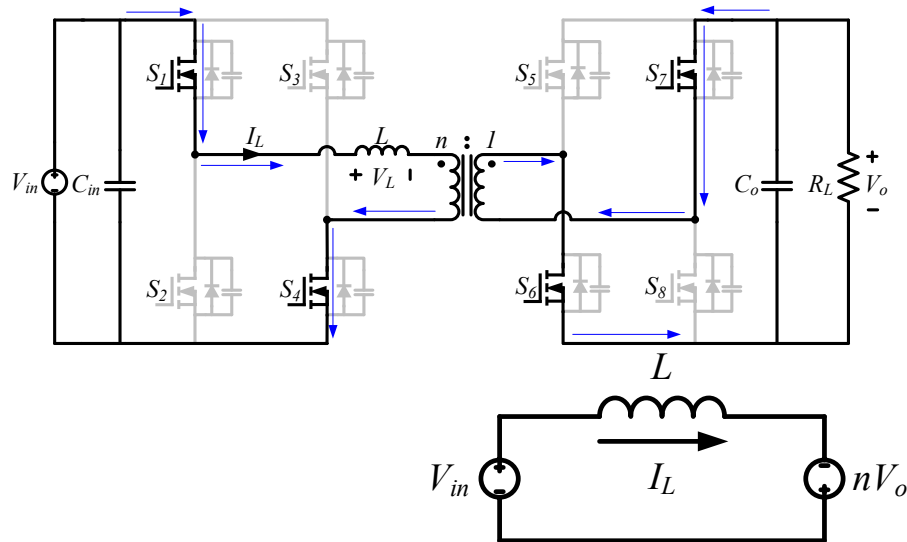
Reactive power period ($t=t_0+ \sim t_1$):

1. $i_{Lr}(t) < 0, V_p > 0 \Rightarrow$ Reactive power
2. $V_L = V_{in} + nV_o, i_{Lr}(t)$ increase linearly



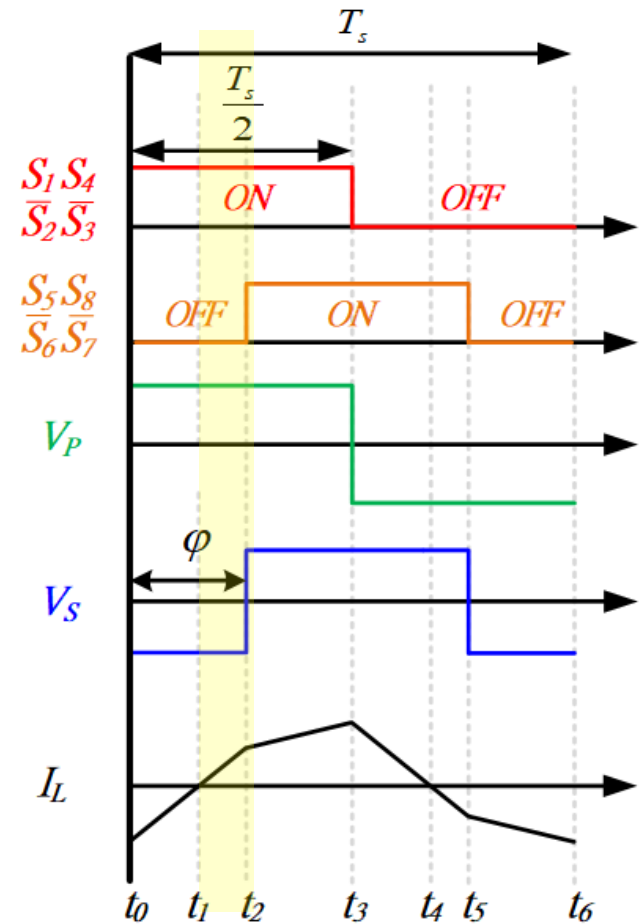
(a) 正功率潮流

SPS DAB Converter – $t_1 \sim t_2$



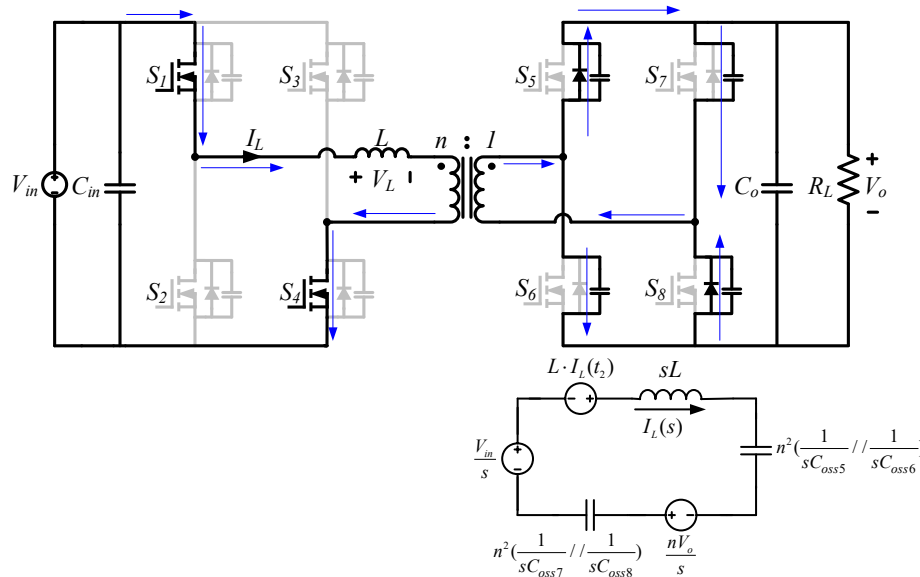
Power delivery period ($t_1 \sim t_2$):

1. $i_{Lr}(t) > 0$, $V_p > 0 \rightarrow$ Real power
2. $V_L = V_{in} + nV_o$, $i_{Lr}(t)$ increase linearly



(a) 正功率潮流

SPS DAB Converter – $t_2 \sim t_3$



Resonant period ($t=t_2$):

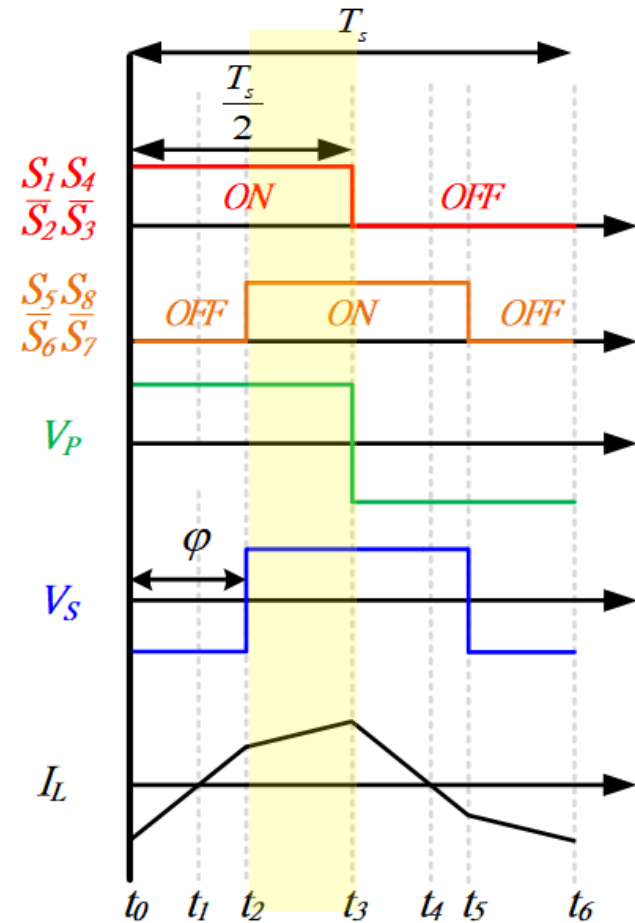
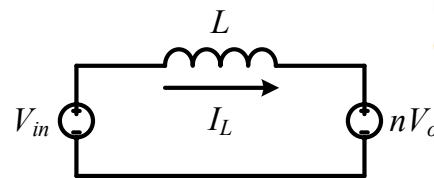
1. Secondary side 4 switches turn off
2. $i_{Lr}(t_2^-) < 0$, discharge C_{oss} and make body diode conduct.

ZVS period ($t=t_2^+$):

1. S_5, S_8 turn on with ZVS

Power delivery period ($t_2 \sim t_3$):

1. $i_{Lr}(t) > 0$, $V_p > 0 \Rightarrow$ Real power
2. $V_L = V_{in} - nV_o$, $i_{Lr}(t)$ increase linearly



(a) 正功率潮流

The relationship of output power, phase shift angle and proportion of real, reactive power

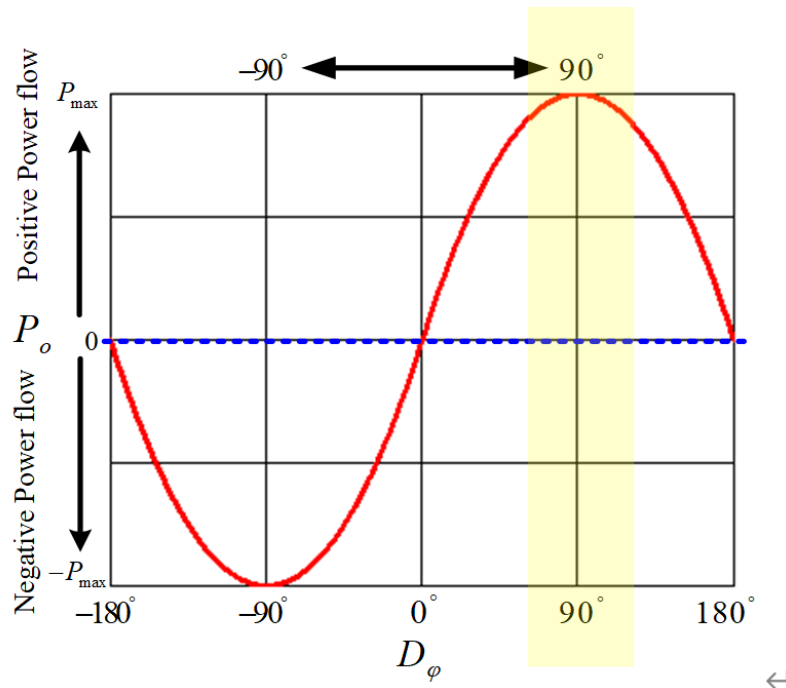


圖 2-7 單相移之輸出功率與相移角度關係圖

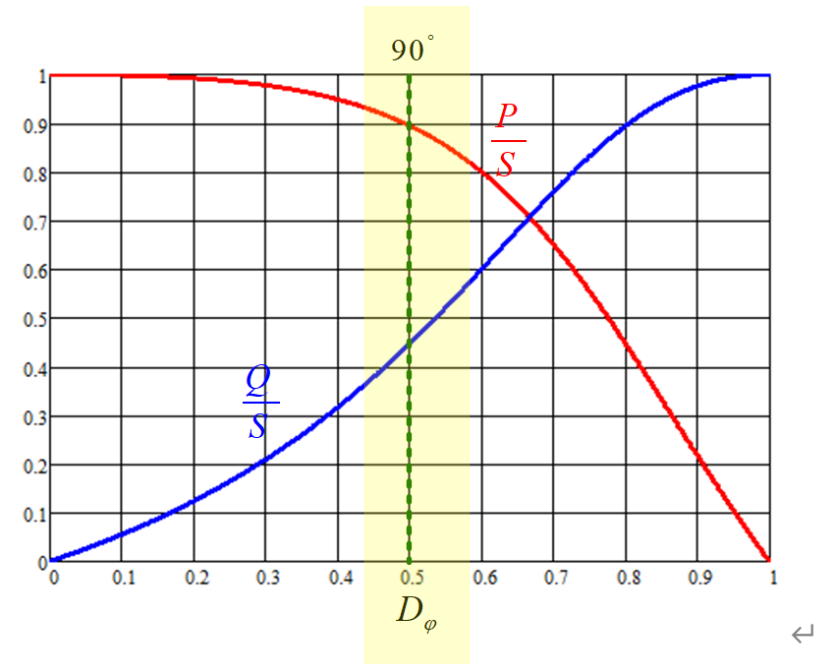
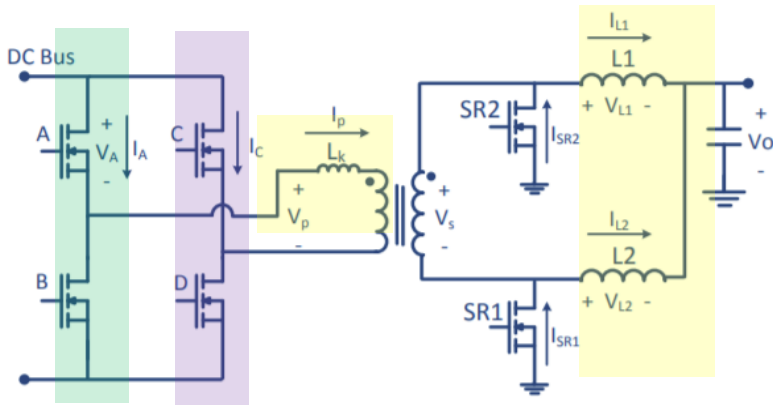


圖 2-8 虛功(Q)、實功(P)與視在功率(S)占比及相移角關係圖

Course outline – Week 5

- Introduction of Zero Voltage Switching / Zero Current Switching technology
 - Review the switching characteristics and the reasons for adopting ZVS or ZCS
 - The basic principle to realize ZVS
- **Common methods to implement ZVS**
 - Critical conduction Mode, CrM
 - Zero Voltage Transition, ZVT
 - Quasi-Resonant Converter, QRC
 - Active-Clamp
 - Resonant Converter
 - Dual Active Bridge, DAB
 - Phase-Shift Full Bridge, PSFB

Phase Shift Full Bridge Converter

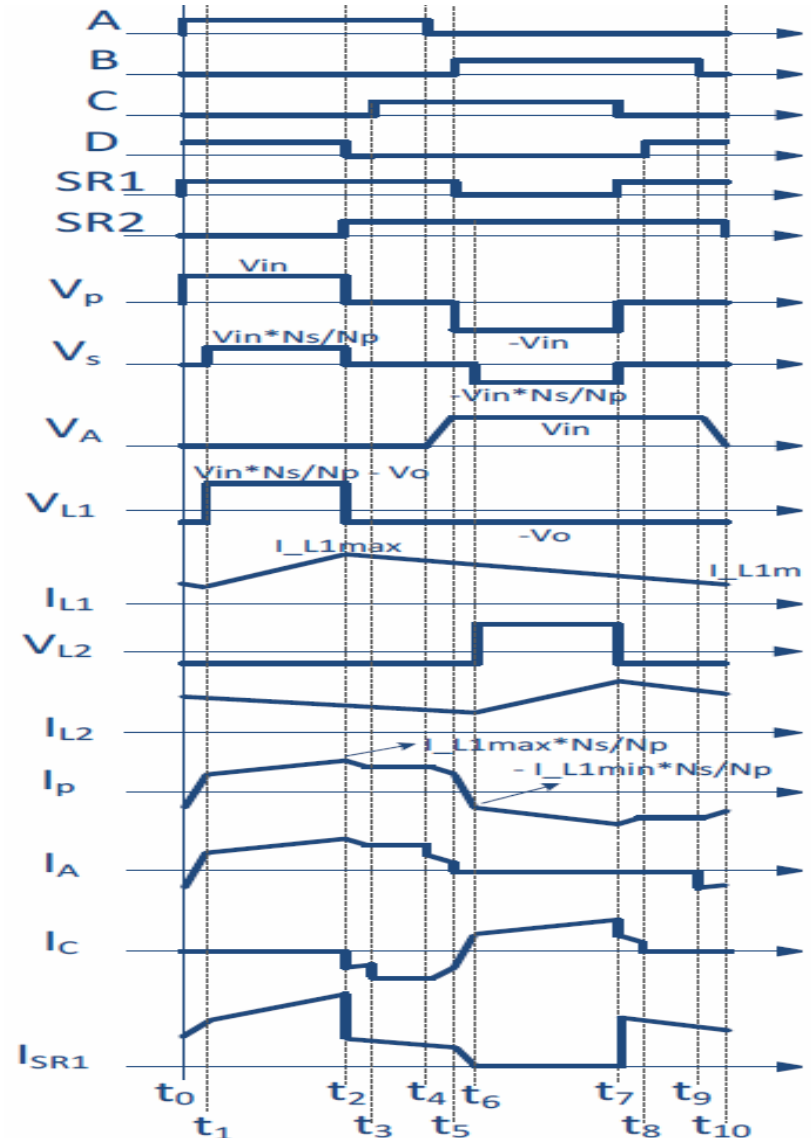


Advantage:

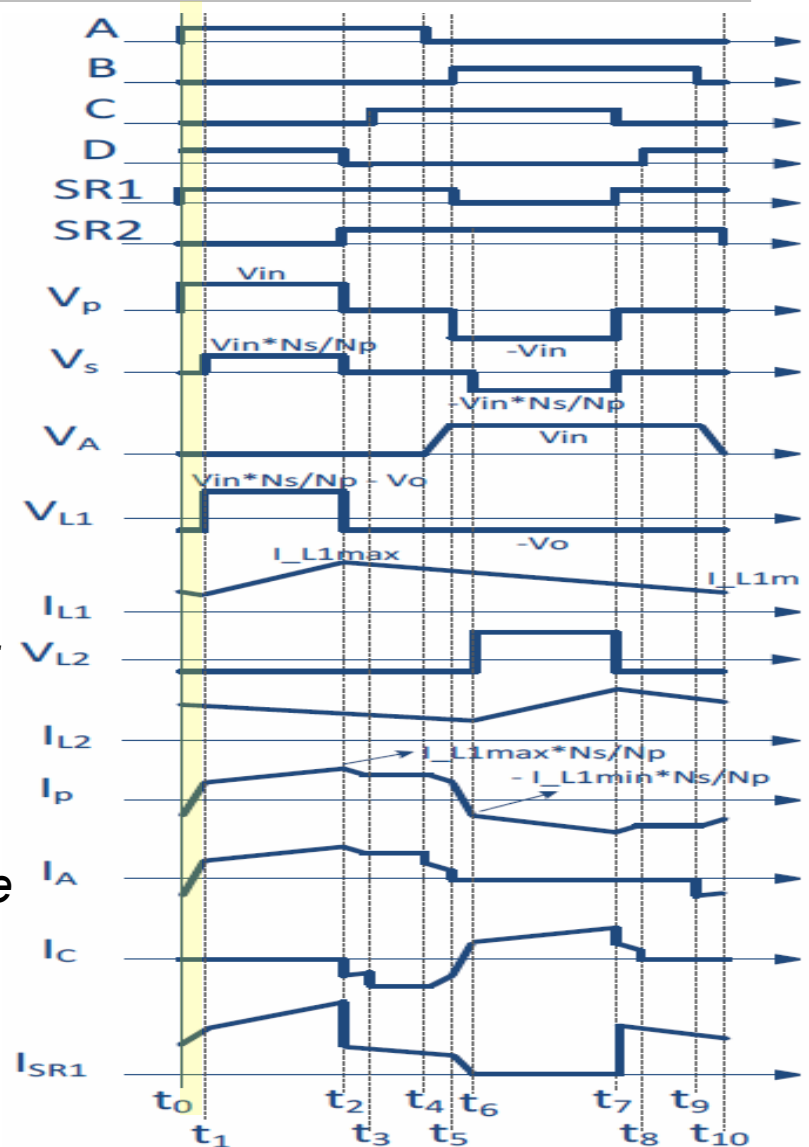
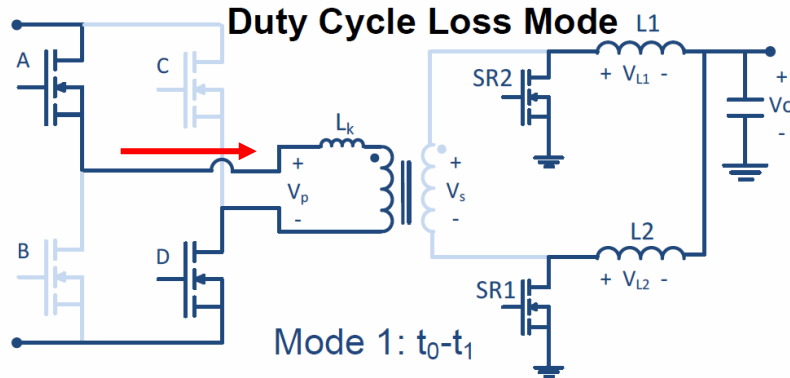
1. The output contains inductance, so the output voltage and current ripple are small
2. ZVS can be achieved but limited by the loading conditions
3. Change the phase shift angle to adjust the voltage regulation, and the converter operates at a fixed frequency
4. The RMS value of the switching current is smaller than that of the resonant converter and DAB converter

Shortcoming:

1. Compared with the resonant converter, the rectifier test switch does not have the characteristic of zero current switching
2. The cut-off current of the switch is more significant than that of the resonant converter, and the cut-off loss is higher
3. When the switch turns off with hard switching, the switch's v_{DS} spike and the interference to the surrounding circuits are relatively large.
4. The zero voltage switching conditions of the leading arm and the lagging arm are different
5. Trade-off between duty cycle loss and zero voltage switching conditions



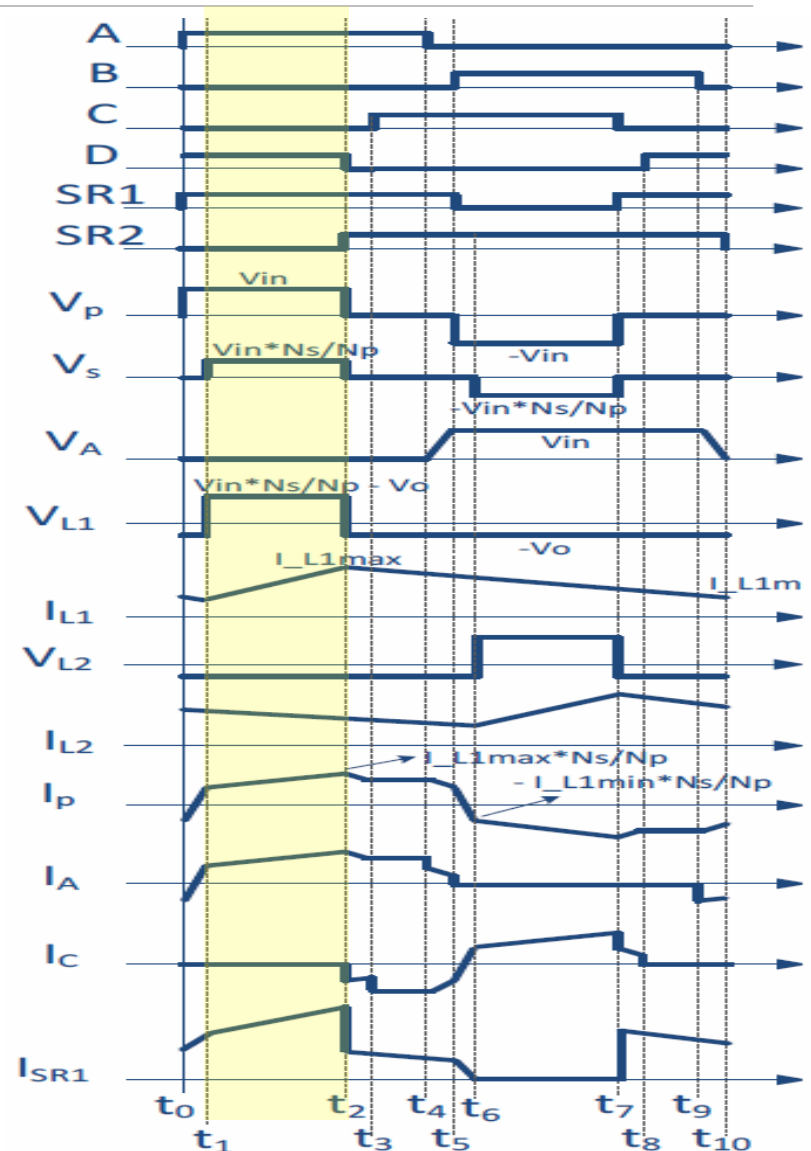
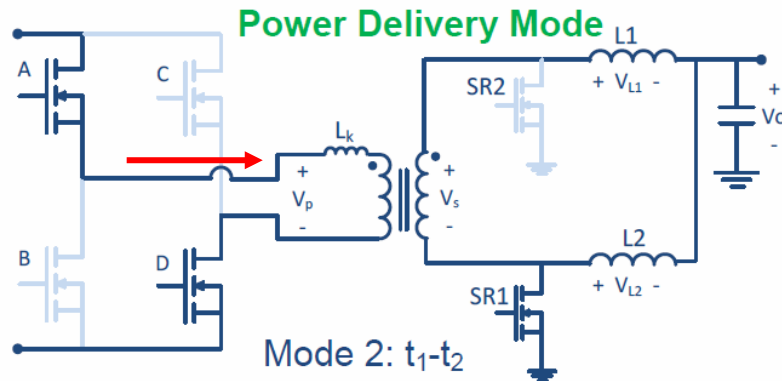
Phase Shift Full Bridge Converter – $t_0 \sim t_1$



Duty cycle loss interval ($t_0 \sim t_1$):

1. $i_{Lk}(t_0) < 0$, let body diode of switch A, D conduct
→ ZVS turns on
2. $i_{Lk}(t_1) < n \cdot i_{L1}$ → transformer decouple
3. $V_{L1} = V_{L2} = -V_o$, i_{L1} , i_{L2} decrease linearly
4. Input power doesn't transfer to secondary side
→ Duty cycle loss

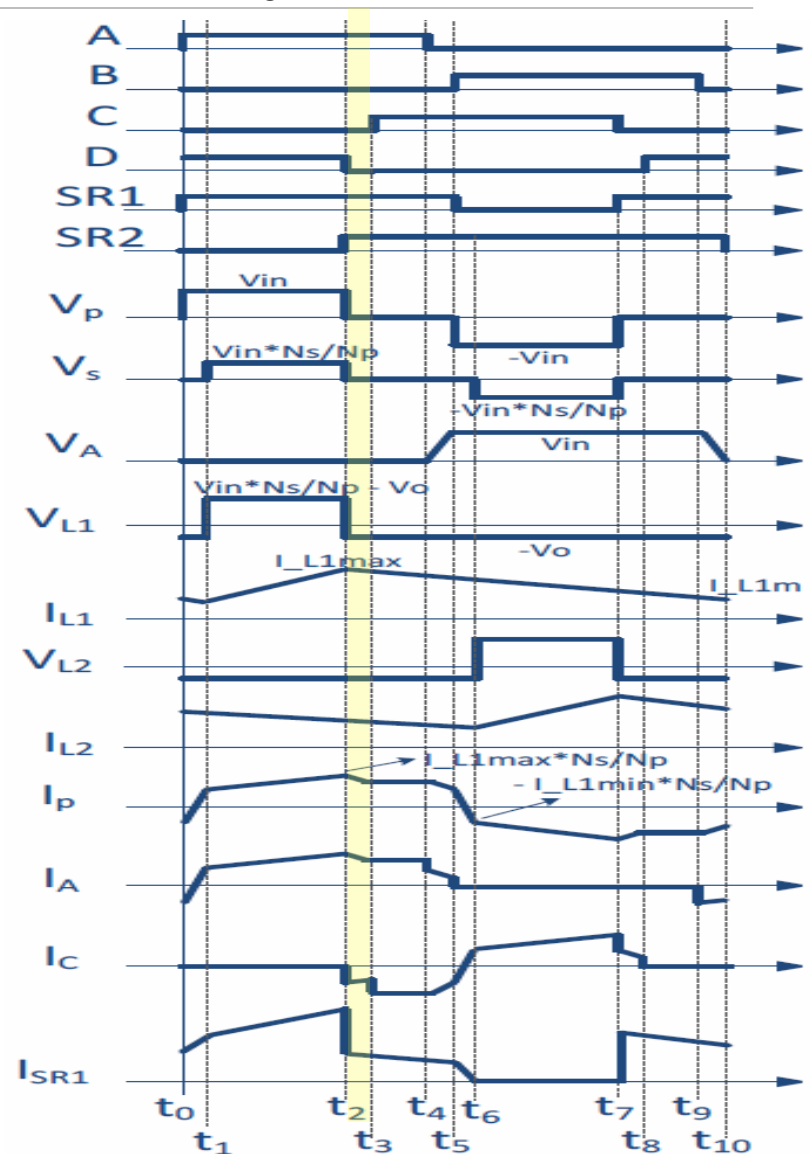
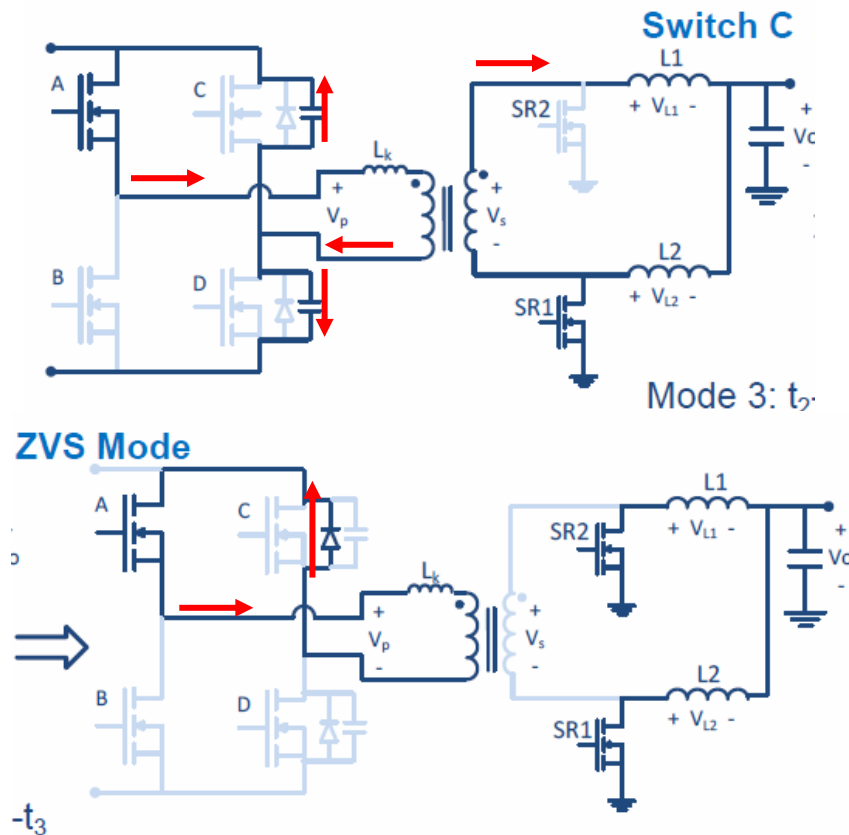
Phase Shift Full Bridge Converter – $t_1 \sim t_2$



Power delivery interval ($t_1 \sim t_2$):

1. $i_{Lk}(t_{1+}) = 1/n \cdot i_{L1} \rightarrow$ body diode of SR2 turns off \rightarrow transformer coupling
2. $V_{L1} = 1/n \cdot V_{in} - V_o$, i_{L1} increase linearly
3. Power delivery from primary side

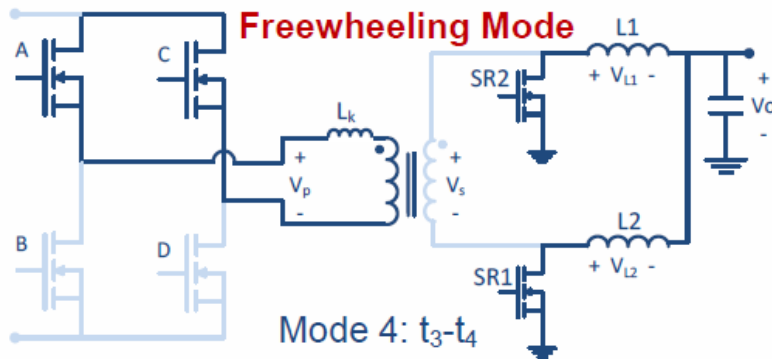
Phase Shift Full Bridge Converter – $t_2 \sim t_3$



Switch C resonant interval ($t_2 \sim t_3$):

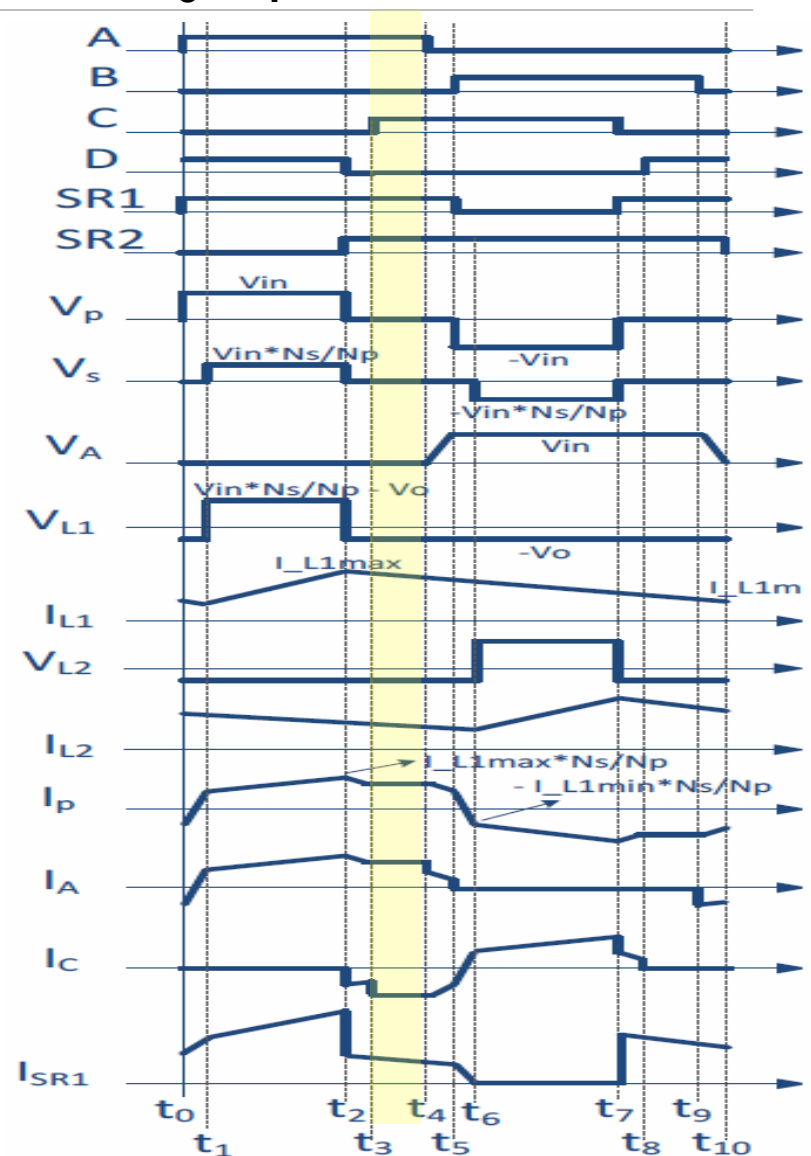
1. $i_{Lk}(t_{2+}) > 0 \Rightarrow C_{oss}$ of switch C discharge
2. Switch's body diode conduct
3. $V_p = 0V$
4. Transformer decouple

Phase Shift Full Bridge Converter – $t_3 \sim t_4$

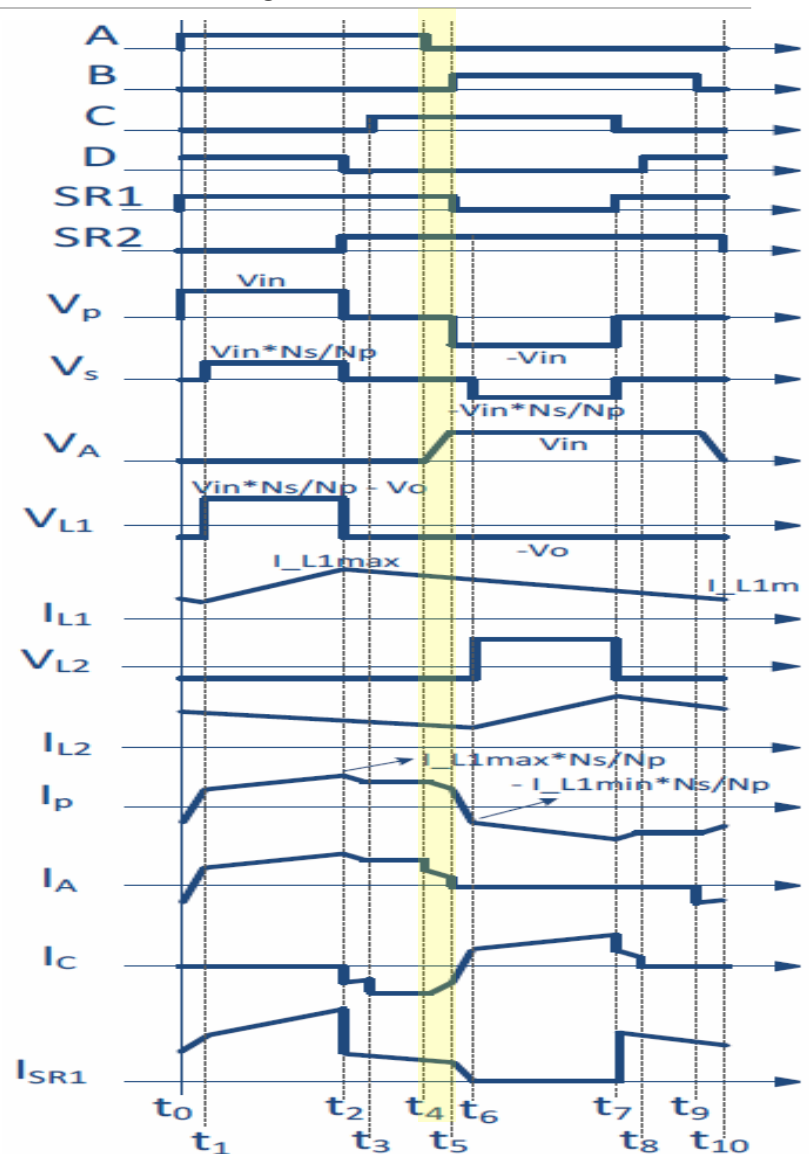
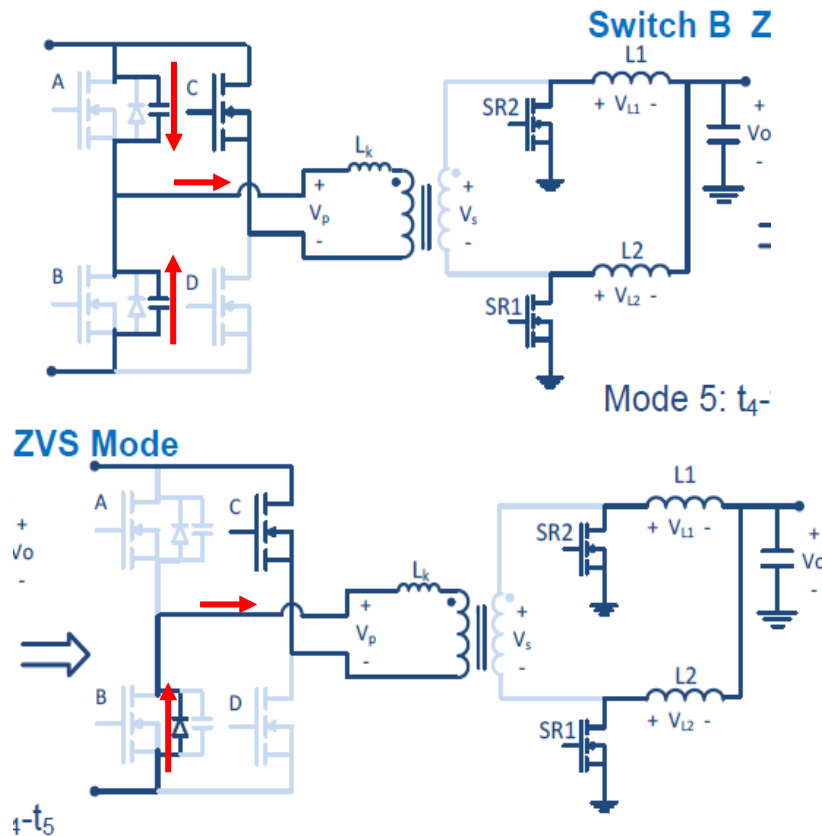


Switch C ZVS interval ($t_3 \sim t_4$):

1. Switch C turns on with ZVS
2. $V_p = 0V$, i_{Lk} freewheeling
3. Transformer decouple, i_{L1} , i_{L2} freewheeling



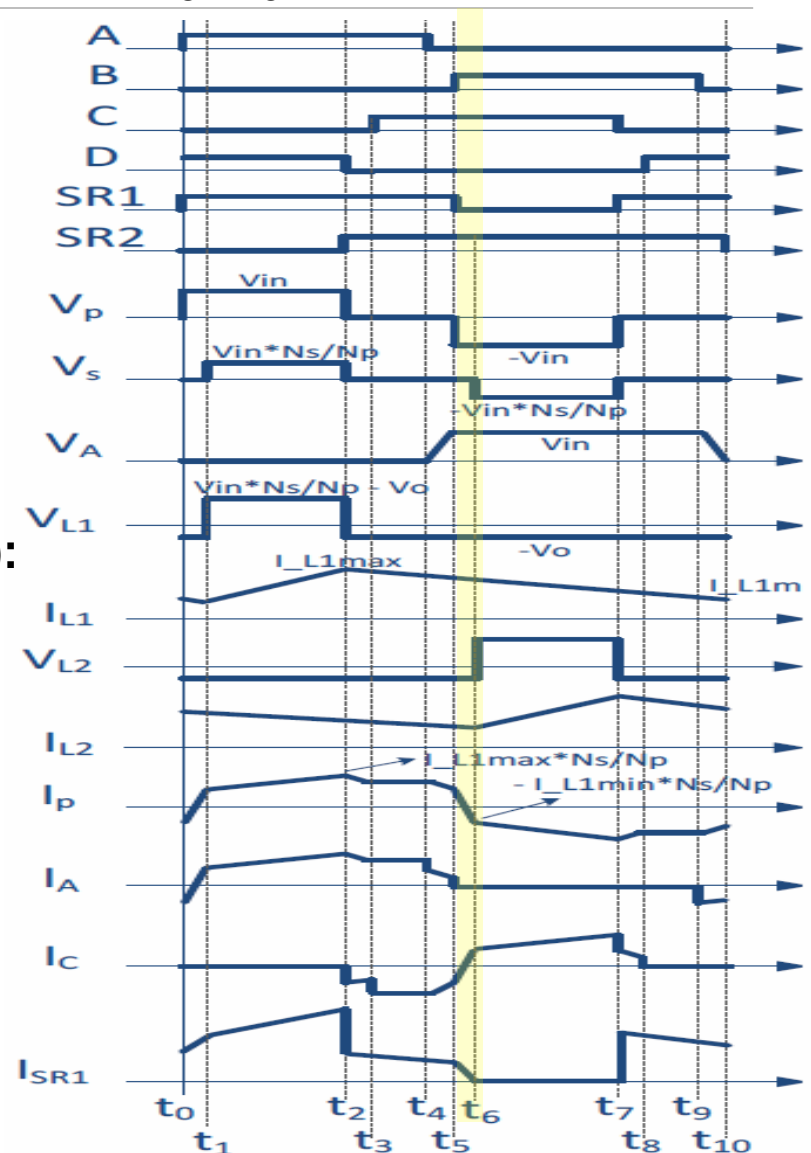
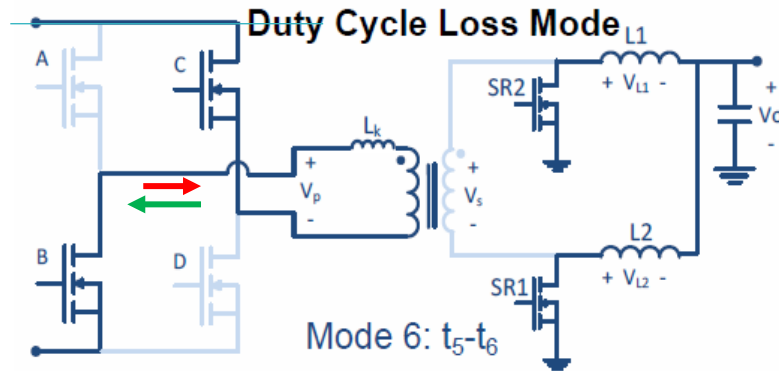
Phase Shift Full Bridge Converter – $t_4 \sim t_5$



Switch B resonant interval ($t_4 \sim t_5$):

1. $i_{Lk}(t_{4+}) > 0 \Rightarrow C_{oss}$ of switch B discharge
2. V_p from $0V$ to $-V_{in} \Rightarrow$
 i_{Lk} decrease linearly after switch B's body diode conduct

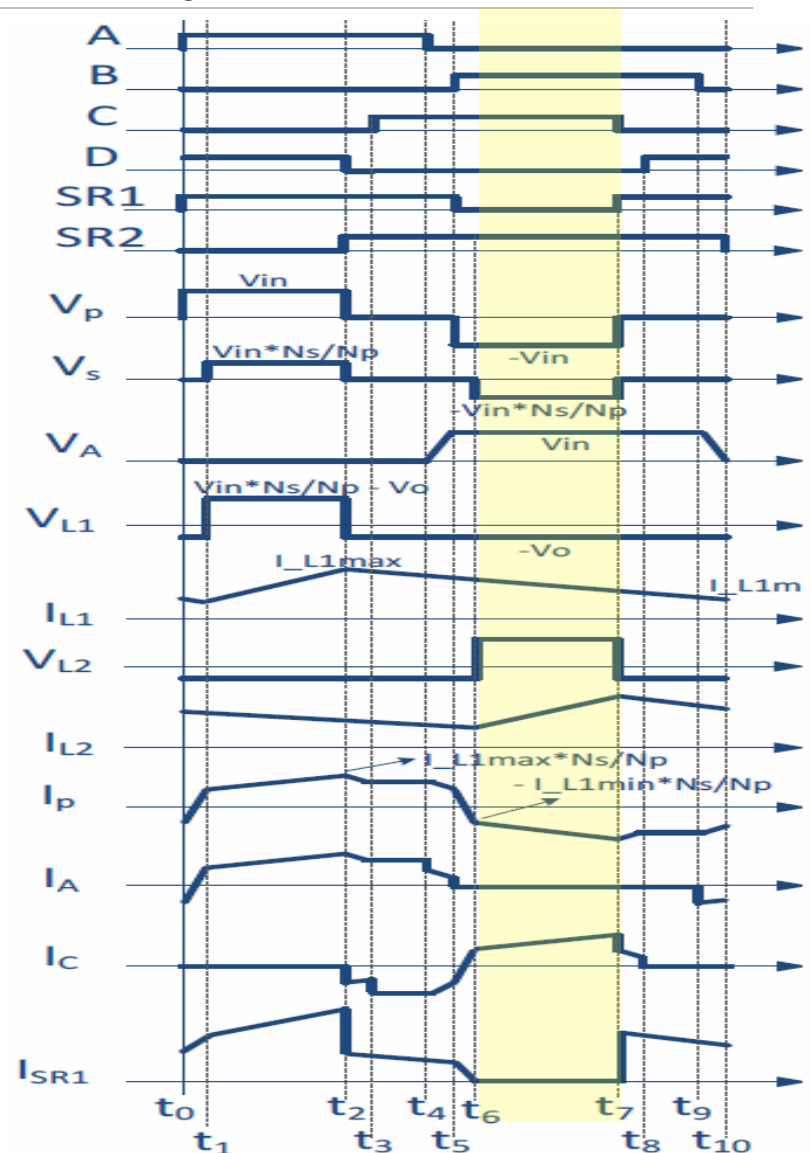
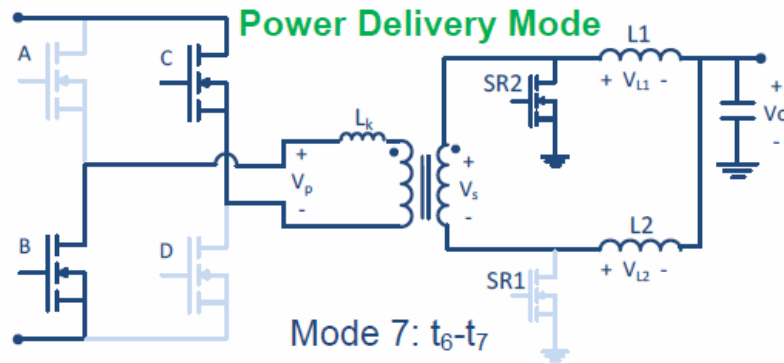
Phase Shift Full Bridge Converter – $t_5 \sim t_6$



Switch B ZVS & Duty cycle loss interval ($t_5 \sim t_6$):

1. Switch B turns on @ $t=t_5$ and $i_{Lk}(t_5) > 0$, ZVS turn on
2. i_{Lk} decrease from positive to negative until it reach $-i_{L1} * 1/n$
3. Transformer decouple

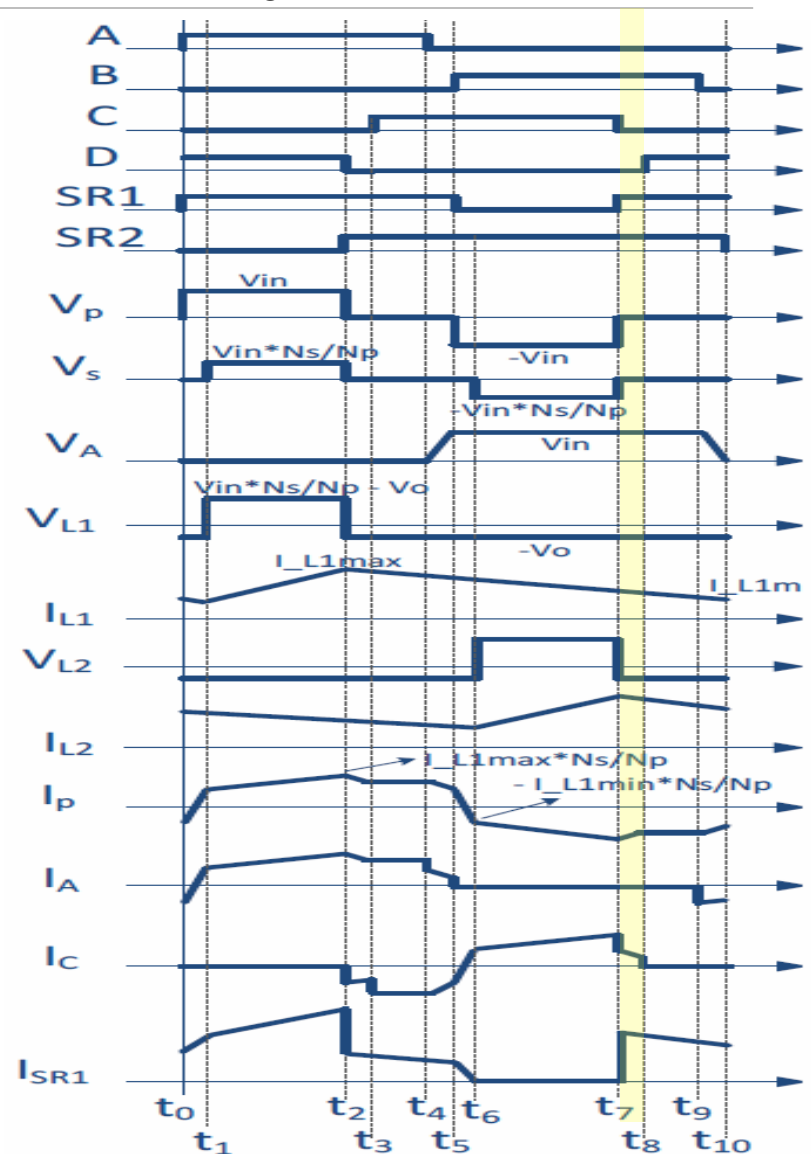
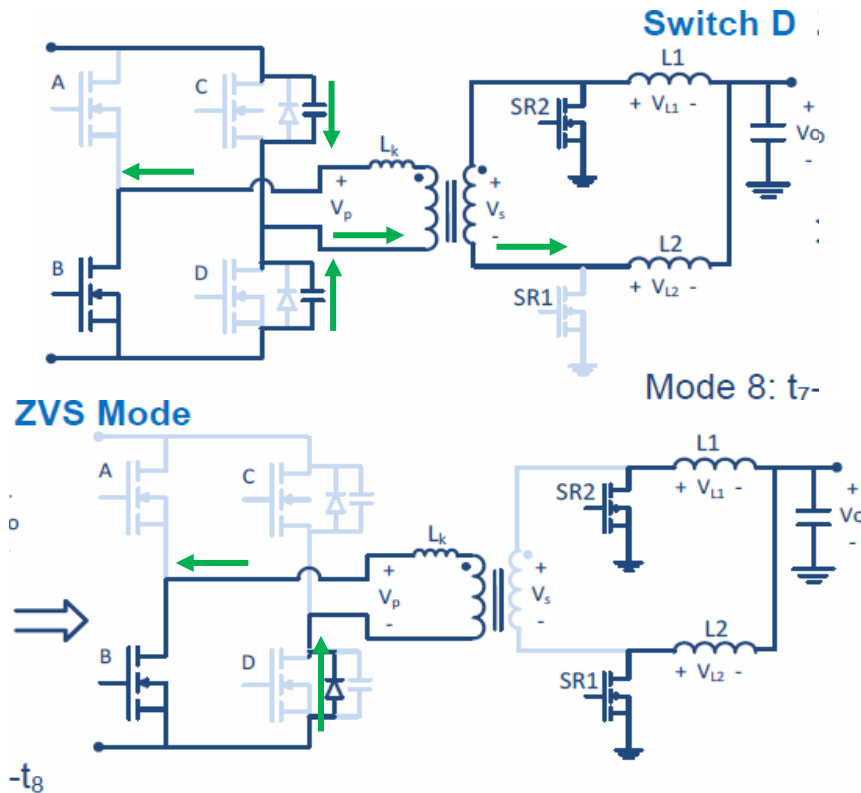
Phase Shift Full Bridge Converter – $t_6 \sim t_7$



Power delivery interval ($t_6 \sim t_7$):

1. $i_{Lk}(t_{6+}) = 1/n * i_{L1} \rightarrow$ body diode of SR1 turns off \rightarrow transformer coupling
2. $V_{L2} = 1/n * V_{in} - V_o$, i_{L2} increase linearly
3. Power delivery from primary side

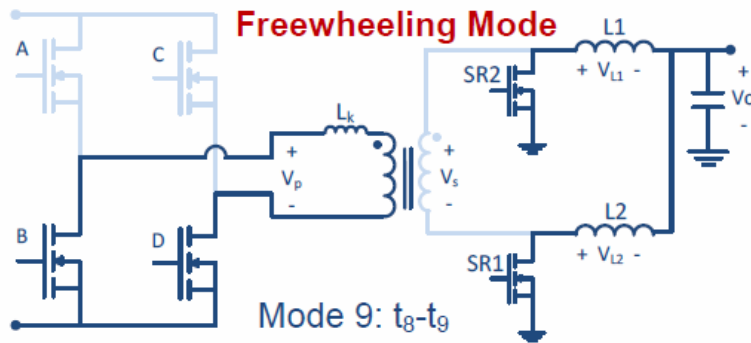
Phase Shift Full Bridge Converter – $t_7 \sim t_8$



Switch D resonant interval ($t_7 \sim t_8$):

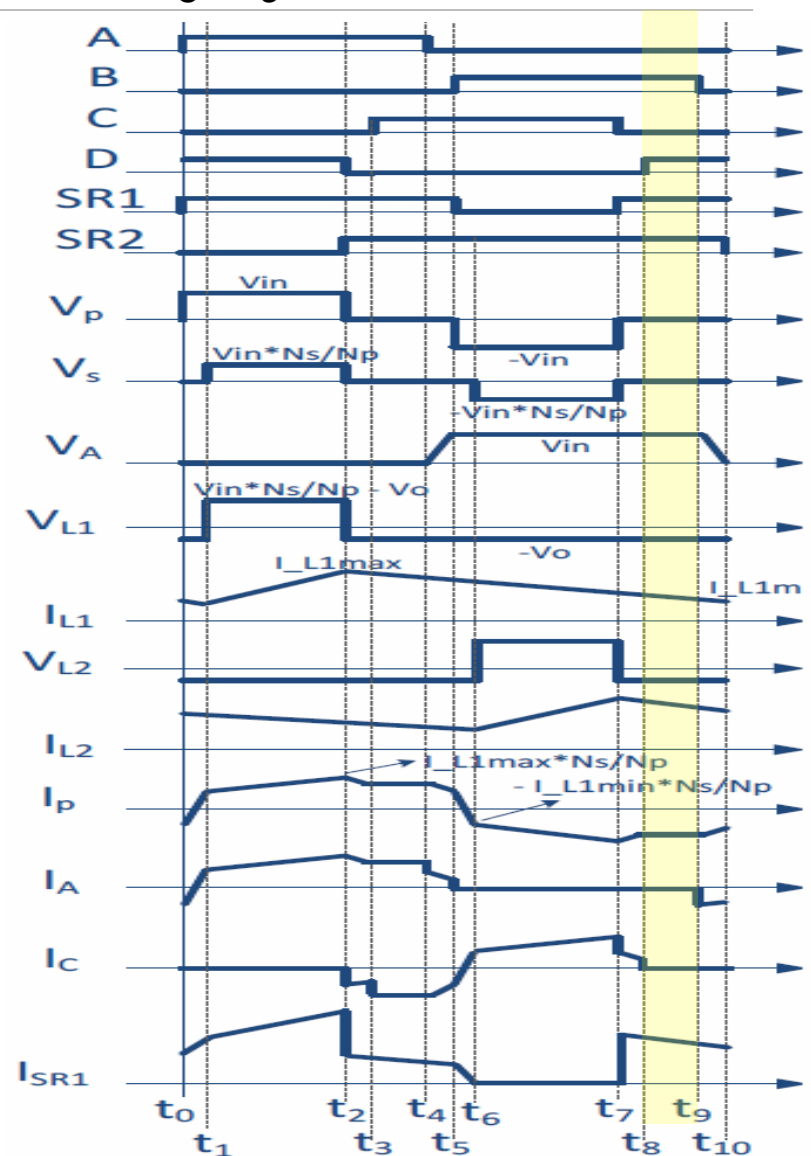
1. $i_{Lk}(t_{7+}) < 0 \Rightarrow C_{oss}$ of switch D discharge
2. Switch's body diode conduct
3. $V_p = 0V$
4. Transformer decouple

Phase Shift Full Bridge Converter – $t_8 \sim t_9$

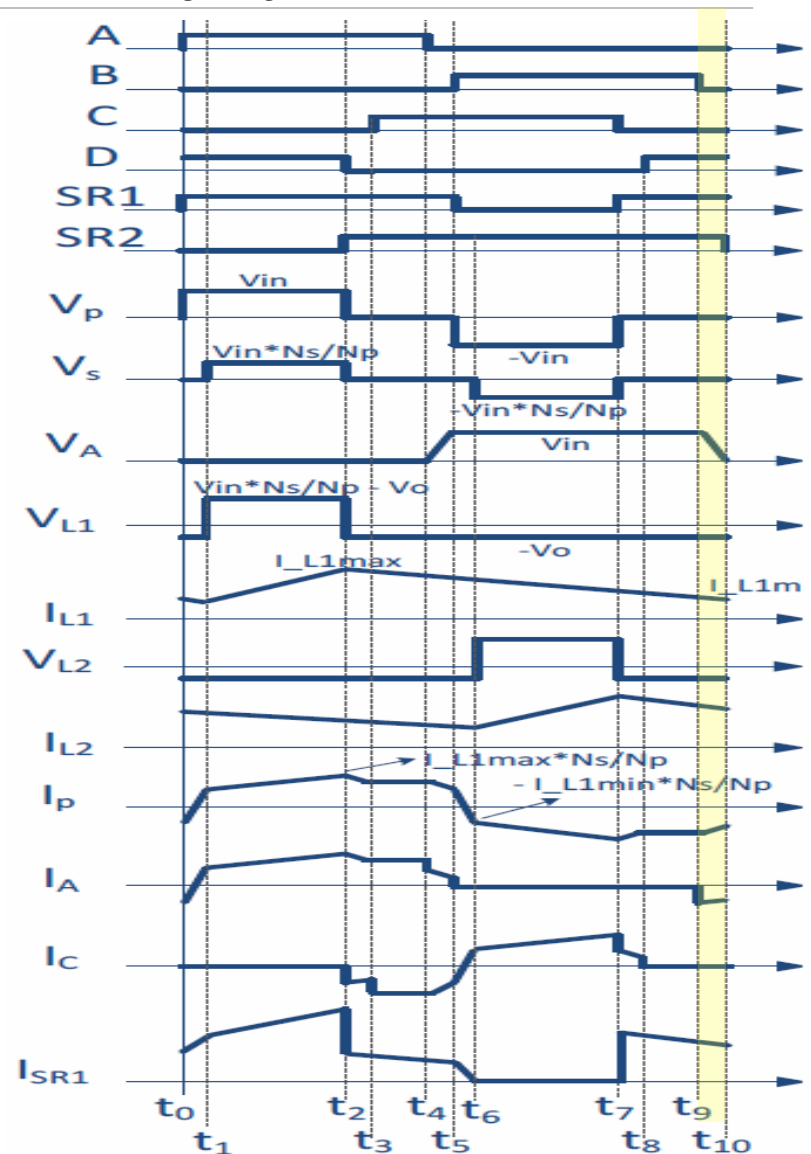
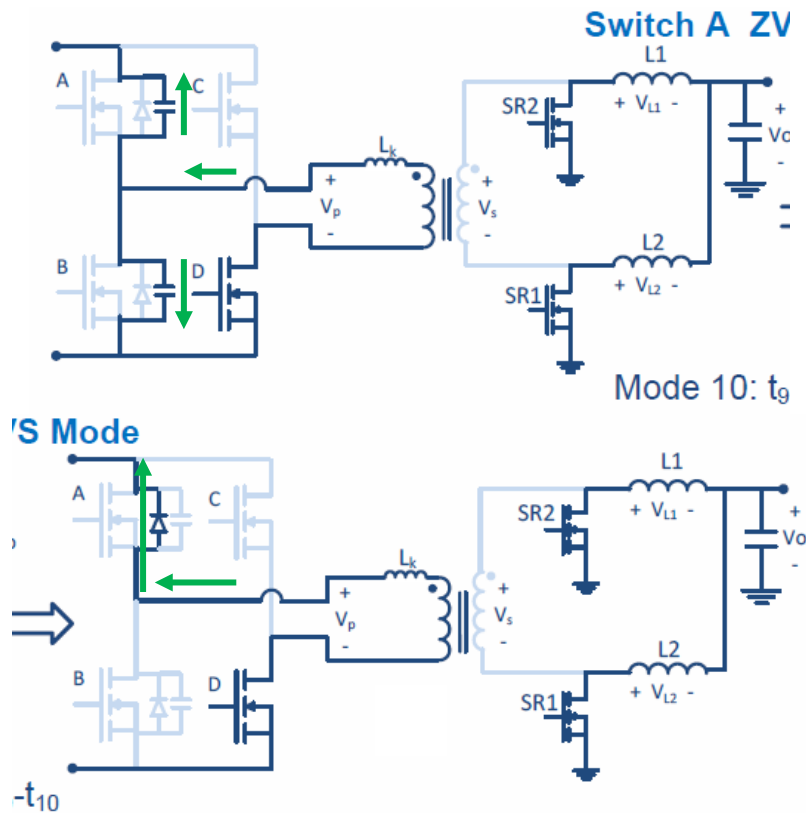


Switch D ZVS interval ($t_8 \sim t_9$):

1. Switch D turns on with ZVS
2. $V_p = 0V$, i_{Lk} freewheeling
3. Transformer decouple, i_{L1} , i_{L2} freewheeling



Phase Shift Full Bridge Converter – $t_8 \sim t_9$



Switch A resonant interval ($t_4 \sim t_5$):

1. $i_{Lk}(t_{9+}) > 0 \Rightarrow C_{oss}$ of switch A discharge
2. V_p from $0V$ to $V_{in} \Rightarrow$
 i_{Lk} increase linearly after switch A's body diode conduct



THANK YOU